

# RF430F5978 MSP430™ System-in-Package

## With Sub-1-GHz Transceiver and 3D LF Wake-up and Transponder Interface

### 1 Device Overview

#### 1.1 Features

- True System-In-Package Based On MSP430™ Microcontroller With Sub-1-GHz Transceiver System-On-Chip (SoC) and Additional 3D LF Wake-up and Transponder Interface
- Wide Supply Voltage Range: 3.6 V Down To 1.8 V
- Ultra-Low Power Consumption
  - CPU Active Mode (AM): 160  $\mu$ A/MHz
  - Standby Mode (LPM3 Real-Time Clock [RTC] Mode): 2.0  $\mu$ A
  - Off Mode (LPM4 RAM Retention): 1.0  $\mu$ A
  - Radio in Receive: 15 mA, 250 kbps, 915 MHz
- MSP430 System and Peripherals
  - 16-Bit RISC Architecture, Extended Memory, up to 20-MHz System Clock
  - Wake up From Standby Mode in Less Than 6  $\mu$ s
  - Flexible Power-Management System With SVS and Brownout
  - Unified Clock System With FLL
  - 16-Bit Timer TA0, Timer\_A With Five Capture/Compare Registers
  - 16-Bit Timer TA1, Timer\_A With Three Capture/Compare Registers
  - Hardware RTC
  - Two Universal Serial Communication Interfaces (USCIs)
    - USCI\_A0 Supports UART, IrDA, SPI
    - USCI\_B0 Supports I<sup>2</sup>C, SPI
  - 12-Bit Analog-to-Digital Converter (ADC) With Internal Reference, Sample-and-Hold, and Autoscan Features
  - Comparator
  - 128-Bit AES Security Encryption and Decryption Coprocessor
  - 32-Bit Hardware Multiplier
  - 3-Channel Internal DMA
  - Serial Onboard Programming, No External Programming Voltage Needed
  - Embedded Emulation Module (EEM)
- High-Performance Sub-1-GHz Radio Frequency (RF) Transceiver Core
  - Same as in [CC1101](#)
  - Wide Supply Voltage Range: 2 V to 3.6 V
  - Frequency Bands: 300 MHz to 348 MHz, 389 MHz to 464 MHz, and 779 MHz to 928 MHz
  - Programmable Data Rate From 0.6 kBaud to 500 kBaud
  - High Sensitivity (–117 dBm at 0.6 kBaud, –111 dBm at 1.2 kBaud, 315 MHz, 1% Packet Error Rate)
  - Excellent Receiver Selectivity and Blocking Performance
  - Programmable Output Power up to +12 dBm for All Supported Frequencies
  - 2-FSK, 2-GFSK, and MSK Supported as Well as OOK and Flexible ASK Shaping
  - Flexible Support for Packet-Oriented Systems: On-Chip Support for Sync Word Detection, Address Check, Flexible Packet Length, and Automatic CRC Handling
  - Support for Automatic Clear Channel Assessment (CCA) Before Transmitting (for Listen-Before-Talk Systems)
  - Digital RSSI Output
  - Suited for Systems Targeting Compliance With EN 300 220 (Europe) and FCC CFR Part 15 (US)
  - Suited for Systems Targeting Compliance With Wireless M-Bus Standard EN 13757-4:2005
  - Support for Asynchronous and Synchronous Serial Receive and Transmit Mode for Backward Compatibility With Existing Radio Communication Protocols



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

- High-Performance Low-Frequency (LF) Interface
  - 3D Wake-up Receiver
    - Low Standby Current Consumption: 4.4  $\mu$ A
    - Regular Sensitivity Mode: 3.7 mVpp → Approximate 3-m Wake Range
    - High Sensitivity Mode: 0.5 mVpp → Approximate 6-m Wake Range
    - Low Sensitivity Variation
    - Digital RSSI, 72 dB, 8-Bit Logarithmic
    - Two Independent Wake Patterns, 0-Bit to 24-Bit Length
    - Dedicated Sensitivity Levels for Both Wake Patterns
    - Integrated LF Bit Stream Data Decoding and Digital Data Output
  - AES-128 Hardware Encryption Coprocessor
  - Resonant Frequency: 134.2 kHz
    - Embedded Resonant Trimming for All Three Resonant Circuits
- 3D Transponder Interface
  - Transponder Read Range up to 4 in (10 cm), Power Received From LF RF Field
  - Half-Duplex (HDX) Communication Protocol
  - Selectable Challenge/Response Length: 32/32, 64/64, or 96/64 Bit
  - Mutual Authentication For All Commands With 32-Bit Reader Signature
  - Burst Read Mode
  - Anticollision Encryption
- EEPROM Memory Size of 2048 Bytes
  - Available User EEPROM is 1776 Bytes
  - Encryption Keys 4  $\times$  128 Bits
  - Configurable Page Types for Selective Access Grant
  - All Pages Lockable (No Reprogramming Possible)
- Switch Interface With up to Eight Inputs

## 1.2 Applications

- Wireless Analog Sensor Systems
- Wireless Digital Sensor Systems
- Access Control
- Asset Tracking
- Smart Grid Wireless Networks

## 1.3 Description

The TI RF430F5978 system-in-package adds a 3D low-frequency (LF) wake-up and transponder interface to the CC430 ultra-low-power microcontroller system-on-chip (SoC) with integrated sub-1-GHz RF transceiver. This architecture allows activation and deactivation of the device in a dedicated and well-defined area "on-demand" to achieve extended battery life for the whole system. The embedded LF transponder interface is always functional even without battery supply and offers the highest level of security through its 128-bit AES encryption for challenge/response and mutual authentication. The embedded LF transponder interface also adds 2KB of programmable EEPROM memory to the system.

The CC430 ultra-low-power microcontroller system-on-chip (SoC) combines the CC1101 sub-1-GHz RF transceiver with the powerful MSP430 16-bit RISC CPU. Sixteen-bit registers and constant generators contribute to maximum code efficiency. The RF430F5978 device features the MSP430 CPUXV2, 32KB of in-system programmable flash memory, 4KB of RAM, two 16-bit timers, a high-performance 12-bit ADC with six external inputs plus internal temperature and battery sensors, a comparator, two USCs, a 128-bit AES security accelerator, a hardware multiplier, DMA, and an RTC module with alarm capabilities.

The RF430F5978 provides a tight integration between the microcontroller core, its peripherals, software, and the integrated sub-1-GHz RF transceiver and 3D LF transceiver for wake-up and transponder interface, making these solutions easy to use while improving performance.

For complete module descriptions, see the *RF430 Family User's Guide* ([SLAU378](#)).

### Device Information<sup>(1)</sup>

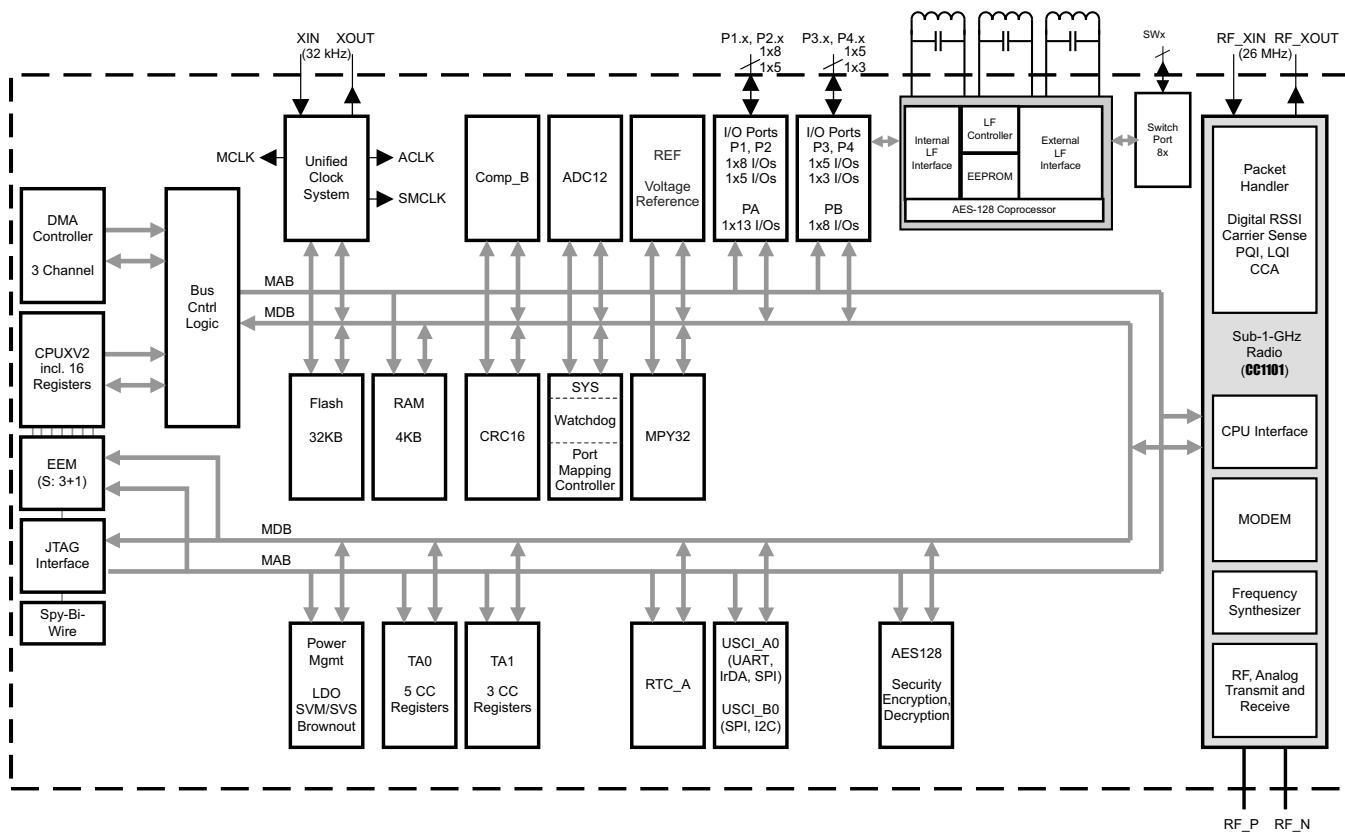
PART NUMBER	PACKAGE	BODY SIZE <sup>(2)</sup>
RF430F5978IRGC	VQFN (64)	9 mm $\times$ 9 mm

(1) For the most current part, package, and ordering information, see the *Package Option Addendum* in [Section 9](#), or see the TI website at [www.ti.com](#).

(2) The size shown here is an approximation. For the package dimensions with tolerances, see the *Mechanical Data* in [Section 9](#).

## 1.4 Functional Block Diagram

Figure 1-1 shows the functional block diagram.



**Figure 1-1. Functional Block Diagram**

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## 2 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from February 12, 2013 to October 28, 2015	Page
• Document organization and structure changes throughout, including addition of section numbering.....	<u>1</u>
• Added <a href="#">Section 1.2, Applications</a> .....	<u>2</u>
• Added <i>Device Information</i> table .....	<u>2</u>
• Moved functional block diagram to <a href="#">Section 1.4</a> .....	<u>3</u>
• Moved <a href="#">Table 3-1, Family Members</a> , to <a href="#">Section 3, Device Characteristics</a> .....	<u>7</u>
• Added <a href="#">Section 5.2, ESD Ratings</a> .....	<u>12</u>
• Added note to the $C_{VCORE}$ parameter in <a href="#">Section 5.3, Recommended Operating Conditions</a> .....	<u>12</u>
• Added <a href="#">Section 5.8, Thermal Resistance Characteristics</a> .....	<u>17</u>
• Corrected spelling of MRG bits in $f_{MCLK,MRG}$ parameter symbol and description in <a href="#">Section 5.38, Flash Memory</a> .....	<u>38</u>
• Changed the "RF crystal oscillator only" test conditions and added note in <a href="#">Section 5.42, Current Consumption, Reduced-Power Modes</a> .....	<u>39</u>
• Changed the TYP value of the "High-bit transmit frequency" parameter in <a href="#">Section 5.67, Resonant Circuits – LF Front End</a> , from 134.2 to 124.2.....	<u>54</u>
• Changed the limits for the trimming capacitor parameters $CT_{max}$ , $CT1$ , $CT2$ , $CT3$ , $CT4$ , $CT5$ , $CT6$ , and $CT7$ in <a href="#">Section 5.69, Resonant Circuit Capacitor – LF Front End</a> .....	<u>54</u>
• Changed all instances of "bootstrap loader" to "bootloader" .....	<u>64</u>
• Corrected spelling of NMIIFG (added missing "I") in <a href="#">Table 6-10, System Module Interrupt Vector Registers</a> .....	<u>69</u>
• Added <a href="#">Section 8, Device and Documentation Support</a> .....	<u>102</u>
• Added <a href="#">Section 9, Mechanical, Packaging, and Orderable Information</a> .....	<u>104</u>

### 3 Device Characteristics

Table 3-1 summarizes the device characteristics.

**Table 3-1. Family Members**

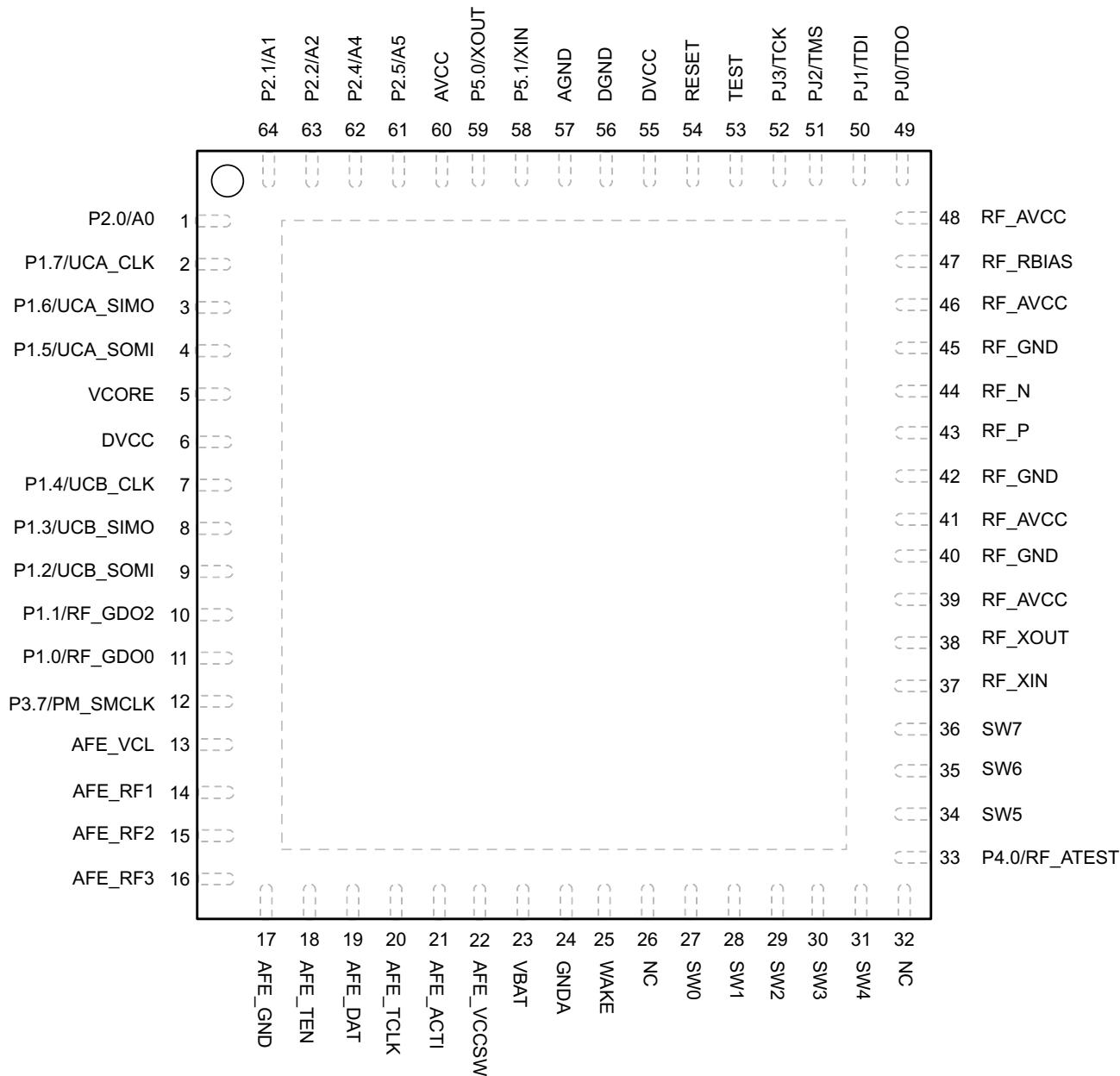
DEVICE	PROGRAM (KB)	SRAM (KB)	EEPROM (Byte)	Timer_A <sup>(1)</sup>	LF INTERFACE		USCI		ADC12_A CHANNELS	Comp_B CHANNELS	I/O	PACKAGE
					TRANSPOUNDER CHANNELS	WAKE RECEIVER CHANNELS	CHANNEL A: UART, LIN, IrDA, SPI	CHANNEL B: SPI, I <sup>2</sup> C				
RF430F5978	32	4	1776	5, 3	3	3	1	1	8 ext, 4 int	8	27	64 RGC

(1) Each number in the sequence represents an instantiation of Timer\_A with its associated number of capture compare registers and PWM output generators available. For example, a number sequence of 5, 3 would represent two instantiations of Timer\_A, the first instantiation having 5 and the second instantiation having 3 capture compare registers and PWM output generators, respectively.

## 4 Terminal Configuration and Functions

## 4.1 Pin Diagram

Figure 4-1 shows the pinout of the 64-pin RGC package.



NOTE: The secondary digital functions on ports P1, P2, and P3 are fully mappable. This pinout shows the default mapping. See [Table 6-8](#) for details.

**Figure 4-1. 64-Pin RGC Package (Top View)**

## 4.2 Signal Descriptions

Table 4-1 describes the signals.

**Table 4-1. Terminal Functions**

TERMINAL		I/O <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
P2.0/PM_CBOUT1/PM_TA1CLK/CB0/A0	1	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Comparator_B output Default mapping: Timer1_A3 clock input Comparator input CB0 Analog input A0 – 12-bit ADC
P1.7/PM_UCA0CLK/PM_UCB0STE	2	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: USCI_A0 clock input/output Default mapping: USCI_B0 SPI slave transmit enable
P1.6/PM_UCA0TXD/PM_UCA0SIMO	3	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: USCI_A0 UART transmit data Default mapping: USCI_A0 SPI slave in/master out
P1.5/PM_UCA0RXD/PM_UCA0SOMI	4	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: USCI_A0 UART receive data Default mapping: USCI_A0 SPI slave out/master in
VCORE	5	S	Regulated core power supply
DVCC	6	S	Digital power supply
P1.4/PM_UCB0CLK/PM_UCA0STE	7	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: USCI_B0 clock input/output Default mapping: USCI_A0 SPI slave transmit enable
P1.3/PM_UCB0SIMO/PM_UCB0SDA	8	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: USCI_B0 SPI slave in/master out Default mapping: USCI_B0 I <sup>2</sup> C data
P1.2/PM_UCB0SOMI/PM_UCB0SCL	9	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: USCI_B0 SPI slave out/master in Default mapping: USCI_B0 I <sup>2</sup> C clock
P1.1/PM_RFGDO2	10	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Radio GDO2 output
P1.0/PM_RFGDO0	11	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: Radio GDO0 output
P3.7/PM_SMCLK	12	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: SMCLK output
AFE_VCL	13	A	Charge capacitor and supply voltage for immobilizer mode
AFE_RF1	14	A	Connection for resonant circuit 1
AFE_RF2	15	A	Connection for resonant circuit 2
AFE_RF3	16	A	Connection for resonant circuit 3
AFE_GND	17		Analog LF front end GND
AFE_TEN	18	I	Test interface enable of analog LF front end
AFE_TDAT	19	I/O	Test interface data of analog LF front end
AFE_TCLK	20	I	Test interface clock of analog LF front end
AFE_ACTI	21	A	Test interface output of analog front end

(1) I = input, O = output, S = supply, G = ground

Table 4-1. Terminal Functions (continued)

TERMINAL		I/O <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
AFE_VCCSW	22	A	Switched power supply buffer (external capacitor)
VBAT	23	S	Supply voltage analog front end
GNDA	24	G	Analog ground
WAKE	25	O	Analog ground
NC	26		Not connected
SW0	27	I	Switch input with internal pullup resistor
SW1	28	I	Switch input with internal pullup resistor
SW2	29	I	Switch input with internal pullup resistor
SW3	30	I	Switch input with internal pullup resistor
SW4	31	I	Switch input with internal pullup resistor
NC	32		Not connected
P4.0	33	I/O	General-purpose digital I/O
SW5	34	I	Switch input with internal pullup resistor
SW6	35	I	Switch input with internal pullup resistor
SW7	36	I	Switch input with internal pullup resistor
RF_XIN	37	I	Input terminal for RF crystal oscillator or external clock input
RF_XOUT	38	O	Output terminal for RF crystal oscillator
RF_AVCC	39	S	Radio analog power supply
RF_GND	40	G	Radio ground
RF_AVCC	41	S	Radio analog power supply
RF_GND	42	G	Radio ground
RF_P	43	RF I/O	Positive RF input to LNA in receive mode Positive RF output from PA in transmit mode
RF_N	44	RF I/O	Negative RF input to LNA in receive mode Negative RF output from PA in transmit mode
RF_GND	45	G	Radio ground
RF_AVCC	46	S	Radio analog power supply
RF_RBIAS	47		External bias resistor for radio reference current
RF_AVCC	48	I/O	Radio analog power supply
PJ.0/TDO	49	I/O	General-purpose digital I/O or test data output port
PJ.1/TDI/TCLK	50	I/O	General-purpose digital I/O or test data input or test clock input
PJ.2/TMS	51	I/O	General-purpose digital I/O or test mode select
PJ.3/TCK	52	I/O	General-purpose digital I/O or test clock
TEST/SBWTC	53	I	Test mode pin – select digital I/O on JTAG pins or Spy-Bi-Wire input clock
<u>RST/NMI/SBWT</u> DIO	54	I/O	Reset input active low
			Nonmaskable interrupt input
			Spy-Bi-Wire data input/output
DVCC	55	S	Digital power supply
DGND	56	G	Digital ground supply
AGND	57	G	Analog ground supply
P5.1/XOUT	58	I/O	General-purpose digital I/O Output terminal of crystal oscillator XT1
P5.0/XIN	59	I/O	General-purpose digital I/O Input terminal for crystal oscillator XT1
AVCC	60	S	Analog power supply

**Table 4-1. Terminal Functions (continued)**

TERMINAL		I/O <sup>(1)</sup>	DESCRIPTION
NAME	NO.		
P2.5/PM_SVMOUT/CB5/A5/ VREF+/VeREF+	61	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: SVM output Comparator input CB5 Analog input A5 – ADC Output of positive reference voltage Input for an external positive reference voltage to the ADC
P2.4/PM_RTCCLK/CB4/A4/ VREF- /VeREF-	62	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: RTCCLK output Comparator input CB4 Analog input A4 – ADC Output of negative reference voltage Input for an external negative reference voltage to the ADC
P2.2/PM_TA1CCR1A/CB2/A2	63	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: TA1 CCR1 compare output/capture input Comparator input CB2 Analog input A2 – ADC
P2.1/PM_TA1CCR0A/CB1/A1	64	I/O	General-purpose digital I/O with port interrupt and mappable secondary function Default mapping: TA1 CCR0 compare output/capture input Comparator input CB1 Analog input A1 – ADC
Exposed die attach pad			Ground supply <b>The exposed die attach pad must be connected to a solid ground plane as this is the ground connection for the chip.</b>

## 5 Specifications

### 5.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Voltage applied at DVCC/VBAT and AVCC pins to V <sub>SS</sub>	−0.3	3.6	V
Voltage applied to any pin (excluding VCORE, RF_P, RF_N, and R_BIAS) <sup>(2)</sup>	−0.3	V <sub>CC</sub> + 0.3 4.1 V Max	V
Voltage applied to VCORE, RF_P, RF_N, and R_BIAS <sup>(2)</sup>	−0.3	2	V
Input RF level at pins RF_P and RF_N		10	dBm
Diode current at any device terminal		±2	mA
Storage temperature <sup>(3)</sup> , T <sub>stg</sub>	−55	125	°C
Maximum junction temperature, T <sub>J</sub>		95	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages referenced to V<sub>SS</sub>.

(3) Higher temperature may be applied during board soldering according to the current JEDEC J-STD-020 specification with peak reflow temperatures not higher than classified on the device label on the shipping boxes or reels.

### 5.2 ESD Ratings

	VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±1000
	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±250

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±1000 V may actually have higher performance.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±250 V may actually have higher performance.

### 5.3 Recommended Operating Conditions

Typical values are specified at V<sub>CC</sub> = 3.3 V and T<sub>A</sub> = 25°C (unless otherwise noted)

	MIN	NOM	MAX	UNIT
V <sub>CC</sub>	PMMCOREVx = 0 (default after POR)	1.8	3.6	V
	PMMCOREVx = 1	2.0	3.6	
V <sub>CC</sub>	PMMCOREVx = 2	2.2	3.6	V
	PMMCOREVx = 3	2.4	3.6	
V <sub>CC</sub>	PMMCOREVx = 2, SVSHRVLx = SVSHRRRLx = 1 or SVSHE = 0	2.0	3.6	V
V <sub>SS</sub>	Supply voltage applied at the exposed die attach VSS and AVSS pin	0		V
T <sub>A</sub>	Operating free-air temperature	−40	85	°C
T <sub>J</sub>	Operating junction temperature	−40	85	°C
C <sub>VCORE</sub>	Recommended capacitor at VCORE <sup>(5)</sup>	470		nF
C <sub>DVCC</sub> / C <sub>VCORE</sub>	Capacitor ratio of capacitor at DVCC to capacitor at VCORE	10		

(1) TI recommends powering AVCC and DVCC from the same source. A maximum difference of 0.3 V between AVCC and DVCC can be tolerated during power up and operation.

(2) Modules may have a different supply voltage range specification. See the specification of the respective module in this data sheet.

(3) The minimum supply voltage is defined by the supervisor SVS levels when it is enabled. See the [Section 5.19](#) threshold parameters for the exact values and further details.

(4) Lowering the high-side SVS level or disabling the high-side SVS might cause the LDO to operate out of regulation, but the core voltage stays within its limits and is still supervised by the low-side SVS to ensure reliable operation.

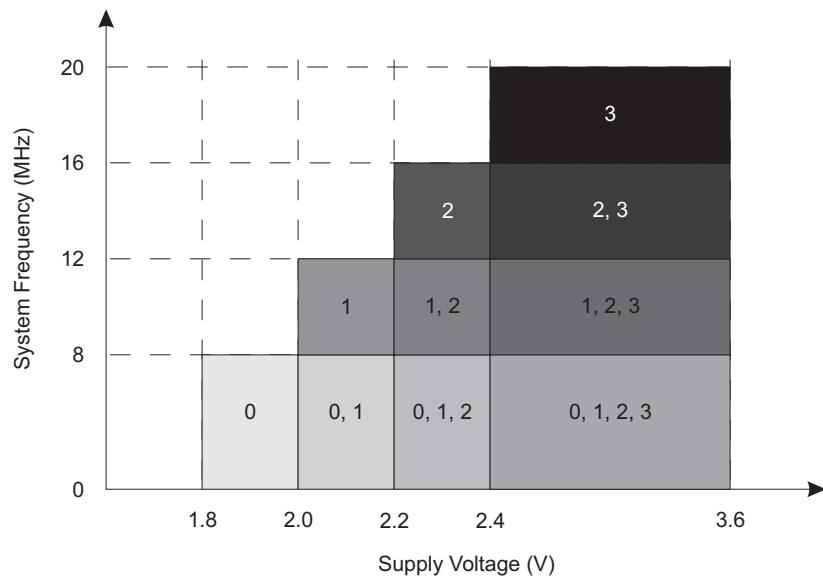
(5) A capacitor tolerance of ±20% or better is required.

## Recommended Operating Conditions (continued)

Typical values are specified at  $V_{CC} = 3.3$  V and  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$f_{\text{SYSTEM}}$	Processor (MCLK) frequency <sup>(6)</sup> (see Figure 5-1)	PMMCOREVx = 0 (default condition)	0	8	MHz
		PMMCOREVx = 1	0	12	
		PMMCOREVx = 2	0	16	
		PMMCOREVx = 3	0	20	
$P_{\text{INT}}$	Internal power dissipation	$V_{CC} \times I_{(\text{DVCC})}$			W
$P_{\text{IO}}$	I/O power dissipation of I/O pins powered by DVCC	$(V_{CC} - V_{IOL}) \times I_{IOL} + V_{IOL} \times I_{IOL}$			W
$P_{\text{MAX}}$	Maximum allowed power dissipation, $P_{\text{MAX}} > P_{\text{IO}} + P_{\text{INT}}$	$(T_J - T_A) / R\theta_{JA}$			W

(6) Modules may have a different maximum input clock specification. See the specification of the respective module in this data sheet.



NOTE: The numbers (0, 1, 2, and 3) in the fields are the supported PMMCOREVx settings.

**Figure 5-1. Maximum System Frequency**

## 5.4 Active Mode Supply Current Into $V_{CC}$ Excluding External Current

over recommended operating free-air temperature (unless otherwise noted)<sup>(1) (2) (3)</sup>

PARAMETER	EXECUTION MEMORY	$V_{CC}$	PMMCOREVx	FREQUENCY ( $f_{DCO} = f_{MCLK} = f_{SMCLK}$ )								UNIT	
				1 MHz		8 MHz		12 MHz		16 MHz			
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX		
$I_{AM}$ , Flash <sup>(4)</sup>	Flash	3 V	0	0.23	0.26	1.35	1.60					mA	
			1	0.25	0.28	1.55		2.30	2.65				
			2	0.27	0.30	1.75		2.60		3.45	3.90		
			3	0.28	0.32	1.85		2.75		3.65			
$I_{AM}$ , RAM <sup>(5)</sup>	RAM	3 V	0	0.18	0.20	0.95	1.10					mA	
			1	0.20	0.22	1.10		1.60	1.85				
			2	0.21	0.24	1.20		1.80		2.40	2.70		
			3	0.22	0.25	1.30		1.90		2.50			

- (1) All inputs are tied to 0 V or to  $V_{CC}$ . Outputs do not source or sink any current.
- (2) The currents are characterized with a Micro Crystal MS1V-T1K crystal with a load capacitance of 12.5 pF. The internal and external load capacitance are chosen to closely match the required 12.5 pF.
- (3) Characterized with program executing typical data processing.  
 $f_{ACLK} = 32786$  Hz,  $f_{DCO} = f_{MCLK} = f_{SMCLK}$  at specified frequency.  
 $XTS = CPUOFF = SCG0 = SCG1 = OSCOFF = SMCLKOFF = 0$ .
- (4) Active mode supply current when program executes in flash at a nominal supply voltage of 3 V.
- (5) Active mode supply current when program executes in RAM at a nominal supply voltage of 3 V.

## 5.5 Typical Characteristics – Active Mode Supply Currents

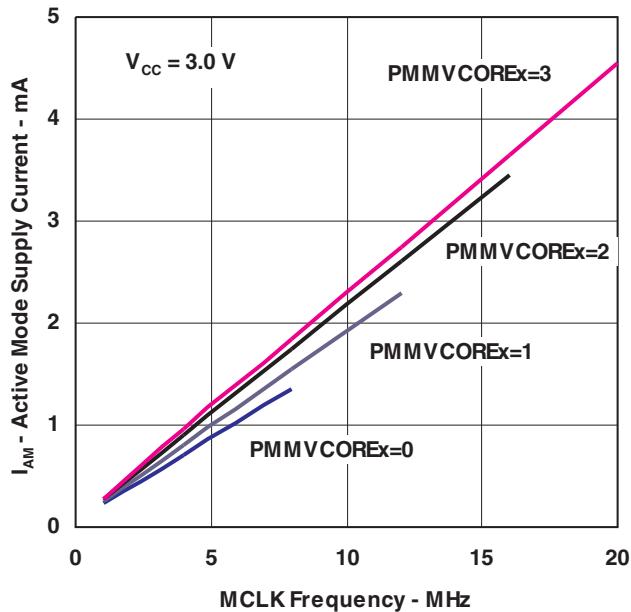


Figure 5-2. Active Mode Supply Current vs MCLK Frequency

## 5.6 Low-Power Mode Supply Currents (Into $V_{CC}$ ) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1) (2)</sup>

PARAMETER	$V_{CC}$	PMMCOREVx	TEMPERATURE ( $T_A$ )								UNIT	
			-40°C		25°C		60°C		85°C			
			TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX		
$I_{LPM0,1MHz}$	Low-power mode 0 <sup>(3) (4)</sup>	2.2 V	0	80	100	80	100	80	100	80	100	$\mu A$
		3 V	3	90	110	90	110	90	110	90	110	
$I_{LPM2}$	Low-power mode 2 <sup>(5) (4)</sup>	2.2 V	0	6.5	11	6.5	11	6.5	11	6.5	11	$\mu A$
		3 V	3	7.5	12	7.5	12	7.5	12	7.5	12	
$I_{LPM3,XT1LF}$	Low-power mode 3, crystal mode <sup>(6) (4)</sup>	3 V	0	1.8	2.0	2.6	3.0	4.0	4.4	5.9		$\mu A$
			1	1.9	2.1		3.2		4.8			
			2	2.0	2.2		3.4		5.1			
			3	2.0	2.2	2.9	3.5	4.8	5.3	7.4		
$I_{LPM3,VLO}$	Low-power mode 3, VLO mode <sup>(7) (4)</sup>	3 V	0	0.9	1.1	2.3	2.1	3.7	3.5	5.6		$\mu A$
			1	1.0	1.2		2.3		3.9			
			2	1.1	1.3		2.5		4.2			
			3	1.1	1.3	2.6	2.6	4.5	4.4	7.1		
$I_{LPM4}$	Low-power mode 4 <sup>(8) (4)</sup>	3 V	0	0.8	1.0	2.2	2.0	3.6	3.4	5.5		$\mu A$
			1	0.9	1.1		2.2		3.8			
			2	1.0	1.2		2.4		4.1			
			3	1.0	1.2	2.5	2.5	4.4	4.3	7.0		

- (1) All inputs are tied to 0 V or to  $V_{CC}$ . Outputs do not source or sink any current.
- (2) The currents are characterized with a Micro Crystal MS1V-T1K crystal with a load capacitance of 12.5 pF. The internal and external load capacitance are chosen to closely match the required 12.5 pF.
- (3) Current for watchdog timer clocked by SMCLK included. ACLK = low frequency crystal operation (XTS = 0, XT1DRIVE<sub>Ex</sub> = 0). CPUOFF = 1, SCG0 = 0, SCG1 = 0, OSCOFF = 0 (LPM0),  $f_{ACLK} = 32768$  Hz,  $f_{MCLK} = 0$  MHz,  $f_{SMCLK} = f_{DCO} = 1$  MHz
- (4) Current for brownout, high side supervisor (SVS<sub>H</sub>) normal mode included. Low-side supervisor (SVS<sub>L</sub>) and low-side monitor (SVM<sub>L</sub>) disabled. High-side monitor (SVM<sub>H</sub>) disabled. RAM retention enabled.
- (5) Current for watchdog timer and RTC clocked by ACLK included. ACLK = low frequency crystal operation (XTS = 0, XT1DRIVE<sub>Ex</sub> = 0). CPUOFF = 1, SCG0 = 0, SCG1 = 1, OSCOFF = 0 (LPM2),  $f_{ACLK} = 32768$  Hz,  $f_{MCLK} = 0$  MHz,  $f_{SMCLK} = f_{DCO} = 0$  MHz, DCO setting = 1 MHz operation, DCO bias generator enabled.
- (6) Current for watchdog timer and RTC clocked by ACLK included. ACLK = low frequency crystal operation (XTS = 0, XT1DRIVE<sub>Ex</sub> = 0). CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 0 (LPM3),  $f_{ACLK} = 32768$  Hz,  $f_{MCLK} = f_{SMCLK} = f_{DCO} = 0$  MHz
- (7) Current for watchdog timer and RTC clocked by ACLK included. ACLK = VLO.
- (8) CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 1 (LPM4),  $f_{DCO} = f_{ACLK} = f_{MCLK} = f_{SMCLK} = 0$  MHz

## 5.7 Typical Characteristics – Low-Power Mode Supply Currents

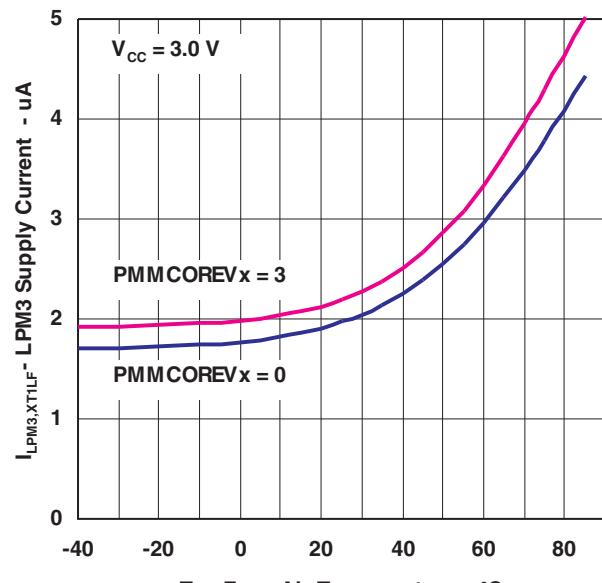


Figure 5-3. LPM3 Supply Current vs Temperature

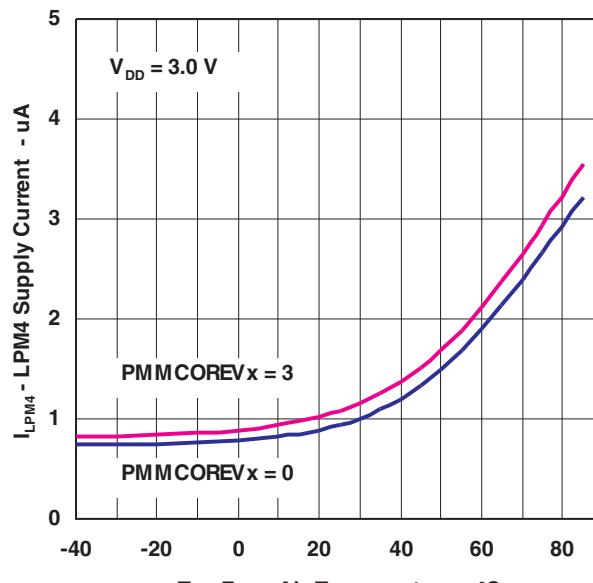


Figure 5-4. LPM4 Supply Current vs Temperature

## 5.8 Thermal Resistance Characteristics

over operating free-air temperature range (unless otherwise noted)

		VALUE	UNIT
$R_{\theta_{JA}}$	Junction-to-ambient thermal resistance, still air <sup>(1)</sup>	VQFN-64 (RGC)	24.6 °C/W
$R_{\theta_{JC(TOP)}}$	Junction-to-case (top) thermal resistance <sup>(2)</sup>		8.8 °C/W
$R_{\theta_{JC(BOT)}}$	Junction-to-case (bottom) thermal resistance <sup>(3)</sup>		0.9 °C/W
$R_{\theta_{JB}}$	Junction-to-board thermal resistance <sup>(4)</sup>		3.8 °C/W
$\Psi_{JB}$	Junction-to-board thermal characterization parameter		3.8 °C/W
$\Psi_{JT}$	Junction-to-top thermal characterization parameter		0.1 °C/W

- (1) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, High-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (2) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (3) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.

## 5.9 Digital Inputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT	
$V_{IT+}$		1.8 V	0.80	1.40		V	
		3 V	1.50	2.10			
$V_{IT-}$		1.8 V	0.45	1.00		V	
		3 V	0.75	1.65			
$V_{hys}$	Input voltage hysteresis ( $V_{IT+} - V_{IT-}$ )	1.8 V	0.3	0.8		V	
		3 V	0.4	1.0			
$R_{Pull}$	Pullup or pulldown resistor	For pullup: $V_{IN} = V_{SS}$ For pulldown: $V_{IN} = V_{CC}$		20	35	50	kΩ
$C_I$	Input capacitance	$V_{IN} = V_{SS}$ or $V_{CC}$			5	pF	
$I_{lkg(Px,y)}$	High-impedance leakage current	(1) (2)	1.8 V, 3 V		±50	nA	
$t_{(int)}$	External interrupt timing (external trigger pulse duration to set interrupt flag) <sup>(3)</sup>	Ports with interrupt capability (see block diagram and terminal function descriptions).	1.8 V, 3 V	20		ns	

- (1) The leakage current is measured with  $V_{SS}$  or  $V_{CC}$  applied to the corresponding pin(s), unless otherwise noted.
- (2) The leakage of the digital port pins is measured individually. The port pin is selected for input and the pullup or pulldown resistor is disabled.
- (3) An external signal sets the interrupt flag every time the minimum interrupt pulse duration  $t_{(int)}$  is met. It may be set by trigger signals shorter than  $t_{(int)}$ .

## 5.10 Digital Outputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	MAX	UNIT
V <sub>OH</sub>	I <sub>(OHmax)</sub> = -1 mA, PxDS.y = 0 <sup>(2)</sup>	1.8 V	V <sub>CC</sub> - 0.25	V <sub>CC</sub>	V
	I <sub>(OHmax)</sub> = -3 mA, PxDS.y = 0 <sup>(3)</sup>		V <sub>CC</sub> - 0.60	V <sub>CC</sub>	
	I <sub>(OHmax)</sub> = -2 mA, PxDS.y = 0 <sup>(2)</sup>	3 V	V <sub>CC</sub> - 0.25	V <sub>CC</sub>	
	I <sub>(OHmax)</sub> = -6 mA, PxDS.y = 0 <sup>(3)</sup>		V <sub>CC</sub> - 0.60	V <sub>CC</sub>	
V <sub>OL</sub>	I <sub>(OLmax)</sub> = 1 mA, PxDS.y = 0 <sup>(2)</sup>	1.8 V	V <sub>SS</sub>	V <sub>SS</sub> + 0.25	V
	I <sub>(OLmax)</sub> = 3 mA, PxDS.y = 0 <sup>(3)</sup>		V <sub>SS</sub>	V <sub>SS</sub> + 0.60	
	I <sub>(OLmax)</sub> = 2 mA, PxDS.y = 0 <sup>(2)</sup>	3 V	V <sub>SS</sub>	V <sub>SS</sub> + 0.25	
	I <sub>(OLmax)</sub> = 6 mA, PxDS.y = 0 <sup>(3)</sup>		V <sub>SS</sub>	V <sub>SS</sub> + 0.60	
V <sub>OH</sub>	I <sub>(OHmax)</sub> = -3 mA, PxDS.y = 1 <sup>(2)</sup>	1.8 V	V <sub>CC</sub> - 0.25	V <sub>CC</sub>	V
	I <sub>(OHmax)</sub> = -10 mA, PxDS.y = 1 <sup>(3)</sup>		V <sub>CC</sub> - 0.60	V <sub>CC</sub>	
	I <sub>(OHmax)</sub> = -5 mA, PxDS.y = 1 <sup>(2)</sup>	3 V	V <sub>CC</sub> - 0.25	V <sub>CC</sub>	
	I <sub>(OHmax)</sub> = -15 mA, PxDS.y = 1 <sup>(3)</sup>		V <sub>CC</sub> - 0.60	V <sub>CC</sub>	
V <sub>OL</sub>	I <sub>(OLmax)</sub> = 3 mA, PxDS.y = 1 <sup>(2)</sup>	1.8 V	V <sub>SS</sub>	V <sub>SS</sub> + 0.25	V
	I <sub>(OLmax)</sub> = 10 mA, PxDS.y = 1 <sup>(3)</sup>		V <sub>SS</sub>	V <sub>SS</sub> + 0.60	
	I <sub>(OLmax)</sub> = 5 mA, PxDS.y = 1 <sup>(2)</sup>	3 V	V <sub>SS</sub>	V <sub>SS</sub> + 0.25	
	I <sub>(OLmax)</sub> = 15 mA, PxDS.y = 1 <sup>(3)</sup>		V <sub>SS</sub>	V <sub>SS</sub> + 0.60	
f <sub>Px,y</sub>	Port output frequency (with load)	C <sub>L</sub> = 20 pF, R <sub>L</sub> <sup>(4)</sup> (5)	V <sub>CC</sub> = 1.8 V, PMMCOREVx = 0	16	MHz
			V <sub>CC</sub> = 3 V, PMMCOREVx = 2	25	
f <sub>Port_CLK</sub>	Clock output frequency	C <sub>L</sub> = 20 pF <sup>(5)</sup>	V <sub>CC</sub> = 1.8 V, PMMCOREVx = 0	16	MHz
			V <sub>CC</sub> = 3 V, PMMCOREVx = 2	25	

- (1) Selecting reduced drive strength may reduce EMI.
- (2) The maximum total current, I<sub>(OHmax)</sub> and I<sub>(OLmax)</sub>, for all outputs combined should not exceed  $\pm 48$  mA to hold the maximum voltage drop specified.
- (3) The maximum total current, I<sub>(OHmax)</sub> and I<sub>(OLmax)</sub>, for all outputs combined should not exceed  $\pm 100$  mA to hold the maximum voltage drop specified.
- (4) A resistive divider with  $2 \times R_1$  between V<sub>CC</sub> and V<sub>SS</sub> is used as load. The output is connected to the center tap of the divider. For full drive strength, R<sub>1</sub> = 550  $\Omega$ . For reduced drive strength, R<sub>1</sub> = 1.6 k $\Omega$ . C<sub>L</sub> = 20 pF is connected to the output to V<sub>SS</sub>.
- (5) The output voltage reaches at least 10% and 90% V<sub>CC</sub> at the specified toggle frequency.

## 5.11 Typical Characteristics – Outputs, Reduced Drive Strength (PxDS.y = 0)

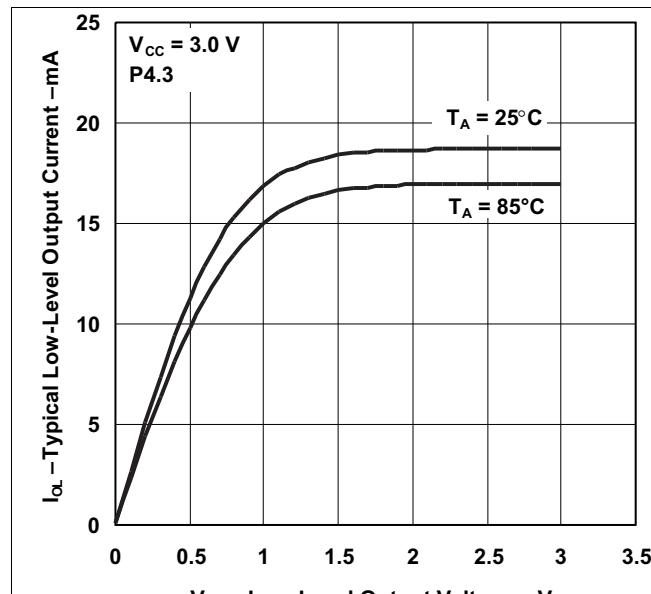


Figure 5-5. Typical Low-Level Output Current vs Low-Level Output Voltage

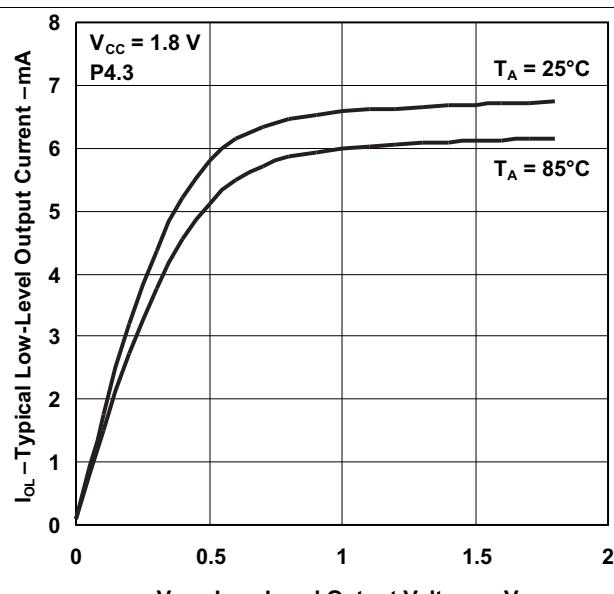


Figure 5-6. Typical Low-Level Output Current vs Low-Level Output Voltage

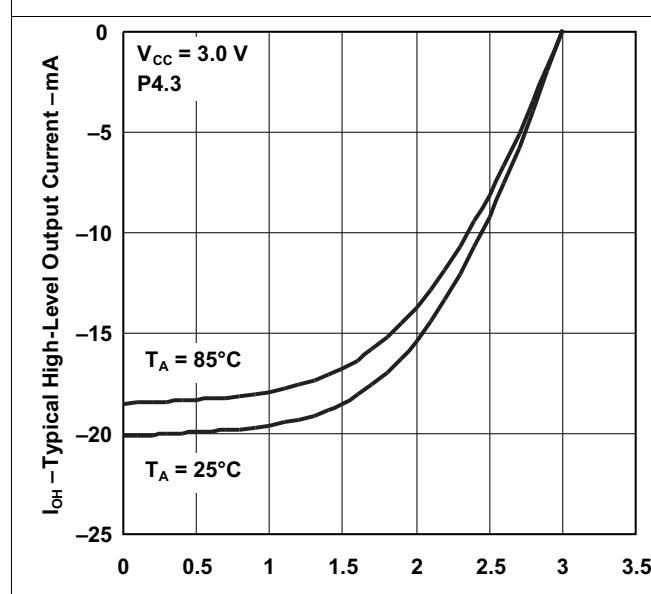


Figure 5-7. Typical High-Level Output Current vs High-Level Output Voltage

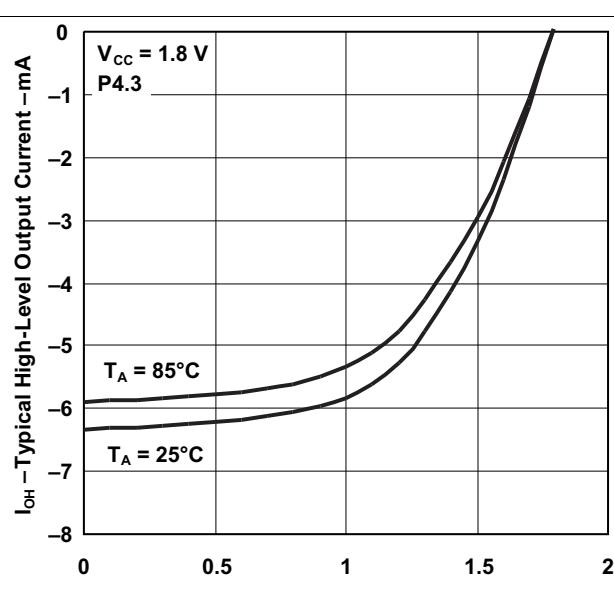
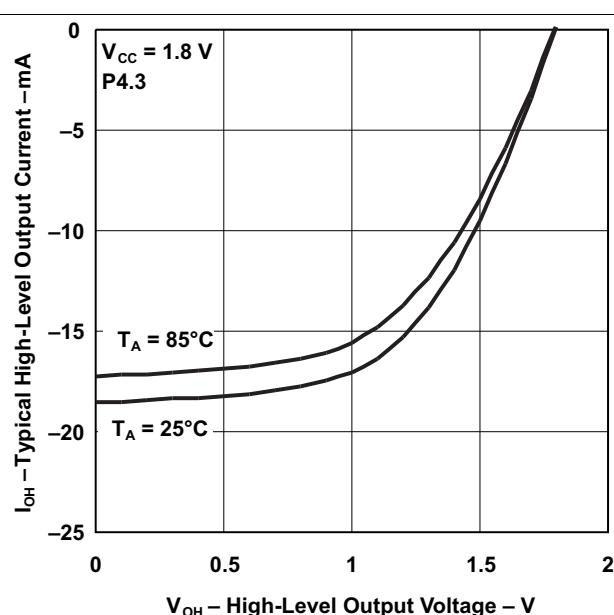
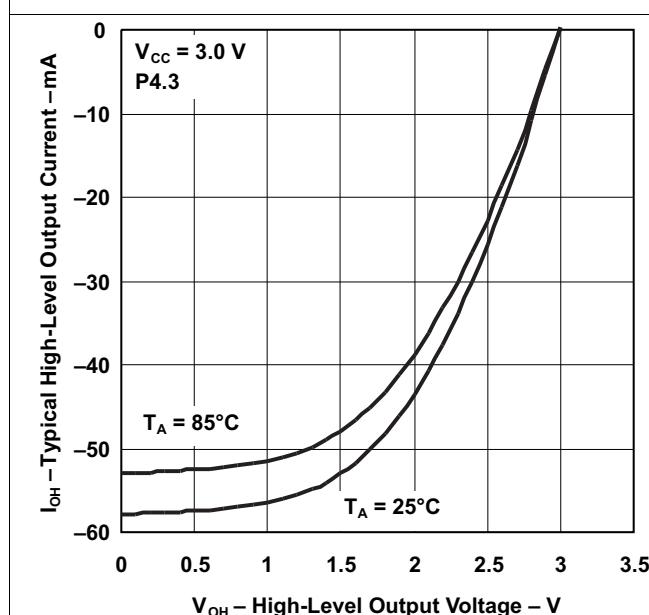
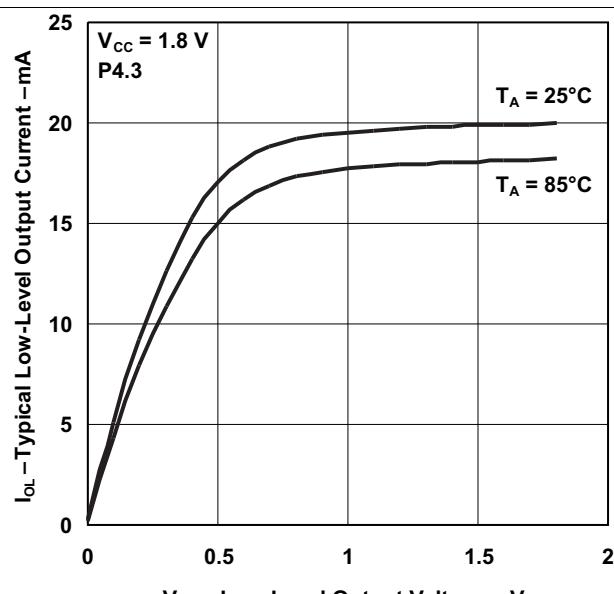
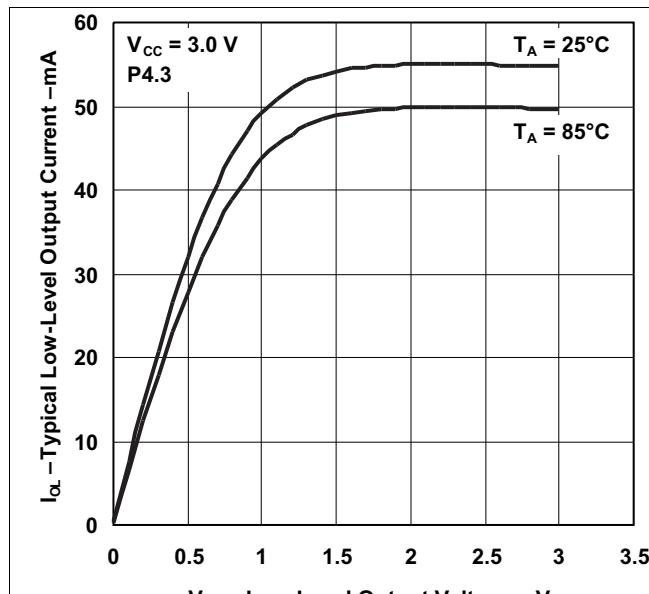


Figure 5-8. Typical High-Level Output Current vs High-Level Output Voltage

## 5.12 Typical Characteristics – Outputs, Full Drive Strength (PxDS.y = 1)



## 5.13 Crystal Oscillator, XT1, Low-Frequency Mode<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
$\Delta I_{DVCC,LF}$ Differential XT1 oscillator crystal current consumption from lowest drive setting, LF mode	$f_{OSC} = 32768$ Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVE <sub>Ex</sub> = 1, $T_A = 25^\circ\text{C}$	3 V		0.075	0.170	$\mu\text{A}$
	$f_{OSC} = 32768$ Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVE <sub>Ex</sub> = 2, $T_A = 25^\circ\text{C}$					
	$f_{OSC} = 32768$ Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVE <sub>Ex</sub> = 3, $T_A = 25^\circ\text{C}$					
$f_{XT1,LF0}$	XT1 oscillator crystal frequency, LF mode			32768		Hz
$f_{XT1,LF,SW}$	XT1 oscillator logic-level square-wave input frequency, LF mode		10	32.768	50	kHz
$OA_{LF}$ Oscillation allowance for LF crystals <sup>(4)</sup>	$XTS = 0, XT1BYPASS = 0, XT1DRIVE_{Ex} = 0, f_{XT1,LF} = 32768$ Hz, $C_{L,eff} = 6$ pF			210	300	$\text{k}\Omega$
	$XTS = 0, XT1BYPASS = 0, XT1DRIVE_{Ex} = 1, f_{XT1,LF} = 32768$ Hz, $C_{L,eff} = 12$ pF					
$C_{L,eff}$ Integrated effective load capacitance, LF mode <sup>(5)</sup>	$XTS = 0, XCAP_x = 0$ <sup>(6)</sup>			2	5.5	$\text{pF}$
	$XTS = 0, XCAP_x = 1$					
	$XTS = 0, XCAP_x = 2$					
	$XTS = 0, XCAP_x = 3$					
Duty cycle, LF mode	$XTS = 0$ , Measured at ACLK, $f_{XT1,LF} = 32768$ Hz			30%	70%	
$f_{Fault,LF}$	Oscillator fault frequency, LF mode <sup>(7)</sup>			10	10000	Hz
$t_{START,LF}$ Start-up time, LF mode	$f_{OSC} = 32768$ Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVE <sub>Ex</sub> = 0, $T_A = 25^\circ\text{C}$ , $C_{L,eff} = 6$ pF	3 V		1000	500	$\text{ms}$
	$f_{OSC} = 32768$ Hz, XTS = 0, XT1BYPASS = 0, XT1DRIVE <sub>Ex</sub> = 3, $T_A = 25^\circ\text{C}$ , $C_{L,eff} = 12$ pF					

- (1) To improve EMI on the XT1 oscillator, the following guidelines should be observed.
  - Keep the trace between the device and the crystal as short as possible.
  - Design a good ground plane around the oscillator pins.
  - Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
  - Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
  - Use assembly materials and processes that avoid any parasitic load on the oscillator XIN and XOUT pins.
  - If conformal coating is used, make sure that it does not induce capacitive or resistive leakage between the oscillator pins.
- (2) When XT1BYPASS is set, XT1 circuits are automatically powered down. Input signal is a digital square wave with parametrics defined in the Schmitt-trigger Inputs section of this datasheet.
- (3) Maximum frequency of operation of the entire device cannot be exceeded.
- (4) Oscillation allowance is based on a safety factor of 5 for recommended crystals. The oscillation allowance is a function of the XT1DRIVE<sub>Ex</sub> settings and the effective load. In general, comparable oscillator allowance can be achieved based on the following guidelines, but should be evaluated based on the actual crystal selected for the application:
  - For XT1DRIVE<sub>Ex</sub> = 0,  $C_{L,eff} \leq 6$  pF
  - For XT1DRIVE<sub>Ex</sub> = 1,  $6 \text{ pF} \leq C_{L,eff} \leq 9$  pF
  - For XT1DRIVE<sub>Ex</sub> = 2,  $6 \text{ pF} \leq C_{L,eff} \leq 10$  pF
  - For XT1DRIVE<sub>Ex</sub> = 3,  $C_{L,eff} \geq 6$  pF
- (5) Includes parasitic bond and package capacitance (approximately 2 pF per pin). Because the PCB adds additional capacitance, TI recommends verifying the correct load by measuring the ACLK frequency. For a correct setup, the effective load capacitance should always match the specification of the used crystal.
- (6) Requires external capacitors at both terminals. Values are specified by crystal manufacturers.
- (7) Frequencies below the MIN specification set the fault flag. Frequencies above the MAX specification do not set the fault flag. Frequencies in between might set the flag.
- (8) Measured with logic-level input frequency but also applies to operation with crystals.

## 5.14 Internal Very-Low-Power Low-Frequency Oscillator (VLO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
f <sub>VLO</sub> VLO frequency	Measured at ACLK	1.8 V to 3.6 V	6	9.4	14	kHz
df <sub>VLO</sub> /dT VLO frequency temperature drift	Measured at ACLK <sup>(1)</sup>	1.8 V to 3.6 V		0.5		%/°C
df <sub>VLO</sub> /dV <sub>CC</sub> VLO frequency supply voltage drift	Measured at ACLK <sup>(2)</sup>	1.8 V to 3.6 V		4		%/V
Duty cycle	Measured at ACLK	1.8 V to 3.6 V	40%	50%	60%	

(1) Calculated using the box method: (MAX(–40°C to 85°C) – MIN(–40°C to 85°C)) / MIN(–40°C to 85°C) / (85°C – (–40°C))

(2) Calculated using the box method: (MAX(1.8 V to 3.6 V) – MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V – 1.8 V)

## 5.15 Internal Reference, Low-Frequency Oscillator (REFO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
I <sub>REFO</sub> REFO oscillator current consumption	T <sub>A</sub> = 25°C	1.8 V to 3.6 V		3		µA
f <sub>REFO</sub> REFO frequency calibrated	Measured at ACLK	1.8 V to 3.6 V		32768		Hz
REFO absolute tolerance calibrated	Full temperature range	1.8 V to 3.6 V		±3.5%		
	T <sub>A</sub> = 25°C	3 V		±1.5%		
df <sub>REFO</sub> /dT REFO frequency temperature drift	Measured at ACLK <sup>(1)</sup>	1.8 V to 3.6 V		0.01		%/°C
df <sub>REFO</sub> /dV <sub>CC</sub> REFO frequency supply voltage drift	Measured at ACLK <sup>(2)</sup>	1.8 V to 3.6 V		1.0		%/V
Duty cycle	Measured at ACLK	1.8 V to 3.6 V	40%	50%	60%	
t <sub>START</sub> REFO start-up time	40%/60% duty cycle	1.8 V to 3.6 V		25		µs

(1) Calculated using the box method: (MAX(–40°C to 85°C) – MIN(–40°C to 85°C)) / MIN(–40°C to 85°C) / (85°C – (–40°C))

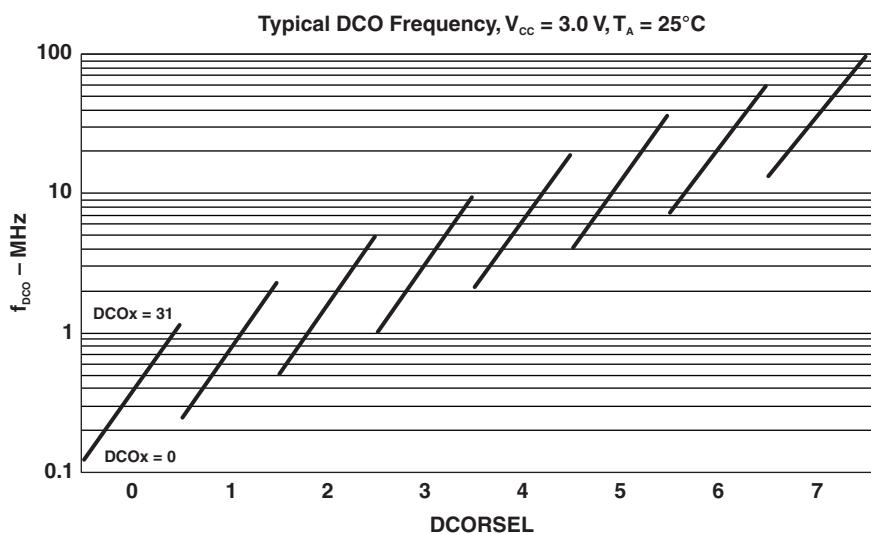
(2) Calculated using the box method: (MAX(1.8 V to 3.6 V) – MIN(1.8 V to 3.6 V)) / MIN(1.8 V to 3.6 V) / (3.6 V – 1.8 V)

## 5.16 DCO Frequency

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{DCO(0,0)}$	DCO frequency (0, 0) <sup>(1)</sup> DCORSELx = 0, DCOx = 0, MODx = 0	0.07	0.20	0.20	MHz
$f_{DCO(0,31)}$	DCO frequency (0, 31) <sup>(1)</sup> DCORSELx = 0, DCOx = 31, MODx = 0	0.70	1.70	1.70	MHz
$f_{DCO(1,0)}$	DCO frequency (1, 0) <sup>(1)</sup> DCORSELx = 1, DCOx = 0, MODx = 0	0.15	0.36	0.36	MHz
$f_{DCO(1,31)}$	DCO frequency (1, 31) <sup>(1)</sup> DCORSELx = 1, DCOx = 31, MODx = 0	1.47	3.45	3.45	MHz
$f_{DCO(2,0)}$	DCO frequency (2, 0) <sup>(1)</sup> DCORSELx = 2, DCOx = 0, MODx = 0	0.32	0.75	0.75	MHz
$f_{DCO(2,31)}$	DCO frequency (2, 31) <sup>(1)</sup> DCORSELx = 2, DCOx = 31, MODx = 0	3.17	7.38	7.38	MHz
$f_{DCO(3,0)}$	DCO frequency (3, 0) <sup>(1)</sup> DCORSELx = 3, DCOx = 0, MODx = 0	0.64	1.51	1.51	MHz
$f_{DCO(3,31)}$	DCO frequency (3, 31) <sup>(1)</sup> DCORSELx = 3, DCOx = 31, MODx = 0	6.07	14.0	14.0	MHz
$f_{DCO(4,0)}$	DCO frequency (4, 0) <sup>(1)</sup> DCORSELx = 4, DCOx = 0, MODx = 0	1.3	3.2	3.2	MHz
$f_{DCO(4,31)}$	DCO frequency (4, 31) <sup>(1)</sup> DCORSELx = 4, DCOx = 31, MODx = 0	12.3	28.2	28.2	MHz
$f_{DCO(5,0)}$	DCO frequency (5, 0) <sup>(1)</sup> DCORSELx = 5, DCOx = 0, MODx = 0	2.5	6.0	6.0	MHz
$f_{DCO(5,31)}$	DCO frequency (5, 31) <sup>(1)</sup> DCORSELx = 5, DCOx = 31, MODx = 0	23.7	54.1	54.1	MHz
$f_{DCO(6,0)}$	DCO frequency (6, 0) <sup>(1)</sup> DCORSELx = 6, DCOx = 0, MODx = 0	4.6	10.7	10.7	MHz
$f_{DCO(6,31)}$	DCO frequency (6, 31) <sup>(1)</sup> DCORSELx = 6, DCOx = 31, MODx = 0	39.0	88.0	88.0	MHz
$f_{DCO(7,0)}$	DCO frequency (7, 0) <sup>(1)</sup> DCORSELx = 7, DCOx = 0, MODx = 0	8.5	19.6	19.6	MHz
$f_{DCO(7,31)}$	DCO frequency (7, 31) <sup>(1)</sup> DCORSELx = 7, DCOx = 31, MODx = 0	60	135	135	MHz
$S_{DCORSEL}$	Frequency step between range DCORSEL and DCORSEL + 1 $S_{RSEL} = f_{DCO(DCORSEL+1,DCO)} / f_{DCO(DCORSEL,DCO)}$	1.2	2.3	2.3	ratio
$S_{DCO}$	Frequency step between tap DCO and DCO + 1 $S_{DCO} = f_{DCO(DCORSEL,DCO+1)} / f_{DCO(DCORSEL,DCO)}$	1.02	1.12	1.12	ratio
	Duty cycle	Measured at SMCLK	40%	50%	60%
$df_{DCO}/dT$	DCO frequency temperature drift	$f_{DCO} = 1$ MHz	0.1	0.1	%/°C
$df_{DCO}/dV_{CC}$	DCO frequency voltage drift	$f_{DCO} = 1$ MHz	1.9	1.9	%/V

(1) When selecting the proper DCO frequency range (DCORSELx), the target DCO frequency,  $f_{DCO}$ , should be set to reside within the range of  $f_{DCO(n, 0),MAX} \leq f_{DCO} \leq f_{DCO(n, 31),MIN}$ , where  $f_{DCO(n, 0),MAX}$  represents the maximum frequency specified for the DCO frequency, range n, tap 0 (DCOx = 0) and  $f_{DCO(n, 31),MIN}$  represents the minimum frequency specified for the DCO frequency, range n, tap 31 (DCOx = 31). This ensures that the target DCO frequency resides within the range selected. It should also be noted that if the actual  $f_{DCO}$  frequency for the selected range causes the FLL or the application to select tap 0 or 31, the DCO fault flag is set to report that the selected range is at its minimum or maximum tap setting.



**Figure 5-13. Typical DCO frequency**

## 5.17 PMM, Brown-Out Reset (BOR)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(DVCC\_BOR\_IT-)}$	$BOR_H$ on voltage, $DV_{CC}$ falling level $ dV_{CC}/dt  < 3 \text{ V/s}$			1.45	V
$V_{(DVCC\_BOR\_IT+)}$	$BOR_H$ off voltage, $DV_{CC}$ rising level $ dV_{CC}/dt  < 3 \text{ V/s}$	0.80	1.30	1.50	V
$V_{(DVCC\_BOR\_hys)}$	$BOR_H$ hysteresis	60		250	mV
$t_{RESET}$	Pulse duration required at $\overline{RST}/\overline{NMI}$ pin to accept a reset		2		$\mu\text{s}$

## 5.18 PMM, Core Voltage

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{CORE3(AM)}$	Core voltage, active mode, $PMMCOREV = 3$ $2.4 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.90		V
$V_{CORE2(AM)}$	Core voltage, active mode, $PMMCOREV = 2$ $2.2 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.80		V
$V_{CORE1(AM)}$	Core voltage, active mode, $PMMCOREV = 1$ $2 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.60		V
$V_{CORE0(AM)}$	Core voltage, active mode, $PMMCOREV = 0$ $1.8 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.40		V
$V_{CORE3(LPM)}$	Core voltage, low-current mode, $PMMCOREV = 3$ $2.4 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.94		V
$V_{CORE2(LPM)}$	Core voltage, low-current mode, $PMMCOREV = 2$ $2.2 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.84		V
$V_{CORE1(LPM)}$	Core voltage, low-current mode, $PMMCOREV = 1$ $2 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.64		V
$V_{CORE0(LPM)}$	Core voltage, low-current mode, $PMMCOREV = 0$ $1.8 \text{ V} \leq DV_{CC} \leq 3.6 \text{ V}$		1.44		V

## 5.19 PMM, SVS High Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVSH)}$	SVSHE = 0, DV <sub>CC</sub> = 3.6 V	0			nA
	SVSHE = 1, DV <sub>CC</sub> = 3.6 V, SVSHFP = 0	200			
	SVSHE = 1, DV <sub>CC</sub> = 3.6 V, SVSHFP = 1	1.5			μA
$V_{(SVSH\_IT-)}$	SVSHE = 1, SVSHRVL = 0	1.53	1.60	1.67	V
	SVSHE = 1, SVSHRVL = 1	1.73	1.80	1.87	
	SVSHE = 1, SVSHRVL = 2	1.93	2.00	2.07	
	SVSHE = 1, SVSHRVL = 3	2.03	2.10	2.17	
$V_{(SVSH\_IT+)}$	SVSHE = 1, SVSMHRRL = 0	1.60	1.70	1.80	V
	SVSHE = 1, SVSMHRRL = 1	1.80	1.90	2.00	
	SVSHE = 1, SVSMHRRL = 2	2.00	2.10	2.20	
	SVSHE = 1, SVSMHRRL = 3	2.10	2.20	2.30	
	SVSHE = 1, SVSMHRRL = 4	2.25	2.35	2.50	
	SVSHE = 1, SVSMHRRL = 5	2.52	2.65	2.78	
	SVSHE = 1, SVSMHRRL = 6	2.85	3.00	3.15	
	SVSHE = 1, SVSMHRRL = 7	2.85	3.00	3.15	
$t_{pd(SVSH)}$	SVSHE = 1, dV <sub>DVCC</sub> /dt = 10 mV/μs, SVSHFP = 1	2.5			μs
	SVSHE = 1, dV <sub>DVCC</sub> /dt = 1 mV/μs, SVSHFP = 0	20			
$t_{(SVSH)}$	SVSHE = 0 → 1, dV <sub>DVCC</sub> /dt = 10 mV/μs, SVSHFP = 1	12.5			μs
	SVSHE = 0 → 1, dV <sub>DVCC</sub> /dt = 1 mV/μs, SVSHFP = 0	100			
$dV_{DVCC}/dt$	DV <sub>CC</sub> rise time	0	1000	V/s	

(1) The SVS<sub>H</sub> settings available depend on the VCORE (PMMCOREVx) setting. See the *Power Management Module and Supply Voltage Supervisor* chapter in the *RF430F5978 User's Guide* ([SLAU378](#)) on recommended settings and usage.

## 5.20 PMM, SVM High Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVMH)}$	SVM <sub>H</sub> current consumption	SVMHE = 0, DV <sub>CC</sub> = 3.6 V		0		nA
		SVMHE = 1, DV <sub>CC</sub> = 3.6 V, SVMHFP = 0		200		
		SVMHE = 1, DV <sub>CC</sub> = 3.6 V, SVMHFP = 1		1.5		μA
$V_{(SVMH)}$	SVM <sub>H</sub> on or off voltage level <sup>(1)</sup>	SVMHE = 1, SVSMHRRRL = 0	1.60	1.70	1.80	V
		SVMHE = 1, SVSMHRRRL = 1	1.80	1.90	2.00	
		SVMHE = 1, SVSMHRRRL = 2	2.00	2.10	2.20	
		SVMHE = 1, SVSMHRRRL = 3	2.10	2.20	2.30	
		SVMHE = 1, SVSMHRRRL = 4	2.25	2.35	2.50	
		SVMHE = 1, SVSMHRRRL = 5	2.52	2.65	2.78	
		SVMHE = 1, SVSMHRRRL = 6	2.85	3.00	3.15	
		SVMHE = 1, SVSMHRRRL = 7	2.85	3.00	3.15	
		SVMHE = 1, SVMHOVPE = 1		3.75		
$t_{pd(SVMH)}$	SVM <sub>H</sub> propagation delay	SVMHE = 1, dV <sub>DVCC</sub> /dt = 10 mV/μs, SVMHFP = 1		2.5		μs
		SVMHE = 1, dV <sub>DVCC</sub> /dt = 1 mV/μs, SVMHFP = 0		20		
$t_{(SVMH)}$	SVM <sub>H</sub> on or off delay time	SVMHE = 0 → 1, dV <sub>DVCC</sub> /dt = 10 mV/μs, SVMHFP = 1		12.5		μs
		SVMHE = 0 → 1, dV <sub>DVCC</sub> /dt = 1 mV/μs, SVMHFP = 0		100		

(1) The SVM<sub>H</sub> settings available depend on the VCORE (PMMCOREVx) setting. See the *Power Management Module and Supply Voltage Supervisor* chapter in the *RF430F5978 User's Guide* ([SLAU378](#)) on recommended settings and usage.

## 5.21 PMM, SVS Low Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVSL)}$	SVS <sub>L</sub> current consumption	SVSLE = 0, PMMCOREV = 2		0		nA
		SVSLE = 1, PMMCOREV = 2, SVSLFP = 0		200		
		SVSLE = 1, PMMCOREV = 2, SVSLFP = 1		1.5		μA
$t_{pd(SVSL)}$	SVS <sub>L</sub> propagation delay	SVSLE = 1, dV <sub>CORE</sub> /dt = 10 mV/μs, SVSLFP = 1		2.5		μs
		SVSLE = 1, dV <sub>CORE</sub> /dt = 1 mV/μs, SVSLFP = 0		20		
$t_{(SVSL)}$	SVS <sub>L</sub> on or off delay time	SVSLE = 0 → 1, dV <sub>CORE</sub> /dt = 10 mV/μs, SVSLFP = 1		12.5		μs
		SVSLE = 0 → 1, dV <sub>CORE</sub> /dt = 1 mV/μs, SVSLFP = 0		100		

## 5.22 PMM, SVM Low Side

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{(SVML)}$	SVM <sub>L</sub> current consumption	SVMLE = 0, PMMCOREV = 2		0		nA
		SVMLE = 1, PMMCOREV = 2, SVMLFP = 0		200		
		SVMLE = 1, PMMCOREV = 2, SVMLFP = 1		1.5		μA
$t_{pd(SVML)}$	SVM <sub>L</sub> propagation delay	SVMLE = 1, $dV_{CORE}/dt = 10 \text{ mV}/\mu\text{s}$ , SVMLFP = 1		2.5		μs
		SVMLE = 1, $dV_{CORE}/dt = 1 \text{ mV}/\mu\text{s}$ , SVMLFP = 0		20		
$t_{(SVML)}$	SVM <sub>L</sub> on or off delay time	SVMLE = 0 → 1, $dV_{CORE}/dt = 10 \text{ mV}/\mu\text{s}$ , SVMLFP = 1		12.5		μs
		SVMLE = 0 → 1, $dV_{CORE}/dt = 1 \text{ mV}/\mu\text{s}$ , SVMLFP = 0		100		

## 5.23 Wake-up Times From Low-Power Modes and Reset

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$t_{WAKE-UP-FAST}$	Wake-up time from LPM2, LPM3, or LPM4 to active mode <sup>(1)</sup>	PMMCOREV = SVSMLRRL = n (where n = 0, 1, 2, or 3), SVSLFP = 1	$f_{MCLK} \geq 4.0 \text{ MHz}$		5		μs
			$f_{MCLK} < 4.0 \text{ MHz}$		6		
$t_{WAKE-UP-SLOW}$	Wake-up time from LPM2, LPM3 or LPM4 to active mode <sup>(2)</sup>	PMMCOREV = SVSMLRRL = n (where n = 0, 1, 2, or 3), SVSLFP = 0			150	165	μs
$t_{WAKE-UP-RESET}$	Wake-up time from $\overline{RST}$ or BOR event to active mode <sup>(3)</sup>				2	3	ms

- (1) This value represents the time from the wake-up event to the first active edge of MCLK. The wake-up time depends on the performance mode of the low-side supervisor (SVS<sub>L</sub>) and low-side monitor (SVM<sub>L</sub>). Fastest wake-up times are possible with SVS<sub>L</sub> and SVM<sub>L</sub> in full performance mode or disabled when operating in AM, LPM0, and LPM1. Various options are available for SVS<sub>L</sub> and SVM<sub>L</sub> while operating in LPM2, LPM3, and LPM4. See the *Power Management Module and Supply Voltage Supervisor* chapter in the *RF430F5978 User's Guide* ([SLAU378](#)).
- (2) This value represents the time from the wake-up event to the first active edge of MCLK. The wake-up time depends on the performance mode of the low-side supervisor (SVS<sub>L</sub>) and low-side monitor (SVM<sub>L</sub>). In this case, the SVS<sub>L</sub> and SVM<sub>L</sub> are in normal mode (low current) mode when operating in AM, LPM0, and LPM1. Various options are available for SVS<sub>L</sub> and SVM<sub>L</sub> while operating in LPM2, LPM3, and LPM4. See the *Power Management Module and Supply Voltage Supervisor* chapter in the *RF430F5978 User's Guide* ([SLAU378](#)).
- (3) This value represents the time from the wake-up event to the reset vector execution.

## 5.24 Timer\_A

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$V_{CC}$	MIN	MAX	UNIT
$f_{TA}$	Timer_A input clock frequency	Internal: SMCLK, ACLK External: TACLK Duty cycle = 50% ±10%	1.8 V, 3 V		25	MHz
$t_{TA,cap}$	Timer_A capture timing	All capture inputs, Minimum pulse duration required for capture		1.8 V, 3 V	20	ns

## 5.25 USCI (UART Mode) Clock Frequency

PARAMETER	CONDITIONS	MIN	MAX	UNIT
$f_{USCI}$ USCI input clock frequency	Internal: SMCLK, ACLK External: UCLK Duty cycle = 50% $\pm 10\%$		$f_{SYSTEM}$	MHz
$f_{BITCLK}$ BITCLK clock frequency (equals baud rate in MBaud)			1	MHz

## 5.26 USCI (UART Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	$V_{CC}$	MIN	TYP	MAX	UNIT
$t_r$ UART receive deglitch time <sup>(1)</sup>	2.2 V	50	600		ns
	3 V	50	600		

(1) Pulses on the UART receive input (UCxRX) shorter than the UART receive deglitch time are suppressed. To ensure that pulses are correctly recognized, their duration should exceed the maximum specification of the deglitch time.

## 5.27 USCI (SPI Master Mode) Clock Frequency

PARAMETER	CONDITIONS	MIN	MAX	UNIT
$f_{USCI}$ USCI input clock frequency	Internal: SMCLK, ACLK Duty cycle = 50% $\pm 10\%$		$f_{SYSTEM}$	MHz

## 5.28 USCI (SPI Master Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1)</sup>  
(see [Figure 5-14](#) and [Figure 5-15](#))

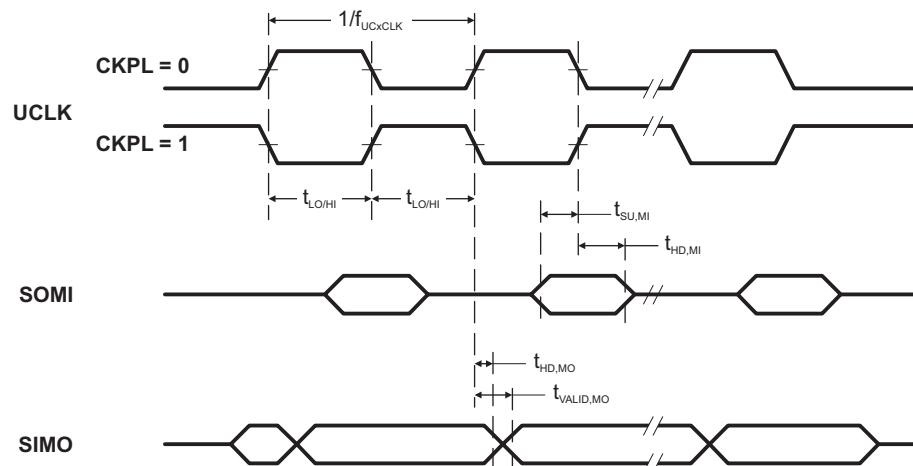
PARAMETER	TEST CONDITIONS	PMMCOREVx	$V_{CC}$	MIN	MAX	UNIT
$t_{SU,MI}$ SOMI input data setup time		0	1.8 V	55		ns
			3 V	38		
		3	2.4 V	30		
			3 V	25		
$t_{HD,MI}$ SOMI input data hold time		0	1.8 V	0		ns
			3 V	0		
		3	2.4 V	0		
			3 V	0		
$t_{VALID,MO}$ SIMO output data valid time <sup>(2)</sup>	UCLK edge to SIMO valid, $C_L = 20 \text{ pF}$	0	1.8 V	20		ns
			3 V	18		
		3	2.4 V	16		
			3 V	15		
$t_{HD,MO}$ SIMO output data hold time <sup>(3)</sup>	$C_L = 20 \text{ pF}$	0	1.8 V	-10		ns
			3 V	-8		
		3	2.4 V	-10		
			3 V	-8		

(1)  $f_{UCxCLK} = 1/2t_{LO/HI}$  with  $t_{LO/HI} \geq \max(t_{VALID,MO(USCI)} + t_{SU,SI(Slave)}, t_{SU,MI(USCI)} + t_{VALID,SO(Slave)})$ .

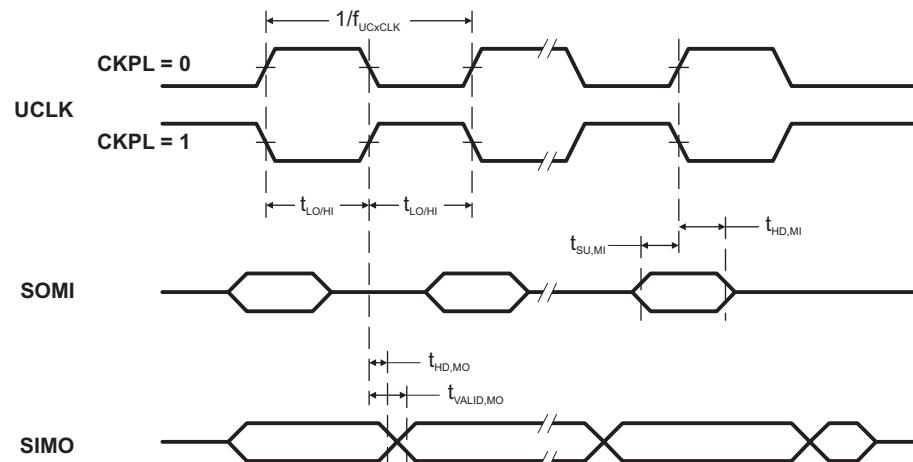
For the slave parameters  $t_{SU,SI(Slave)}$  and  $t_{VALID,SO(Slave)}$ , see the SPI parameters of the attached slave.

(2) Specifies the time to drive the next valid data to the SIMO output after the output changing UCLK clock edge. See the timing diagrams in [Figure 5-14](#) and [Figure 5-15](#).

(3) Specifies how long data on the SIMO output is valid after the output changing UCLK clock edge. Negative values indicate that the data on the SIMO output can become invalid before the output changing clock edge observed on UCLK. See the timing diagrams in [Figure 5-14](#) and [Figure 5-15](#).



**Figure 5-14. SPI Master Mode, CKPH = 0**



**Figure 5-15. SPI Master Mode, CKPH = 1**

## 5.29 USCI (SPI Slave Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1)</sup>  
(see [Figure 5-16](#) and [Figure 5-17](#))

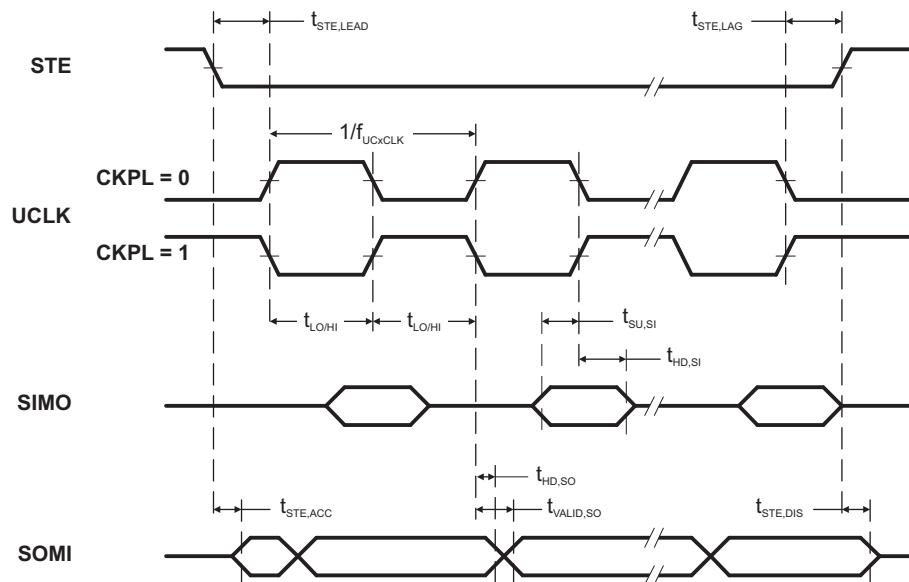
PARAMETER	TEST CONDITIONS	PMMCOREVx	V <sub>CC</sub>	MIN	MAX	UNIT		
t <sub>STE,LEAD</sub> STE lead time, STE low to clock	0	1.8 V	11	ns	3 V	8		
		2.4 V	7					
		3 V	6					
		1.8 V	3		2.4 V	3		
	3	3 V	3					
		2.4 V	3					
		3 V	3					
		1.8 V	66		3 V	50		
t <sub>STE,ACC</sub> STE access time, STE low to SOMI data out	0	2.4 V	36	ns				
		3 V	30					
	3	1.8 V	30	2.4 V	23			
		3 V	23					
	3	2.4 V	16					
		3 V	13					
	0	1.8 V	5	3 V	2			
		3 V	5					
t <sub>HD,SI</sub> SIMO input data setup time	3	2.4 V	2			ns		
		3 V	2					
	0	1.8 V	5	2.4 V	5			
		3 V	5					
	3	2.4 V	5					
		3 V	5					
t <sub>VALID,SO</sub> SOMI output data valid time <sup>(2)</sup>	0	1.8 V	76	ns	3 V	60		
		3 V	60					
	3	2.4 V	44					
		3 V	40					
t <sub>HD,SO</sub> SOMI output data hold time <sup>(3)</sup>	0	1.8 V	18	ns	3 V	12		
		3 V	12					
	3	2.4 V	10					
		3 V	8					

(1)  $f_{UCXCLK} = 1/2t_{LO/HI}$  with  $t_{LO/HI} \geq \max(t_{VALID,MO(\text{Master})} + t_{SU,SI(\text{USCI})}, t_{SU,MI(\text{Master})} + t_{VALID,SO(\text{USCI})})$ .

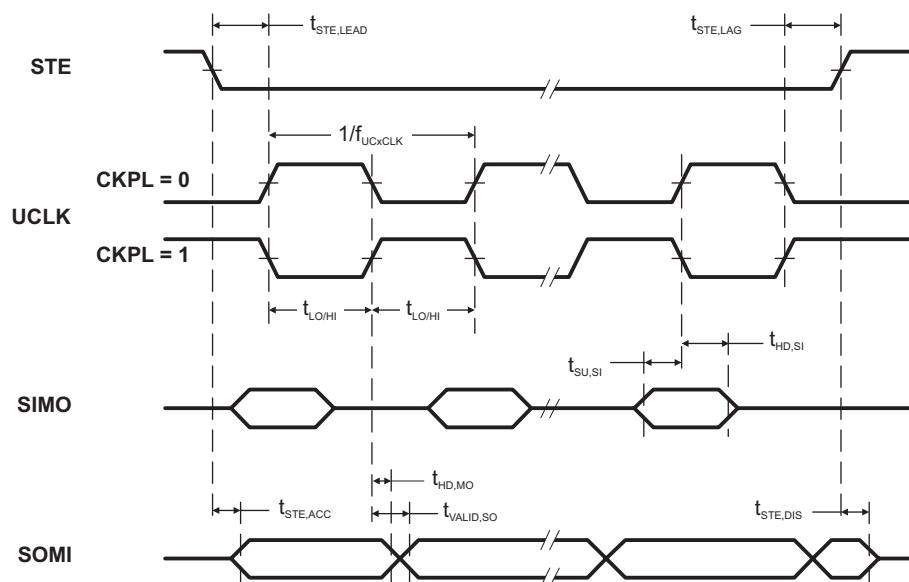
For the master parameters  $t_{SU,MI(\text{Master})}$  and  $t_{VALID,MO(\text{Master})}$ , see the SPI parameters of the attached master.

(2) Specifies the time to drive the next valid data to the SOMI output after the output changing UCLK clock edge. See the timing diagrams in [Figure 5-16](#) and [Figure 5-17](#).

(3) Specifies how long data on the SOMI output is valid after the output changing UCLK clock edge. See the timing diagrams in [Figure 5-16](#) and [Figure 5-17](#).



**Figure 5-16. SPI Slave Mode, CKPH = 0**



**Figure 5-17. SPI Slave Mode, CKPH = 1**

### 5.30 USCI (I<sup>2</sup>C Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 5-18](#))

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	MAX	UNIT
f <sub>USCI</sub> USCI input clock frequency	Internal: SMCLK, ACLK External: UCLK Duty cycle = 50% $\pm 10\%$			f <sub>SYSTEM</sub>	MHz
f <sub>SCL</sub> SCL clock frequency		2.2 V, 3 V	0	400	kHz
t <sub>HD,STA</sub> Hold time (repeated) START	f <sub>SCL</sub> $\leq$ 100 kHz	2.2 V, 3 V	4.0		μs
	f <sub>SCL</sub> > 100 kHz		0.6		
t <sub>SU,STA</sub> Setup time for a repeated START	f <sub>SCL</sub> $\leq$ 100 kHz	2.2 V, 3 V	4.7		μs
	f <sub>SCL</sub> > 100 kHz		0.6		
t <sub>HD,DAT</sub> Data hold time		2.2 V, 3 V	0		ns
t <sub>SU,DAT</sub> Data setup time		2.2 V, 3 V	250		ns
t <sub>SU,STO</sub> Setup time for STOP	f <sub>SCL</sub> $\leq$ 100 kHz	2.2 V, 3 V	4.0		μs
	f <sub>SCL</sub> > 100 kHz		0.6		
t <sub>SP</sub> Pulse duration of spikes suppressed by input filter		2.2 V	50	600	ns
		3 V	50	600	

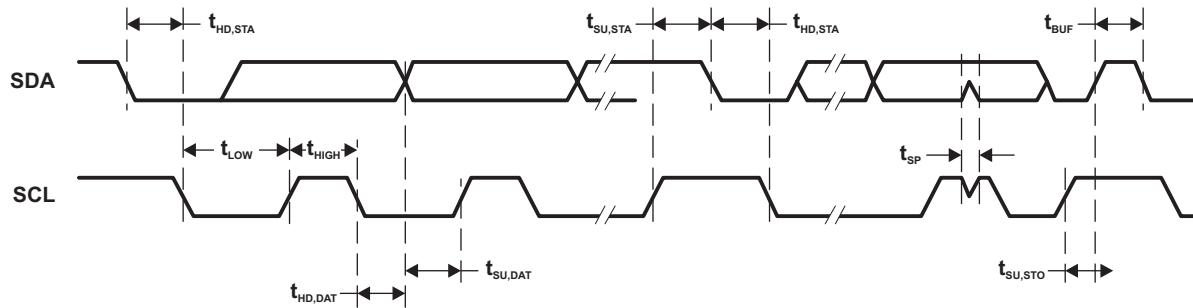


Figure 5-18. I<sup>2</sup>C Mode Timing

### 5.31 12-Bit ADC, Power Supply and Input Range Conditions

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1)</sup>

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT	
AV <sub>CC</sub>	Analog supply voltage, Full performance	AVCC and DVCC are connected together, AVSS and DVSS are connected together, V <sub>(AVSS)</sub> = V <sub>(DVSS)</sub> = 0 V		2.2	3.6	V	
V <sub>(Ax)</sub>	Analog input voltage range <sup>(2)</sup>	All ADC12 analog input pins Ax		0	AV <sub>CC</sub>	V	
I <sub>ADC12_A</sub>	Operating supply current into AVCC terminal <sup>(3)</sup>	f <sub>ADC12CLK</sub> = 5.0 MHz, ADC12ON = 1, REFON = 0, SHT0 = 0, SHT1 = 0, ADC12DIV = 0	2.2 V	125	155	μA	
			3 V	150	220		
C <sub>I</sub>	Input capacitance	Only one terminal Ax can be selected at one time	2.2 V	20	25	pF	
R <sub>I</sub>	Input MUX ON resistance	0 V ≤ V <sub>Ax</sub> ≤ AV <sub>CC</sub>		10	200	1900	Ω

(1) The leakage current is specified by the digital I/O input leakage.

(2) The analog input voltage range must be within the selected reference voltage range V<sub>R+</sub> to V<sub>R-</sub> for valid conversion results. If the reference voltage is supplied by an external source or if the internal reference voltage is used and REFOUT = 1, then decoupling capacitors are required. See [Section 5.35](#) and [Section 5.36](#).

(3) The internal reference supply current is not included in current consumption parameter I<sub>ADC12\_A</sub>.

### 5.32 12-Bit ADC, Timing Parameters

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT	
f <sub>ADC12CLK</sub>	For specified performance of ADC12 linearity parameters	2.2 V, 3 V	0.45	4.8	5.4	MHz	
f <sub>ADC12OSC</sub>	Internal ADC12 oscillator <sup>(1)</sup>	ADC12DIV = 0, f <sub>ADC12CLK</sub> = f <sub>ADC12OSC</sub>	2.2 V, 3 V	4.2	4.8	5.4	MHz
t <sub>CONVERT</sub>	Conversion time	REFON = 0, Internal oscillator, f <sub>ADC12OSC</sub> = 4.2 MHz to 5.4 MHz	2.2 V, 3 V	2.4	3.1	μs	
		External f <sub>ADC12CLK</sub> from ACLK, MCLK or SMCLK, ADC12SSEL ≠ 0			(2)		
t <sub>Sample</sub>	Sampling time	R <sub>S</sub> = 400 Ω, R <sub>I</sub> = 1000 Ω, C <sub>I</sub> = 30 pF, τ = [R <sub>S</sub> + R <sub>I</sub> ] × C <sub>I</sub> <sup>(3)</sup>	2.2 V, 3 V	1000		ns	

(1) The ADC12OSC is sourced directly from MODOSC inside the UCS.

(2) 13 × ADC12DIV × 1/f<sub>ADC12CLK</sub>

(3) Approximately ten Tau (τ) are needed to get an error of less than ±0.5 LSB:

$$t_{\text{Sample}} = \ln(2^{n+1}) \times (R_S + R_I) \times C_I + 800 \text{ ns, where } n = \text{ADC resolution} = 12, R_S = \text{external source resistance}$$

### 5.33 12-Bit ADC, Linearity Parameters

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
E <sub>I</sub>	1.4 V ≤ (V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> )min ≤ 1.6 V	2.2 V, 3 V		±2		LSB
	1.6 V < (V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> )min ≤ V <sub>AVCC</sub>			±1.7		
E <sub>D</sub>	(V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> )min ≤ (V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> ), C <sub>VREF+</sub> = 20 pF	2.2 V, 3 V		±1.0		LSB
E <sub>O</sub>	(V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> )min ≤ (V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> ), Internal impedance of source R <sub>S</sub> < 100 Ω, C <sub>VREF+</sub> = 20 pF	2.2 V, 3 V		±1.0	±2.0	LSB
E <sub>G</sub>	(V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> )min ≤ (V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> ), C <sub>VREF+</sub> = 20 pF	2.2 V, 3 V		±1.0	±2.0	LSB
E <sub>T</sub>	(V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> )min ≤ (V <sub>eREF+</sub> – V <sub>REF-</sub> /V <sub>eREF-</sub> ), C <sub>VREF+</sub> = 20 pF	2.2 V, 3 V		±1.4	±3.5	LSB

### 5.34 12-Bit ADC, Temperature Sensor and Built-In $V_{MID}$ <sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$V_{CC}$	MIN	TYP	MAX	UNIT
$V_{SENSOR}$	See <sup>(2)</sup> (3)	ADC12ON = 1, INCH = 0Ah, $T_A = 0^\circ\text{C}$	2.2 V	680			mV
			3 V	680			
$TC_{SENSOR}$	See <sup>(3)</sup>	ADC12ON = 1, INCH = 0Ah	2.2 V	2.25			$\text{mV}/^\circ\text{C}$
			3 V	2.25			
$t_{SENSOR(sample)}$	Sample time required if channel 10 is selected <sup>(4)</sup>	ADC12ON = 1, INCH = 0Ah, Error of conversion result $\leq 1$ LSB	2.2 V	100			$\mu\text{s}$
			3 V	100			
$V_{MID}$	AV <sub>CC</sub> divider at channel 11, $V_{AVCC}$ factor	ADC12ON = 1, INCH = 0Bh		0.48	0.5	0.52	$V_{AVCC}$
	AV <sub>CC</sub> divider at channel 11	ADC12ON = 1, INCH = 0Bh	2.2 V	1.06	1.1	1.14	V
$t_{V_{MID}(sample)}$	Sample time required if channel 11 is selected <sup>(6)</sup>	ADC12ON = 1, INCH = 0Bh, Error of conversion result $\leq 1$ LSB	3 V	1.44	1.5	1.56	
			2.2 V, 3 V	1000			ns

- (1) The temperature sensor is provided by the REF module. See the REF module parametric,  $I_{REF+}$ , regarding the current consumption of the temperature sensor.
- (2) The temperature sensor offset can be significant. TI recommends a single-point calibration to minimize the offset error of the built-in temperature sensor.
- (3) The device descriptor structure contains calibration values for  $30^\circ\text{C} \pm 3^\circ\text{C}$  and  $85^\circ\text{C} \pm 3^\circ\text{C}$  for each of the available reference voltage levels. The sensor voltage can be computed as  $V_{SENSE} = TC_{SENSOR} * (\text{Temperature}, {}^\circ\text{C}) + V_{SENSOR}$ , where  $TC_{SENSOR}$  and  $V_{SENSOR}$  can be computed from the calibration values for higher accuracy.
- (4) The typical equivalent impedance of the sensor is 51 k $\Omega$ . The sample time required includes the sensor-on time  $t_{SENSOR(on)}$ .
- (5) The on-time  $t_{V_{MID}(on)}$  is included in the sampling time  $t_{V_{MID}(sample)}$ ; no additional on time is needed.

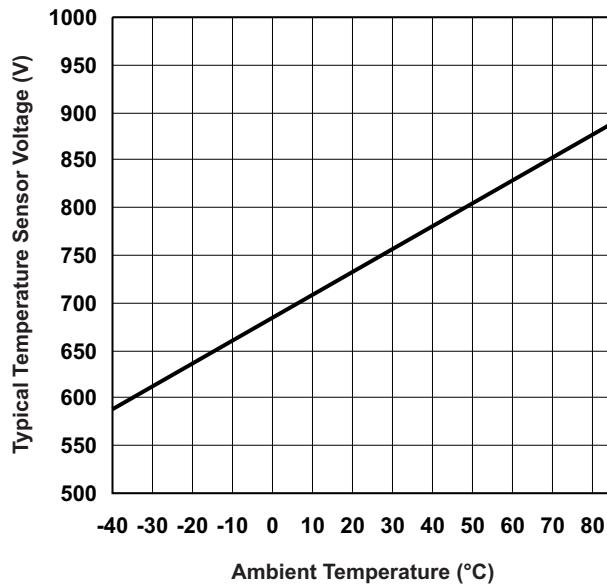


Figure 5-19. Typical Temperature Sensor Voltage

## 5.35 REF, External Reference

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1)</sup>

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>eREF+</sub>	Positive external reference voltage input	V <sub>eREF+</sub> > V <sub>REF-/V<sub>eREF-</sub></sub> <sup>(2)</sup>		1.4	AV <sub>CC</sub>	V
V <sub>REF-/V<sub>eREF-</sub></sub>	Negative external reference voltage input	V <sub>eREF+</sub> > V <sub>REF-/V<sub>eREF-</sub></sub> <sup>(3)</sup>		0	1.2	V
(V <sub>eREF+</sub> – V <sub>REF-/V<sub>eREF-</sub></sub> )	Differential external reference voltage input	V <sub>eREF+</sub> > V <sub>REF-/V<sub>eREF-</sub></sub> <sup>(4)</sup>		1.4	AV <sub>CC</sub>	V
I <sub>V<sub>eREF+</sub></sub> I <sub>V<sub>REF-/V<sub>eREF-</sub></sub></sub>	Static input current	1.4 V ≤ V <sub>eREF+</sub> ≤ V <sub>AVCC</sub> , V <sub>eREF-</sub> = 0 V, f <sub>ADC12CLK</sub> = 5 MHz, ADC12SHTx = 1h, Conversion rate 200ksps	2.2 V, 3 V	±8.5	±26	μA
		1.4 V ≤ V <sub>eREF+</sub> ≤ V <sub>AVCC</sub> , V <sub>eREF-</sub> = 0 V f <sub>ADC12CLK</sub> = 5 MHz, ADC12SHTx = 8h, Conversion rate 20 ksps	2.2 V, 3 V		±1	
C <sub>V<sub>REF±</sub></sub>	Capacitance at V <sub>REF+</sub> or V <sub>REF-</sub> terminal, external reference <sup>(5)</sup>			10		μF

- (1) The external reference is used during ADC conversion to charge and discharge the capacitance array. The input capacitance, C<sub>i</sub>, is also the dynamic load for an external reference during conversion. The dynamic impedance of the reference supply should follow the recommendations on analog-source impedance to allow the charge to settle for 12-bit accuracy.
- (2) The accuracy limits the minimum positive external reference voltage. Lower reference voltage levels may be applied with reduced accuracy requirements.
- (3) The accuracy limits the maximum negative external reference voltage. Higher reference voltage levels may be applied with reduced accuracy requirements.
- (4) The accuracy limits minimum external differential reference voltage. Lower differential reference voltage levels may be applied with reduced accuracy requirements.
- (5) Two decoupling capacitors, 10 μF and 100 nF, should be connected to V<sub>REF</sub> to decouple the dynamic current required for an external reference source if it is used for the ADC12\_A. See also the *RF430F5978 User's Guide* ([SLAU378](#)).

## 5.36 REF, Built-In Reference

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1)</sup>

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>REF+</sub>	REFVSEL = 2 for 2.5 V, REFON = REFOUT = 1, I <sub>VREF+</sub> = 0 A	3 V		2.41	±1.5%	V
	REFVSEL = 1 for 2 V, REFON = REFOUT = 1, I <sub>VREF+</sub> = 0 A	3 V		1.93	±1.5%	
	REFVSEL = 0 for 1.5 V, REFON = REFOUT = 1, I <sub>VREF+</sub> = 0 A	2.2 V, 3 V		1.45	±1.5%	
AV <sub>CC(min)</sub>	REFVSEL = 0 for 1.5 V, reduced performance			1.8		V
	REFVSEL = 0 for 1.5 V			2.2		
	REFVSEL = 1 for 2 V			2.3		
	REFVSEL = 2 for 2.5 V			2.8		
I <sub>REF+</sub>	REFON = 1, REFOUT = 0, REFBURST = 0	3 V	100	140	μA	μA
	REFON = 1, REFOUT = 1, REFBURST = 0	3 V	0.9	1.5	mA	
I <sub>L(VREF+)</sub>	REFVSEL = (0, 1, or 2), I <sub>VREF+</sub> = +10 μA–1000 μA, AV <sub>CC</sub> = AV <sub>CC(min)</sub> for each reference level, REFVSEL = (0, 1, or 2), REFON = REFOUT = 1				2500	μV/mA
C <sub>VREF±</sub>	Capacitance at VREF+ and VREF- terminals, internal reference	REFON = REFOUT = 1		20	100	pF
TC <sub>REF+</sub>	I <sub>VREF+</sub> = 0 A, REFVSEL = (0, 1, or 2), REFON = 1, REFOUT = 0 or 1			30	50	ppm/ °C
PSRR_DC	AV <sub>CC</sub> = AV <sub>CC(min)</sub> to AV <sub>CC(max)</sub> , T <sub>A</sub> = 25°C, REFVSEL = (0, 1, or 2), REFON = 1, REFOUT = 0 or 1			120	300	μV/V
PSRR_AC	AV <sub>CC</sub> = AV <sub>CC(min)</sub> to AV <sub>CC(max)</sub> , T <sub>A</sub> = 25°C, f = 1 kHz, ΔVpp = 100 mV, REFVSEL = 0, 1, or 2, REFON = 1, REFOUT = 0 or 1			6.4		mV/V
t <sub>SETTLE</sub>	AV <sub>CC</sub> = AV <sub>CC(min)</sub> to AV <sub>CC(max)</sub> , REFVSEL = (0, 1, or 2), REFOUT = 0, REFON = 0 → 1				75	μs
	AV <sub>CC</sub> = AV <sub>CC(min)</sub> to AV <sub>CC(max)</sub> , C <sub>VREF</sub> = C <sub>VREF(max)</sub> , REFVSEL = (0, 1, or 2), REFON = 1, REFOUT = 0 → 1				75	

- (1) The reference is supplied to the ADC by the REF module and is buffered locally inside the ADC. The ADC uses two internal buffers, one smaller and one larger for driving the V<sub>REF+</sub> terminal. When REFOUT = 1, the reference is available at the V<sub>REF+</sub> terminal, as well as, used as the reference for the conversion and utilizes the larger buffer. When REFOUT = 0, the reference is only used as the reference for the conversion and utilizes the smaller buffer.
- (2) The internal reference current is supplied through the AVCC terminal. Consumption is independent of the ADC12ON control bit, unless a conversion is active. The REFON bit enables to settle the built-in reference before starting an A/D conversion. REFOUT = 0 represents the current contribution of the smaller buffer. REFOUT = 1 represents the current contribution of the larger buffer without external load.
- (3) The temperature sensor is provided by the REF module. Its current is supplied through the AVCC terminal and is equivalent to I<sub>REF+</sub> with REFON = 1 and REFOUT = 0.
- (4) Contribution only due to the reference and buffer including package. This does not include resistance due to PCB trace, etc.
- (5) Calculated using the box method: (MAX(–40°C to 85°C) – MIN(–40°C to 85°C)) / MIN(–40°C to 85°C)/(85°C – (–40°C)).
- (6) The condition is that the error in a conversion started after t<sub>REFON</sub> is less than ±0.5 LSB. The settling time depends on the external capacitive load when REFOUT = 1.

### 5.37 Comparator B

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.8	3.6		V
I <sub>AVCC_COMP</sub>	Comparator operating supply current into AVCC, Excludes reference resistor ladder	CBPWRMD = 00	1.8 V		40	μA
			2.2 V		30	
			3 V		40	
		CBPWRMD = 01	2.2 V, 3 V		10	
		CBPWRMD = 10	2.2 V, 3 V		0.1	
I <sub>AVCC_REF</sub>	Quiescent current of local reference voltage amplifier into AVCC	CBREFACC = 1, CBREFLx = 01			22	μA
V <sub>IC</sub>	Common mode input range		0	V <sub>CC</sub> –1		V
V <sub>OFFSET</sub>	Input offset voltage	CBPWRMD = 00			±20	mV
		CBPWRMD = 01, 10			±10	
C <sub>IN</sub>	Input capacitance			5		pF
R <sub>SIN</sub>	Series input resistance	ON - switch closed		3	4	kΩ
		OFF - switch opened		30		MΩ
t <sub>PD</sub>	Propagation delay, response time	CBPWRMD = 00, CBF = 0			450	ns
		CBPWRMD = 01, CBF = 0			600	
		CBPWRMD = 10, CBF = 0			50	
t <sub>PD,filter</sub>	Propagation delay with filter active	CBPWRMD = 00, CBON = 1, CBF = 1, CBFDLY = 00		0.35	0.6	1.0
		CBPWRMD = 00, CBON = 1, CBF = 1, CBFDLY = 01		0.6	1.0	1.8
		CBPWRMD = 00, CBON = 1, CBF = 1, CBFDLY = 10		1.0	1.8	3.4
		CBPWRMD = 00, CBON = 1, CBF = 1, CBFDLY = 11		1.8	3.4	6.5
t <sub>EN_CMP</sub>	Comparator enable time, settling time	CBON = 0 to CBON = 1, CBPWRMD = 00, 01, 10			1	2
t <sub>EN_REF</sub>	Resistor reference enable time	CBON = 0 to CBON = 1			0.3	1.5
V <sub>CB_REF</sub>	Reference voltage for a given tap	VIN = reference into resistor ladder, n = 0 to 31		VIN × (n + 1) / 32		V

### 5.38 Flash Memory

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	T <sub>J</sub>	MIN	TYP	MAX	UNIT
DV <sub>CC(PGM/ERASE)</sub> Program and erase supply voltage		1.8		3.6	V
I <sub>PGM</sub> Average supply current from DVCC during program			3	5	mA
I <sub>ERASE</sub> Average supply current from DVCC during erase			2	6.5	mA
I <sub>MERASE</sub> , I <sub>BANK</sub> Average supply current from DVCC during mass erase or bank erase			2	6.5	mA
t <sub>CPT</sub> Cumulative program time <sup>(1)</sup>				16	ms
Program and erase endurance		10 <sup>4</sup>	10 <sup>5</sup>		cycles
t <sub>Retention</sub> Data retention duration	25°C	100			years
t <sub>Word</sub> Word or byte program time <sup>(2)</sup>		64	85	μs	
t <sub>Block, 0</sub> Block program time for first byte or word <sup>(2)</sup>		49	65	μs	
t <sub>Block, 1–(N–1)</sub> Block program time for each additional byte or word, except for last byte or word <sup>(2)</sup>		37	49	μs	
t <sub>Block, N</sub> Block program time for last byte or word <sup>(2)</sup>		55	73	μs	
t <sub>Erase</sub> Erase time for segment erase, mass erase, and bank erase when available <sup>(2)</sup>		23	32	ms	
f <sub>MCLK,MRG</sub> MCLK frequency in marginal read mode (FCTL4.MRG0 = 1 or FCTL4.MRG1 = 1)		0	1	MHz	

(1) The cumulative program time must not be exceeded when writing to a 128-byte flash block. This parameter applies to all programming methods: individual word or byte write and block write modes.

(2) These values are hardwired into the state machine of the flash controller.

### 5.39 JTAG and Spy-Bi-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
f <sub>SBW</sub> Spy-Bi-Wire input frequency	2.2 V, 3 V	0		20	MHz
t <sub>SBW,Low</sub> Spy-Bi-Wire low clock pulse duration	2.2 V, 3 V	0.025		15	μs
t <sub>SBW,En</sub> Spy-Bi-Wire enable time (TEST high to acceptance of first clock edge) <sup>(1)</sup>	2.2 V, 3 V			1	μs
t <sub>SBW,Rst</sub> Spy-Bi-Wire return to normal operation time		15		100	μs
f <sub>TCK</sub> TCK input frequency to 4-wire JTAG <sup>(2)</sup>	2.2 V	0		5	MHz
	3 V	0		10	MHz
R <sub>internal</sub> Internal pulldown resistance on TEST	2.2 V, 3 V	45	60	80	kΩ

(1) Tools that access the Spy-Bi-Wire interface must wait for the minimum t<sub>SBW,En</sub> time after pulling the TEST/SBWTCK pin high before applying the first SBWTCK clock edge.

(2) f<sub>TCK</sub> may be restricted to meet the timing requirements of the module selected.

## 5.40 RF1A CC1101 Radio Parameters

**Table 5-1. Recommended Operating Conditions**

		MIN	NOM	MAX	UNIT
$V_{CC}$	Supply voltage range during radio operation	2.0	3.6		V
PMMCOREVx	Core voltage range, PMMCOREVx setting during radio operation	2	3		
RF frequency range		300	348		MHz
		389 <sup>(1)</sup>	464		
		779	928		
Data rate	2-FSK	0.6	500		kBaud
	2-GFSK, OOK, and ASK	0.6	250		
	(Shaped) MSK (also known as differential offset QPSK) <sup>(2)</sup>	26	500		
RF crystal frequency		26	26	27	MHz
RF crystal tolerance	Total tolerance including initial tolerance, crystal loading, aging and temperature dependency. <sup>(3)</sup>	±40			ppm
RF crystal load capacitance		10	13	20	pF
RF crystal effective series resistance		100			Ω

(1) If using a 27-MHz crystal, the lower frequency limit for this band is 392 MHz.

(2) If using optional Manchester encoding, the data rate in kbps is half the baud rate.

(3) The acceptable crystal tolerance depends on frequency band, channel bandwidth, and spacing. Also see design note *DN005 -- CC11xx Sensitivity versus Frequency Offset and Crystal Accuracy* ([SWRA122](#)).

## 5.41 RF Crystal Oscillator, XT2

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER	MIN	TYP	MAX	UNIT
Start-up time <sup>(2)</sup>	150	810		μs
Duty cycle	45%	50%	55%	

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

(2) The start-up time depends to a very large degree on the crystal that is used.

## 5.42 Current Consumption, Reduced-Power Modes

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Current consumption	RF crystal oscillator only <sup>(2)</sup>			100	μA
	IDLE state (including RF crystal oscillator)			1.7	mA
	FSTXON state (only the frequency synthesizer is running) <sup>(3)</sup>			9.5	mA

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

(2) To measure the current, follow this sequence:

- Enable XT2 with `XOSC_FORCE_ON = 1`.
- Set radio to sleep mode.
- Disable XT2 clock requests from any module.

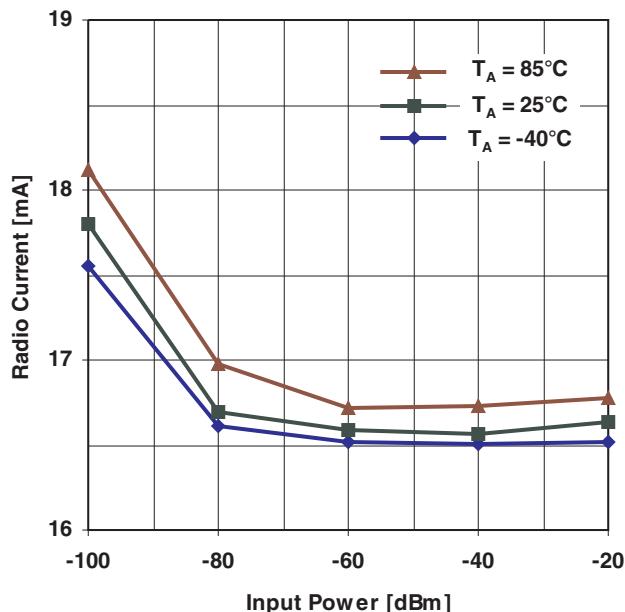
(3) This current consumption is also representative of other intermediate states when going from IDLE to RX or TX, including the calibration state.

## 5.43 Current Consumption, Receive Mode

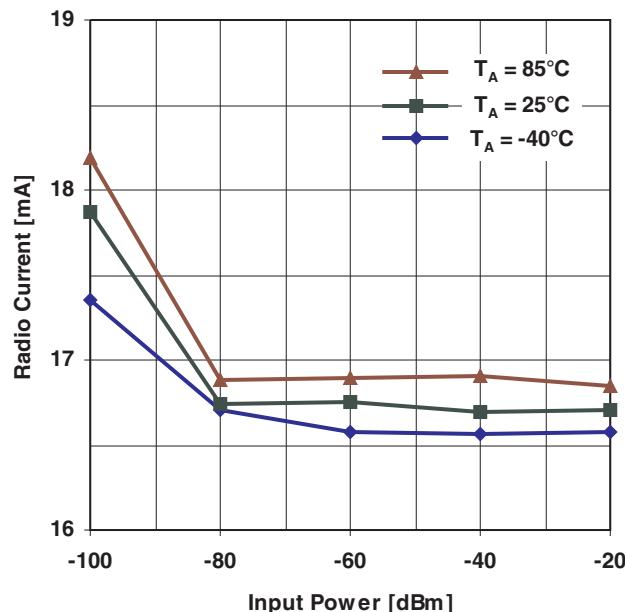
$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup> <sup>(2)</sup>

PARAMETER	FREQ (MHz)	DATA RATE (kBaud)	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Current consumption, RX	315	1.2	Register settings optimized for reduced current	Input at $-100\text{ dBm}$ (close to sensitivity limit)	17		mA	
				Input at $-40\text{ dBm}$ (well above sensitivity limit)	16			
				Input at $-100\text{ dBm}$ (close to sensitivity limit)	17			
		38.4		Input at $-40\text{ dBm}$ (well above sensitivity limit)	16			
				Input at $-100\text{ dBm}$ (close to sensitivity limit)	18			
				Input at $-40\text{ dBm}$ (well above sensitivity limit)	16.5			
	433	1.2	Register settings optimized for reduced current	Input at $-100\text{ dBm}$ (close to sensitivity limit)	18			
				Input at $-40\text{ dBm}$ (well above sensitivity limit)	17			
				Input at $-100\text{ dBm}$ (close to sensitivity limit)	18			
		38.4		Input at $-40\text{ dBm}$ (well above sensitivity limit)	17			
				Input at $-100\text{ dBm}$ (close to sensitivity limit)	18.5			
				Input at $-40\text{ dBm}$ (well above sensitivity limit)	17			
	868, 915	1.2	Register settings optimized for reduced current <sup>(3)</sup>	Input at $-100\text{ dBm}$ (close to sensitivity limit)	16			
				Input at $-40\text{ dBm}$ (well above sensitivity limit)	15			
				Input at $-100\text{ dBm}$ (close to sensitivity limit)	16			
		38.4		Input at $-40\text{ dBm}$ (well above sensitivity limit)	15			
				Input at $-100\text{ dBm}$ (close to sensitivity limit)	16			
				Input at $-40\text{ dBm}$ (well above sensitivity limit)	15			

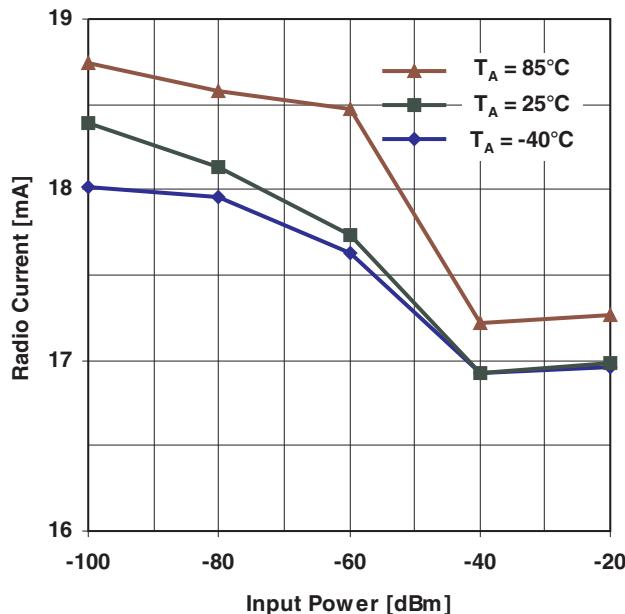
- (1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.
- (2) Reduced current setting (MDMCFG2.DEM\_DCFILT\_OFF = 1) gives a slightly lower current consumption at the cost of a reduction in sensitivity. See tables "RF Receive" for additional details on current consumption and sensitivity.
- (3) For 868 or 915 MHz, see [Figure 5-20](#) for current consumption with register settings optimized for sensitivity.



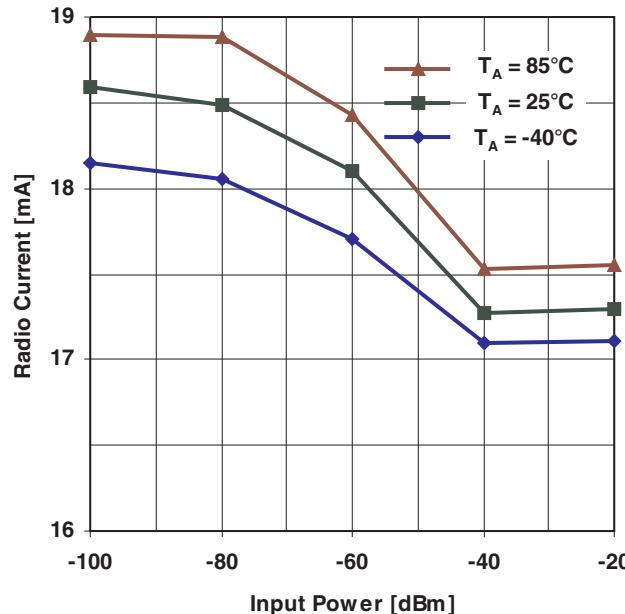
1.2 kBaud GFSK



38.4 kBaud GFSK



250 kBaud GFSK



500 kBaud MSK

**Figure 5-20. Typical RX Current Consumption Over Temperature and Input Power Level, 868 MHz, Sensitivity-Optimized Setting**

## 5.44 Current Consumption, Transmit Mode

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup> <sup>(2)</sup>

PARAMETER	FREQUENCY [MHz]	PATABLE SETTING	OUTPUT POWER (dBm)	TYP	UNIT
Current consumption, TX	315	0xC0	Maximum	26	mA
		0xC4	+10	25	
		0x51	0	15	
		0x29	-6	15	
	433	0xC0	Maximum	33	
		0xC6	+10	29	
		0x50	0	17	
		0x2D	-6	17	
	868	0xC0	Maximum	36	
		0xC3	+10	33	
		0x8D	0	18	
		0x2D	-6	18	
	915	0xC0	Maximum	35	
		0xC3	+10	32	
		0x8D	0	18	
		0x2D	-6	18	

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.  
 (2) Reduced current setting (MDMCFG2.DEM\_DCFILT\_OFF = 1) gives a slightly lower current consumption at the cost of a reduction in sensitivity. See tables "RF Receive" for additional details on current consumption and sensitivity.

### 5.45 Typical TX Current Consumption, 315 MHz

PARAMETER	PATABLE SETTING	OUTPUT POWER (dBm)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT			
			T <sub>A</sub>	25°C		25°C		25°C		25°C						
Current consumption, TX	0xC0	Maximum		27.5			26.4			28.1			mA			
	0xC4	+10		25.1			25.2			25.3						
	0x51	0		14.4			14.6			14.7						
	0x29	-6		14.2			14.7			15.0						

### 5.46 Typical TX Current Consumption, 433 MHz

PARAMETER	PATABLE SETTING	OUTPUT POWER (dBm)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT			
			T <sub>A</sub>	25°C		25°C		25°C		25°C						
Current consumption, TX	0xC0	Maximum		33.1			33.4			33.8			mA			
	0xC6	+10		28.6			28.8			28.8						
	0x50	0		16.6			16.8			16.9						
	0x2D	-6		16.8			17.5			17.8						

### 5.47 Typical TX Current Consumption, 868 MHz

PARAMETER	PATABLE SETTING	OUTPUT POWER (dBm)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
			T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Current consumption, TX	0xC0	Maximum		36.7	35.2	34.2	38.5	35.5	34.9	37.1	35.7	34.7	mA
	0xC3	+10		34.0	32.8	32.0	34.2	33.0	32.5	34.3	33.1	32.2	
	0x8D	0		18.0	17.6	17.5	18.3	17.8	18.1	18.4	18.0	17.7	
	0x2D	-6		17.1	17.0	17.2	17.8	17.8	18.3	18.2	18.1	18.1	

### 5.48 Typical TX Current Consumption, 915 MHz

PARAMETER	PATABLE SETTING	OUTPUT POWER (dBm)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
			T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Current consumption, TX	0xC0	Maximum		35.5	33.8	33.2	36.2	34.8	33.6	36.3	35.0	33.8	mA
	0xC3	+10		33.2	32.0	31.0	33.4	32.1	31.2	33.5	32.3	31.3	
	0x8D	0		17.8	17.4	17.1	18.1	17.6	17.3	18.2	17.8	17.5	
	0x2D	-6		17.0	16.9	16.9	17.7	17.6	17.6	18.1	18.0	18.0	

## 5.49 RF Receive, Overall

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Digital channel filter bandwidth <sup>(2)</sup>		58	812		kHz
Spurious emissions <sup>(3) (4)</sup>	25 MHz to 1 GHz		-68	-57	dBm
	Above 1 GHz		-66	-47	
RX latency	Serial operation <sup>(5)</sup>		9		bit

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

(2) User programmable. The bandwidth limits are proportional to crystal frequency (given values assume a 26.0-MHz crystal).

(3) Typical radiated spurious emission is -49 dBm measured at the VCO frequency

(4) Maximum figure is the ETSI EN 300 220 limit

(5) Time from start of reception until data is available on the receiver data output pin is equal to 9 bit.

## 5.50 RF Receive, 315 MHz

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

2-FSK, 1% packet error rate, 20-byte packet length, Sensitivity optimized, MDMCFG2.DEM\_DCFILT\_OFF = 0 (unless otherwise noted)

PARAMETER	DATA RATE (kBaud)	TEST CONDITIONS	TYP	UNIT
Receiver sensitivity	0.6	14.3-kHz deviation, 58-kHz digital channel filter bandwidth	-117	dBm
	1.2	5.2-kHz deviation, 58-kHz digital channel filter bandwidth <sup>(2)</sup>	-111	
	38.4	20-kHz deviation, 100-kHz digital channel filter bandwidth <sup>(3)</sup>	-103	
	250	127-kHz deviation, 540-kHz digital channel filter bandwidth <sup>(4)</sup>	-95	
	500	MSK, 812-kHz digital channel filter bandwidth <sup>(4)</sup>	-86	

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

(2) Sensitivity can be traded for current consumption by setting MDMCFG2.DEM\_DCFILT\_OFF = 1. The typical current consumption is then reduced by approximately 2 mA close to the sensitivity limit. The sensitivity is typically reduced to -109 dBm.

(3) Sensitivity can be traded for current consumption by setting MDMCFG2.DEM\_DCFILT\_OFF = 1. The typical current consumption is then reduced by approximately 2 mA close to the sensitivity limit. The sensitivity is typically reduced to -102 dBm.

(4) MDMCFG2.DEM\_DCFILT\_OFF = 1 can not be used for data rates  $\geq 250$  kBaud.

## 5.51 RF Receive, 433 MHz

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

2-FSK, 1% packet error rate, 20-byte packet length, Sensitivity optimized, MDMCFG2.DEM\_DCFILT\_OFF = 0 (unless otherwise noted)

PARAMETER	DATA RATE (kBaud)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Receiver sensitivity	0.6	14.3-kHz deviation, 58-kHz digital channel filter bandwidth	-114	dBm		
	1.2	5.2-kHz deviation, 58-kHz digital channel filter bandwidth <sup>(2)</sup>	-111			
	38.4	20-kHz deviation, 100-kHz digital channel filter bandwidth <sup>(3)</sup>	-104			
	250	127-kHz deviation, 540-kHz digital channel filter bandwidth <sup>(4)</sup>	-93			
	500	MSK, 812-kHz digital channel filter bandwidth <sup>(4)</sup>	-85			

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

(2) Sensitivity can be traded for current consumption by setting MDMCFG2.DEM\_DCFILT\_OFF = 1. The typical current consumption is then reduced by approximately 2 mA close to the sensitivity limit. The sensitivity is typically reduced to -109 dBm.

(3) Sensitivity can be traded for current consumption by setting MDMCFG2.DEM\_DCFILT\_OFF = 1. The typical current consumption is then reduced by approximately 2 mA close to the sensitivity limit. The sensitivity is typically reduced to -101 dBm.

(4) MDMCFG2.DEM\_DCFILT\_OFF = 1 can not be used for data rates  $\geq 250$  kBaud.

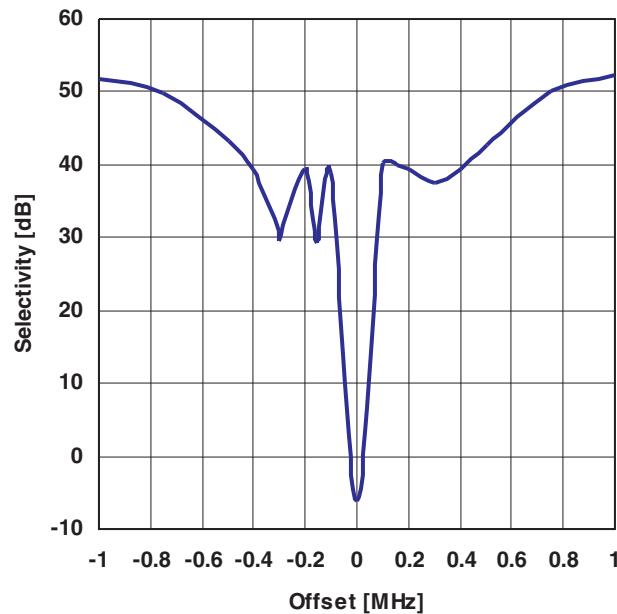
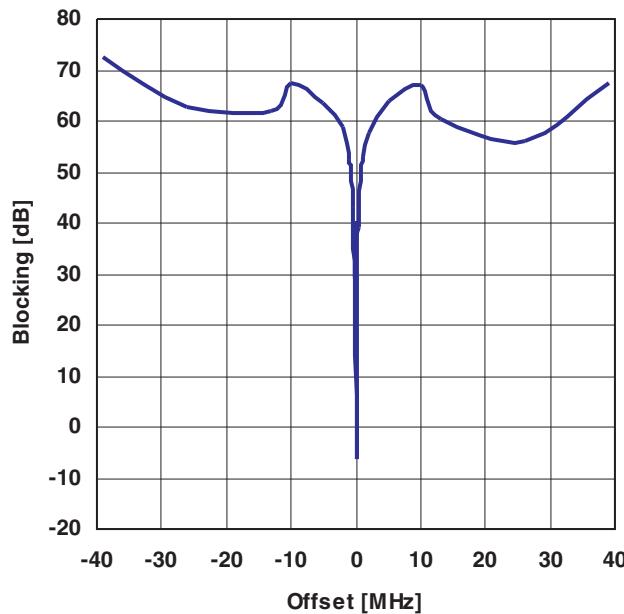
## 5.52 RF Receive, 868 or 915 MHz

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>,

1% packet error rate, 20-byte packet length, Sensitivity optimized,  $\text{MDMCFG2.DEM\_DCFILT\_OFF} = 0$  (unless otherwise noted)

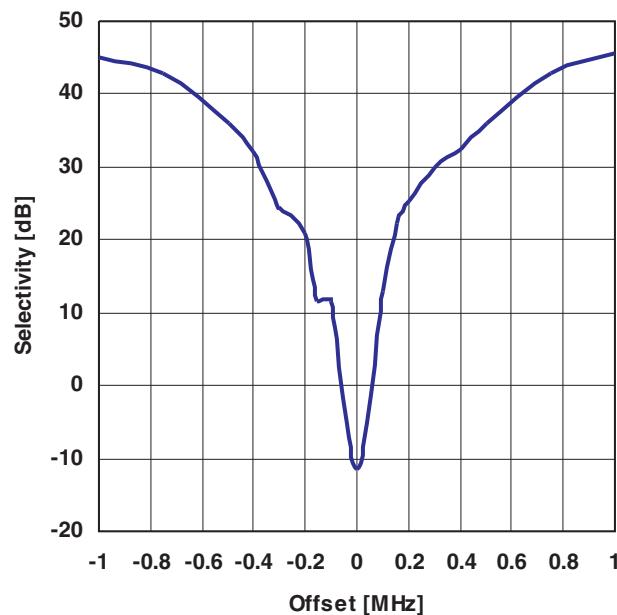
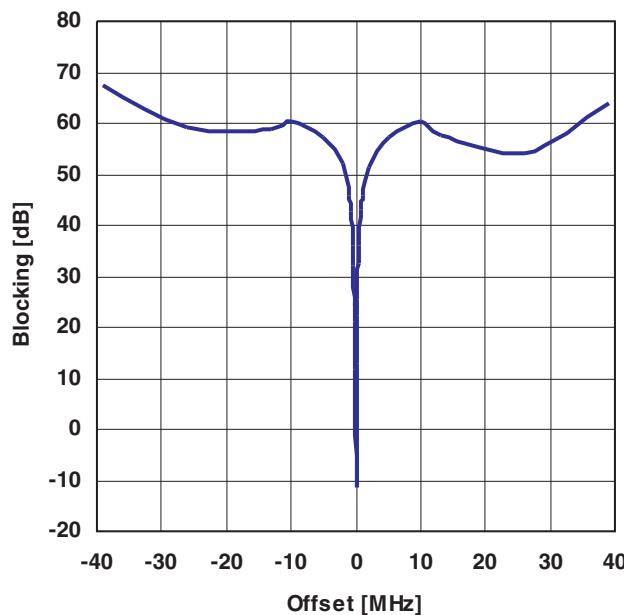
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>0.6-kBaud data rate, 2-FSK, 14.3-kHz deviation, 58-kHz digital channel filter bandwidth (unless otherwise noted)</b>					
Receiver sensitivity		–115			dBm
<b>1.2-kBaud data rate, 2-FSK, 5.2-kHz deviation, 58-kHz digital channel filter bandwidth (unless otherwise noted)</b>					
Receiver sensitivity <sup>(2)</sup>	2-GFSK modulation by setting $\text{MDMCFG2.MOD\_FORMAT} = 2$ , Gaussian filter with $\text{BT} = 0.5$	–109			dBm
		–109			
Saturation	$\text{FIFOTHR CLOSE\_IN\_RX} = 0$ <sup>(3)</sup>	–28			dBm
Adjacent channel rejection	Desired channel 3 dB above the sensitivity limit, 100-kHz channel spacing <sup>(4)</sup>	–100-kHz offset	39		dB
		+100-kHz offset	39		
Image channel rejection	IF frequency 152 kHz, desired channel 3 dB above the sensitivity limit		29		dB
Blocking	Desired channel 3 dB above the sensitivity limit <sup>(5)</sup>	±2-MHz offset	–48		dBm
		±10-MHz offset	–40		
<b>38.4-kBaud data rate, 2-FSK, 20-kHz deviation, 100-kHz digital channel filter bandwidth (unless otherwise noted)</b>					
Receiver sensitivity <sup>(6)</sup>	2-GFSK modulation by setting $\text{MDMCFG2.MOD\_FORMAT} = 2$ , Gaussian filter with $\text{BT} = 0.5$	–102			dBm
		–101			
Saturation	$\text{FIFOTHR CLOSE\_IN\_RX} = 0$ <sup>(3)</sup>	–19			dBm
Adjacent channel rejection	Desired channel 3 dB above the sensitivity limit, 200 kHz channel spacing <sup>(5)</sup>	–200-kHz offset	20		dB
		+200-kHz offset	25		
Image channel rejection	IF frequency 152 kHz, Desired channel 3 dB above the sensitivity limit		23		dB
Blocking	Desired channel 3 dB above the sensitivity limit <sup>(5)</sup>	±2-MHz offset	–48		dBm
		±10-MHz offset	–40		
<b>250-kBaud data rate, 2-FSK, 127-kHz deviation, 540-kHz digital channel filter bandwidth (unless otherwise noted)</b>					
Receiver sensitivity <sup>(7)</sup>	2-GFSK modulation by setting $\text{MDMCFG2.MOD\_FORMAT} = 2$ , Gaussian filter with $\text{BT} = 0.5$	–90			dBm
		–90			
Saturation	$\text{FIFOTHR CLOSE\_IN\_RX} = 0$ <sup>(3)</sup>	–19			dBm
Adjacent channel rejection	Desired channel 3 dB above the sensitivity limit, 750-kHz channel spacing <sup>(8)</sup>	–750-kHz offset	24		dB
		+750-kHz offset	30		
Image channel rejection	IF frequency 304 kHz, Desired channel 3 dB above the sensitivity limit		18		dB
Blocking	Desired channel 3 dB above the sensitivity limit <sup>(8)</sup>	±2-MHz offset	–53		dBm
		±10-MHz offset	–39		
<b>500-kBaud data rate, MSK, 812-kHz digital channel filter bandwidth (unless otherwise noted)</b>					
Receiver sensitivity <sup>(7)</sup>		–84			dBm
Image channel rejection	IF frequency 355 kHz, Desired channel 3 dB above the sensitivity limit	–2			dB
Blocking	Desired channel 3 dB above the sensitivity limit <sup>(9)</sup>	±2-MHz offset	–53		dBm
		±10-MHz offset	–38		

- (1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.
- (2) Sensitivity can be traded for current consumption by setting  $\text{MDMCFG2.DEM\_DCFILT\_OFF} = 1$ . The typical current consumption is then reduced by approximately 2 mA close to the sensitivity limit. The sensitivity is typically reduced to –107 dBm.
- (3) See design note *DN010 Close-in Reception with CC1101 (SWRA147)*.
- (4) See [Figure 5-21](#) for blocking performance at other offset frequencies.
- (5) See [Figure 5-22](#) for blocking performance at other offset frequencies.
- (6) Sensitivity can be traded for current consumption by setting  $\text{MDMCFG2.DEM\_DCFILT\_OFF} = 1$ . The typical current consumption is then reduced by approximately 2 mA close to the sensitivity limit. The sensitivity is typically reduced to –100 dBm.
- (7)  $\text{MDMCFG2.DEM\_DCFILT\_OFF} = 1$  cannot be used for data rates  $\geq 250$  kBaud.
- (8) See [Figure 5-23](#) for blocking performance at other offset frequencies.
- (9) See [Figure 5-24](#) for blocking performance at other offset frequencies.



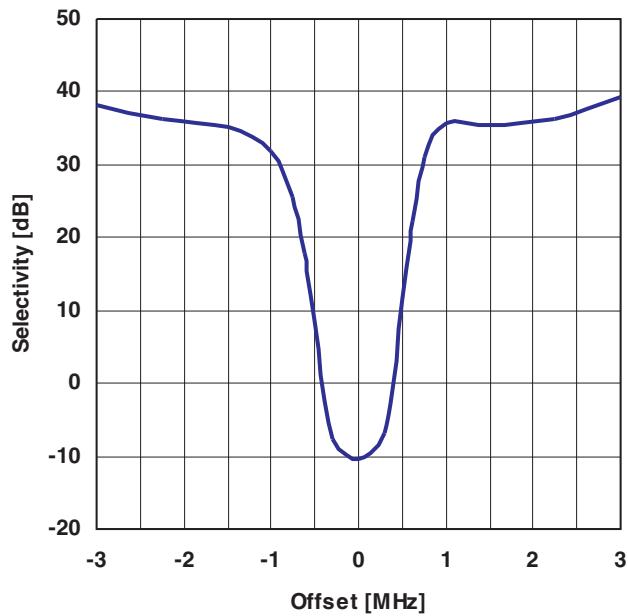
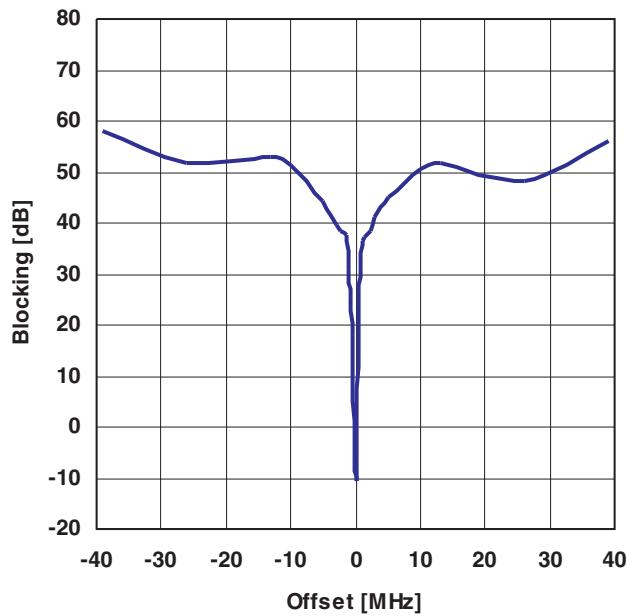
NOTE: 868.3 MHz, 2-FSK, 5.2-kHz deviation, IF frequency is 152.3 kHz, digital channel filter bandwidth is 58 kHz

**Figure 5-21. Typical Selectivity at 1.2-kBaud Data Rate**



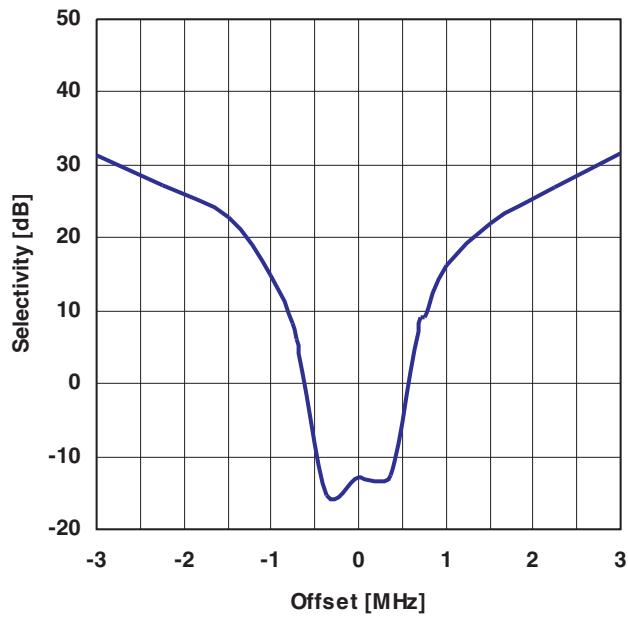
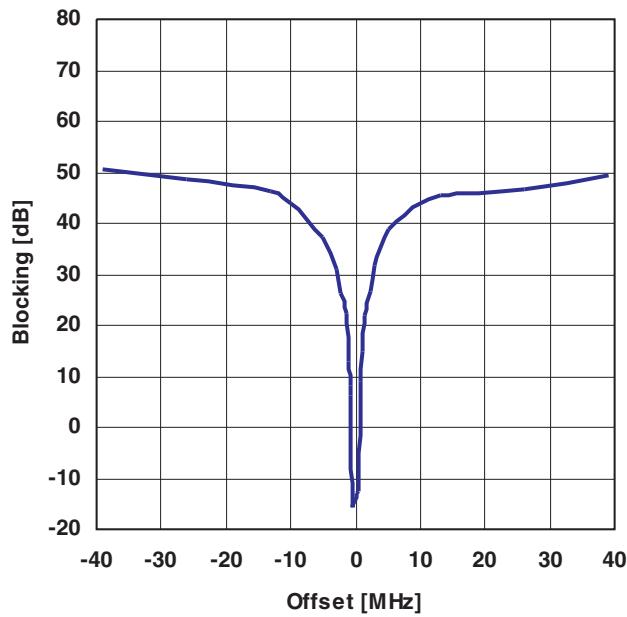
NOTE: 868 MHz, 2-FSK, 20 kHz deviation, IF frequency is 152.3 kHz, digital channel filter bandwidth is 100 kHz

**Figure 5-22. Typical Selectivity at 38.4-kBaud Data Rate**



NOTE: 868 MHz, 2-FSK, IF frequency is 304 kHz, digital channel filter bandwidth is 540 kHz

**Figure 5-23. Typical Selectivity at 250-kBaud Data Rate**



NOTE: 868 MHz, 2-FSK, IF frequency is 355 kHz, digital channel filter bandwidth is 812 kHz

**Figure 5-24. Typical Selectivity at 500-kBaud Data Rate**

### 5.53 Typical Sensitivity, 315 MHz, Sensitivity-Optimized Setting

PARAMETER	DATA RATE (kBaud)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Sensitivity, 315MHz	1.2		-112	-112	-110	-112	-111	-109	-112	-111	-108	dBm
	38.4		-105	-105	-104	-105	-103	-102	-105	-104	-102	
	250		-95	-95	-92	-94	-95	-92	-95	-94	-91	

### 5.54 Typical Sensitivity, 433 MHz, Sensitivity-Optimized Setting

PARAMETER	DATA RATE (kBaud)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Sensitivity, 433MHz	1.2		-111	-110	-108	-111	-111	-108	-111	-110	-107	dBm
	38.4		-104	-104	-101	-104	-104	-101	-104	-103	-101	
	250		-93	-94	-91	-93	-93	-90	-93	-93	-90	

### 5.55 Typical Sensitivity, 868 MHz, Sensitivity-Optimized Setting

PARAMETER	DATA RATE (kBaud)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Sensitivity, 868MHz	1.2		-109	-109	-107	-109	-109	-106	-109	-108	-106	dBm
	38.4		-102	-102	-100	-102	-102	-99	-102	-101	-99	
	250		-90	-90	-88	-89	-90	-87	-89	-90	-87	
	500		-84	-84	-81	-84	-84	-80	-84	-84	-80	

### 5.56 Typical Sensitivity, 915 MHz, Sensitivity-Optimized Setting

PARAMETER	DATA RATE (kBaud)	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Sensitivity, 915MHz	1.2		-109	-109	-107	-109	-109	-106	-109	-108	-105	dBm
	38.4		-102	-102	-100	-102	-102	-99	-103	-102	-99	
	250		-92	-92	-89	-92	-92	-88	-92	-92	-88	
	500		-87	-86	-81	-86	-86	-81	-86	-85	-80	

## 5.57 RF Transmit

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>,  $P_{TX} = +10\text{ dBm}$  (unless otherwise noted)

PARAMETER	FREQUENCY (MHz)	TEST CONDITIONS			MIN	TYP	MAX	UNIT		
Differential load impedance <sup>(2)</sup>	315				122 + j31			$\Omega$		
	433				116 + j41					
	868/915				86.5 + j43					
Output power, highest setting <sup>(3)</sup>	315	Delivered to a 50- $\Omega$ single-ended load through the RF matching network of the CC430 reference design			+12			dBm		
	433				+13					
	868				+11					
	915				+11					
Output power, lowest setting <sup>(3)</sup>		Delivered to a 50- $\Omega$ single-ended load through the RF matching network of the CC430 reference design			-30			dBm		
Harmonics, radiated <sup>(4)(5)(6)</sup>	433	Second harmonic			-56			dBm		
		Third harmonic			-57					
	868	Second harmonic			-50					
		Third harmonic			-52					
	915	Second harmonic			-50					
		Third harmonic			-54					
Harmonics, conducted	315	Frequencies below 960 MHz		+10 dBm CW	< -38			dBm		
		Frequencies above 960 MHz			< -48					
	433	Frequencies below 1 GHz		+10 dBm CW	-45					
		Frequencies above 1 GHz			< -48					
	868	Second harmonic		+10 dBm CW	-59					
		Other harmonics			< -71					
Spurious emissions, conducted, harmonics not included <sup>(8)</sup>	915	Second harmonic		+11 dBm CW <sup>(7)</sup>	-53			dBm		
		Other harmonics			< -47					
	315	Frequencies below 960 MHz		+10 dBm CW	< -58					
		Frequencies above 960 MHz			< -53					
	433	Frequencies below 1 GHz		+10 dBm CW	< -54					
		Frequencies above 1 GHz			< -54					
	868	Frequencies within 47 to 74, 87.5 to 118, 174 to 230, 470 to 862 MHz		+10 dBm CW	< -63					
		Frequencies within 47 to 74, 87.5 to 118, 174 to 230, 470 to 862 MHz			< -63					
	915	Frequencies below 1 GHz		+10 dBm CW	< -46					
		Frequencies above 1 GHz			< -59					
		Frequencies within 47 to 74, 87.5 to 118, 174 to 230, 470 to 862 MHz			< -56					
		Frequencies below 960 MHz		+11 dBm CW	< -49					
		Frequencies above 960 MHz			< -63					
TX latency <sup>(9)</sup>		Serial operation			8			bits		

- (1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.
- (2) Differential impedance as seen from the RF port (RF\_P and RF\_N) toward the antenna. Follow the CC430 reference designs available from the TI website.
- (3) Output power is programmable, and full range is available in all frequency bands. Output power may be restricted by regulatory limits. See also Application Note *AN050 Using the CC1101 in the European 868MHz SRD Band* ([SWRA146](#)) and design note *DN013 Programming Output Power on CC1101* ([SWRA168](#)), which gives the output power and harmonics when using multi-layer inductors. The output power is then typically +10 dBm when operating at 868 or 915 MHz.
- (4) The antennas used during the radiated measurements (SMAFF-433 from R.W.Badland and Nearson S331 868/915) play a part in attenuating the harmonics.
- (5) Measured on EM430F6137RF900 with CW, maximum output power
- (6) All harmonics are below -41.2 dBm when operating in the 902 through 928 MHz band.
- (7) Requirement is -20 dBc under FCC 15.247
- (8) All radiated spurious emissions are within the limits of ETSI. Also see design note *DN017 CC11xx 868 or 915 MHz RF Matching* ([SWRA168](#)).
- (9) Time from sampling the data on the transmitter data input pin until it is observed on the RF output ports

## 5.58 Optimum PATABLE Settings for Various Output Power Levels and Frequency Bands

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

OUTPUT POWER (dBm)	PATABLE SETTING			
	315 MHz	433 MHz	868 MHz	915 MHz
-30	0x12	0x05	0x03	0x03
-12	0x33	0x26	0x25	0x25
-6	0x29	0x2D	0x2D	0x2D
0	0x51	0x50	0x8D	0x8D
10	0xC4	0xC4	0xC3	0xC3
Maximum	0xC0	0xC0	0xC0	0xC0

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

### 5.59 Typical Output Power, 315 MHz<sup>(1)</sup>

PARAMETER	PATABLE SETTING	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Output power, 315 MHz	0xC0 (max)			11.9			11.8			11.8		dBm
	0xC4 (10 dBm)			10.3			10.3			10.3		
	0xC6 (default)						9.3					
	0x51 (0 dBm)			0.7			0.6			0.7		
	0x29 (-6 dBm)			-6.8			-5.6			-5.3		

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

### 5.60 Typical Output Power, 433 MHz<sup>(1)</sup>

PARAMETER	PATABLE SETTING	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Output power, 433 MHz	0xC0 (max)			12.6			12.6			12.6		dBm
	0xC4 (10 dBm)			10.3			10.2			10.2		
	0xC6 (default)						10.0					
	0x50 (0 dBm)			0.3			0.3			0.3		
	0x2D (-6 dBm)			-6.4			-5.4			-5.1		

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

### 5.61 Typical Output Power, 868 MHz<sup>(1)</sup>

PARAMETER	PATABLE SETTING	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Output power, 868 MHz	0xC0 (max)		11.9	11.2	10.5	11.9	11.2	10.5	11.9	11.2	10.5	dBm
	0xC3 (10 dBm)		10.8	10.1	9.4	10.8	10.1	9.4	10.7	10.1	9.4	
	0xC6 (default)						8.8					
	0x8D (0 dBm)		1.0	0.3	-0.3	1.1	0.3	-0.3	1.1	0.3	-0.3	
	0x2D (-6 dBm)		-6.5	-6.8	-7.3	-5.3	-5.8	-6.3	-4.9	-5.4	-6.0	

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

### 5.62 Typical Output Power, 915 MHz<sup>(1)</sup>

PARAMETER	PATABLE SETTING	V <sub>CC</sub>	2 V			3 V			3.6 V			UNIT
		T <sub>A</sub>	-40°C	25°C	85°C	-40°C	25°C	85°C	-40°C	25°C	85°C	
Output power, 915 MHz	0xC0 (max)		12.2	11.4	10.6	12.1	11.4	10.7	12.1	11.4	10.7	dBm
	0xC3 (10 dBm)		11.0	10.3	9.5	11.0	10.3	9.5	11.0	10.3	9.6	
	0xC6 (default)						8.8					
	0x8D (0 dBm)		1.9	1.0	0.3	1.9	1.0	0.3	1.9	1.1	0.3	
	0x2D (-6 dBm)		-5.5	-6.0	-6.5	-4.3	-4.8	-5.5	-3.9	-4.4	-5.1	

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

## 5.63 Frequency Synthesizer Characteristics

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

MIN figures are given using a 27MHz crystal. TYP and MAX figures are given using a 26MHz crystal.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Programmed frequency resolution <sup>(2)</sup>	26- to 27-MHz crystal	397	$f_{XOSC}/2^{16}$	412	Hz
Synthesizer frequency tolerance <sup>(3)</sup>			$\pm 40$		ppm
RF carrier phase noise	50-kHz offset from carrier		-95		dBc/Hz
	100-kHz offset from carrier		-94		
	200-kHz offset from carrier		-94		
	500-kHz offset from carrier		-98		
	1-MHz offset from carrier		-107		
	2-MHz offset from carrier		-112		
	5-MHz offset from carrier		-118		
	10-MHz offset from carrier		-129		
PLL turnon or hop time <sup>(4)</sup>	Crystal oscillator running	85.1	88.4	88.4	$\mu\text{s}$
PLL RX-to-TX settling time <sup>(5)</sup>		9.3	9.6	9.6	$\mu\text{s}$
PLL TX-to-RX settling time <sup>(6)</sup>		20.7	21.5	21.5	$\mu\text{s}$
PLL calibration time <sup>(7)</sup>		694	721	721	$\mu\text{s}$

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.

(2) The resolution (in Hz) is equal for all frequency bands.

(3) Depends on crystal used. Required accuracy (including temperature and aging) depends on frequency band and channel bandwidth and spacing.

(4) Time from leaving the IDLE state until arriving in the RX, FSTXON, or TX state, when not performing calibration.

(5) Settling time for the 1-IF frequency step from RX to TX

(6) Settling time for the 1-IF frequency step from TX to RX

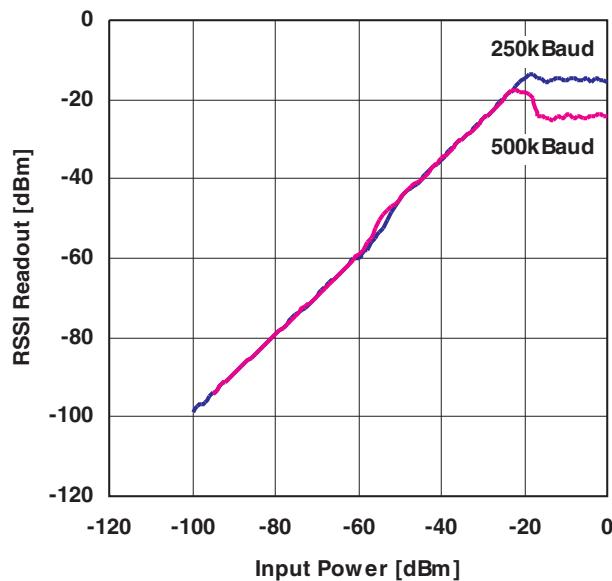
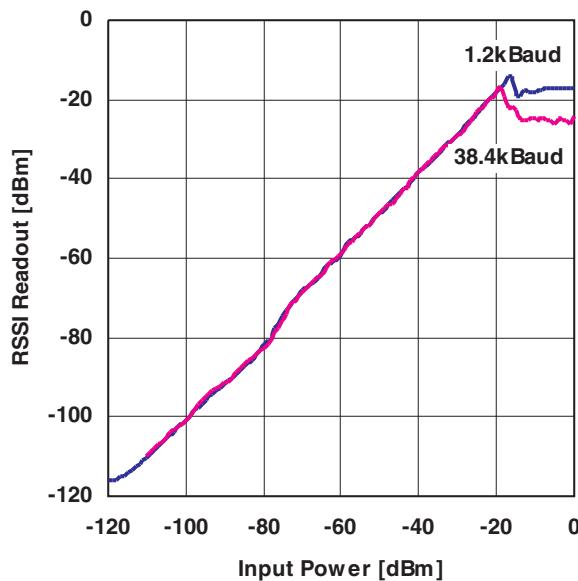
(7) Calibration can be initiated manually or automatically before entering or after leaving RX/TX.

## 5.64 Typical RSSI\_Offset Values

$T_A = 25^\circ\text{C}$ ,  $V_{CC} = 3\text{ V}$  (unless otherwise noted)<sup>(1)</sup>

DATA RATE (kBaud)	RSSI_OFFSET (dB)	
	433 MHz	868 MHz
1.2	74	74
38.4	74	74
250	74	74
500	74	74

(1) All measurement results are obtained using the EM430F6137RF900 with BOM according to tested frequency range.



**Figure 5-25. Typical RSSI Value vs Input Power Level for Different Data Rates at 868 MHz**

## 5.65 3D LF Front-End Parameters

## 5.66 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
$V_{BAT}$	Supply voltage range during LF operation	2.0		3.6	V
RF crystal load capacitance		10	13	20	pF
RF crystal effective series resistance				100	$\Omega$

## 5.67 Resonant Circuits – LF Front End

The resonance circuit quality factor  $Q_{OP}$  can have a wide range between 10 and 120. The resonance frequency can be trimmed by the embedded trimming capacitor array.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{RES}$	25°C	133.2	134.2	135.2	kHz
$f_L$	25°C, $Q_{OP} = 10$ to 120	133.2	134.2	135.2	
	–40°C to 85°C, $Q_{OP} = 10$ to 120	132.2	134.2	136.2	
$f_H$	25°C, $Q_{OP} = 10$ to 120	123.2	124.2	125.2	
	–40°C to 85°C, $Q_{OP} = 10$ to 120	122.2	124.2	126.2	

## 5.68 External Antenna Coil – LF Front End

The antenna coil LR, resonant capacitor CR and charge capacitor CL are external components with following recommended parameters

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$L_{R1}$	25°C, $f = 134.2$ kHz	7.37	7.6	7.81	mH
$L_{R2}$	25°C, $f = 134.2$ kHz	4.37	4.5	4.63	mH
$dL_R/L_RdT$	–40°C to 85°C			250	ppm/°C
$Q_{LRT}$	–40°C to 85°C	10		150	

## 5.69 Resonant Circuit Capacitor – LF Front End

The input capacitance of the RF pins  $C_{RF}$  is the sum of parasitic capacitances of circuit blocks connected to the RF pin. The trimming capacitors are internal capacitances and can be programmed on or off. The resonance capacitor  $C_R$  is an external component and is not part of this IC.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$C_R$	Resonant circuit capacitor (option 1) ( $dCR = \pm 2.0\%$ )	LR = 7.6mH	147	150	153
$C_R$	Resonant circuit capacitor (option 2) ( $dCR = \pm 2.0\%$ )	LR = 4.5mH	264.6	270	275.4
	Dielectric of CR	$dL_R/L_RdT \leq 250$ ppm		NPO	
$dC_R/C_RdT$	Temperature coefficient of CR (NP0)	$dLR/LRdT \leq 250$ ppm		±30	73
$Q_{CR}$	Quality factor		2000		
$V_{RF}$	Operating voltage		20	50	$V_{PP}$
$C_{RF}$	RF input capacitance	$VCL = 5$ V CT = off	21.3	24	26.6
$Q_{RF}$	IC input quality factor (RF1, RF2, RF3)	$VRF = 0.1$ V, CT = max, CM = on or off	250	350	
	Capacitance voltage dependency	$VCL = 0$ to 5 V, CT = on or off		–1	%/V
$T_{step}$	Trimming steps			128	
$CT_{min}$	Minimum trimming capacitor			0	pF
$CT_{max}$	Maximum trimming capacitor ( $CT = CT1 + CT2 + \dots + CT7$ )	Calculated	70.8	74.7	78.8
$CT1$	Trimming capacitor 1			0.6	pF
$CT2$	Trimming capacitor 2			1.2	pF

## Resonant Circuit Capacitor – LF Front End (continued)

The input capacitance of the RF pins  $C_{RF}$  is the sum of parasitic capacitances of circuit blocks connected to the RF pin. The trimming capacitors are internal capacitances and can be programmed on or off. The resonance capacitor  $C_R$  is an external component and is not part of this IC.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
CT3 Trimming capacitor 3			2.4		pF
CT4 Trimming capacitor 4			4.7		pF
CT5 Trimming capacitor 5			9.4		pF
CT6 Trimming capacitor 6			18.8		pF
CT7 Trimming capacitor 7			37.6		pF
dCT/dV Voltage coefficient of CT				0.1	pF/V
dCT/dT Temperature coefficient of CT				0.02	pF/K
CM1 Modulation capacitor 4.5 mH: CM1 + CM2 7.6 mH: CM1	Integrated capacitor	33.1	35.0	36.9	pF
CM2 Modulation capacitor	Integrated capacitor	17.0	18.0	19.0	pF
dCM/dV  Modulation capacitor voltage coefficient	25°C			0.1	%/V
dCM/dT Modulation capacitor voltage coefficient				0.02	pF/K

## 5.70 Charge Capacitor – LF Front End

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
CL Charge capacitor (dCL = $\pm 10\%$ )	25°C, $Q_{OP} = 134.2$ kHz	198	220	242	nF
dCL(T) Temperature coefficient of CL	-40°C to 85°C		-10%	10%	
Dielectric of CL			XR7		
DCL(t) Charge capacitor aging	100000 h		-10%	0%	

## 5.71 LF Wake Receiver Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$f_{RES,PE}$ Resonant circuit frequency	25°C	110		140	kHz
$t_{WakeUp}$ Wake-up time		500	560	1000	μs
$I_{PESBWP}$ Standby current	Wake pattern A active, wake pattern B off, regular sensitivity, $V_{BAT} = 3$ V		4.4		μA
$V_{WAKEA}$ Sensitivity A (regular)	Configured to highest sensitivity	2.6	3.7	6.2	mV <sub>pp</sub>
$V_{WAKEA}$ Sensitivity A (regular)	Configured to lowest sensitivity	9	13.5	23	mV <sub>pp</sub>
$V_{WAKEA}$ Sensitivity A (high sensitivity mode)	Configured to highest sensitivity and high sensitivity mode	0.3	0.5	0.9	mV <sub>pp</sub>
$V_{WAKEB}$ Sensitivity B	Configured to highest sensitivity	2.3	4.2	7.5	mV <sub>pp</sub>
$V_{WAKEB}$ Sensitivity B	Configured to lowest sensitivity	50	110	200	mV <sub>pp</sub>
VRF Maximum RF input voltage				10	V <sub>pp</sub>
S/N Wake pattern detection error rate (S/N)			10		dB
$t_{sA}$ WDE settling time (wake A, low sensitivity)				500	μs
$t_{sAh}$ WDE settling time (wake A, high sensitivity)				600	μs
$t_{sB}$ WDE settling time (wake B)				2000	μs
$t_{resA}$ WDE resettling time (strong burst recovery time)	Step VRF 2V <sub>pp</sub> to 10mV <sub>pp</sub>			3000	μs

## 5.72 RSSI - LF Wake Receiver Electrical Characteristics

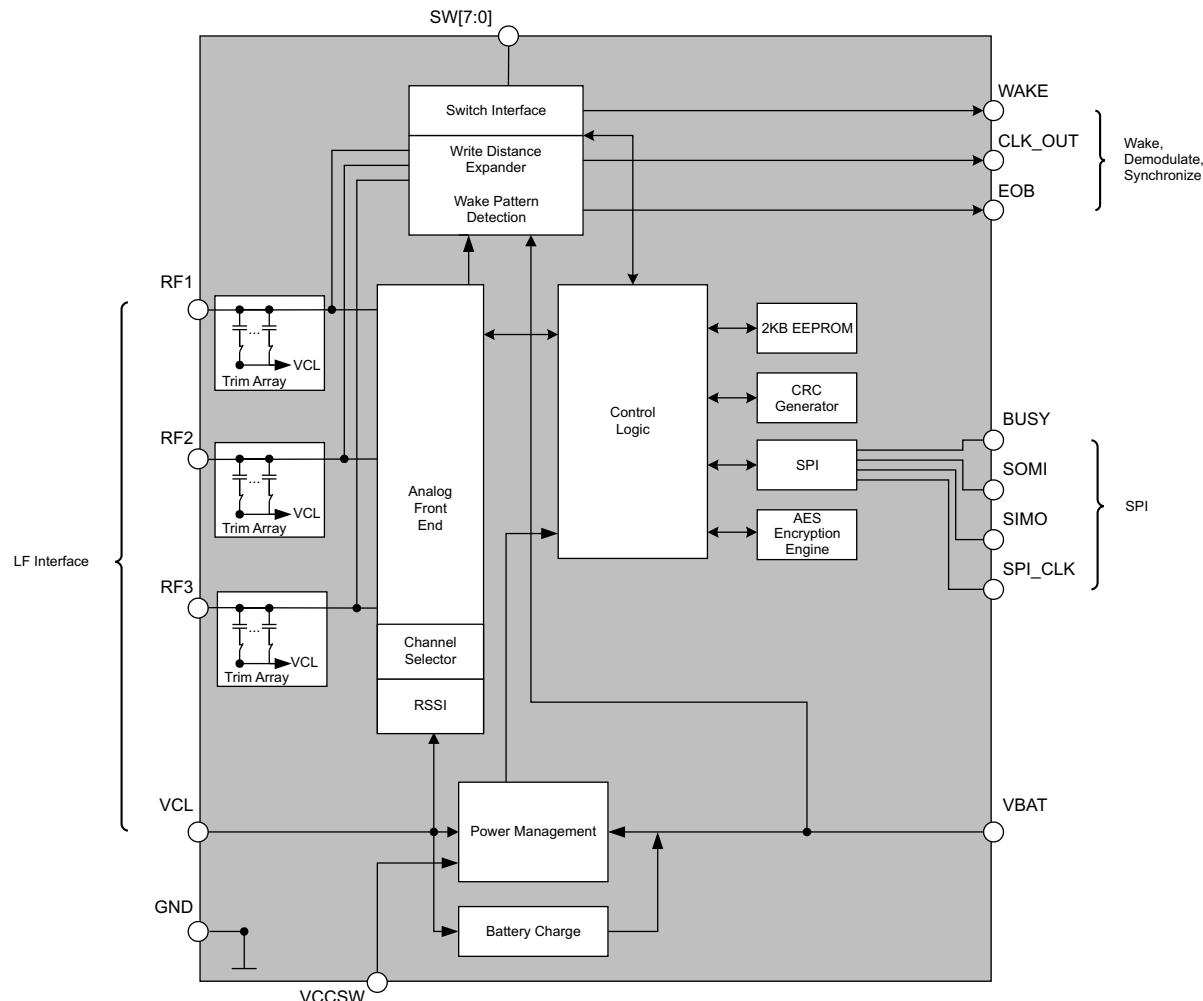
over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNIT
DR	Dynamic range		72		dB
VRF	Input voltage range	0.002		8	V <sub>pp</sub>
A	RSSI linear coefficient		28		
B	RSSI constant coefficient		180		
#RSSI	Number of RSSI values		128		
Verr16mV	Absolute RSSI error at VRF = 16 mV <sub>pp</sub>	-1.28		1.28	mV <sub>pp</sub>
err16mV	Relative RSSI error VRF $\geq$ 16 mV <sub>pp</sub>	-8%		8%	
Verr2mV	Absolute RSSI error at VRF = 2 mV <sub>pp</sub>	-0.4		0.4	mV <sub>pp</sub>
err2mV	Relative RSSI error at VRF = 2 mV <sub>pp</sub>	-20%		20%	
Vmin	Resolution at VRF = 2 mV <sub>pp</sub>	0.14			mV
t	Measurement time (all three channels)			2	ms

## 6 Detailed Description

### 6.1 3D LF Wake Receiver and 3D Transponder Interface

Figure 6-1 shows the LF interface block diagram.



**Figure 6-1. LF Interface Block Diagram**

The LF front end provides a SPI that is used for the communication with the CPU core. Data access, configuration, and status queries to the MSP430 core are executed with predefined commands over this interface, which is internally connected to IO ports (see [Table 6-1](#)).

**Table 6-1. Intermodule Connections for RF430F59xx**

MICROCONTROLLER PORT	LF FRONT-END MODULE PORT
P3.1	Input
P3.2	Output
P3.3	Output
P3.5	Input
P4.1	Input
P4.2	Input
	SPI_SOMI
	SPI_SIMO
	SPI_CLK
	CLK_OUT
	EOB
	SPI_BUSY

### 6.1.1 3D LF Front End

The 3D LF front end provides two basic operation modes: transponder mode and wake receiver mode. The LF front end provides an external trigger to wake up the microcontroller on LF reception. Data received by the LF interface and status of the device can be read through SPI communication. Features of the LF front end include:

- Resonant frequency: 134.2 kHz
  - Embedded resonant trimming for all three resonant circuits
- Quality factor range: 10 to 60
- Antenna Inductance 2.66 mH, 4.5 mH, or 7.6 mH
- AES-128 hardware-encryption coprocessor
- 3D wake receiver
  - Fixed downlink start pattern S10
  - Downlink data rate up to 4 kBps with bit-length coding
  - Two independent wake patterns WP A or WP B with 0-, 4-, 8-, 12-, 16-, 20-, or 24-bit length
    - Dedicated sensitivity levels for both WP
  - Digital RSSI 72 dB, 8-bit logarithmic
    - Accuracy  $\pm 8\%$  in near distance (<16 mVpp)
    - Accuracy  $\pm 20\%$  in far distance (>16 mVpp)
- 3D RFID transponder interface
  - Batteryless operation
  - Fixed downlink start pattern S01
  - Transponder read range up to 4 inches (10 cm)
  - Half-duplex communication protocol
    - Adaptive downlink data rate: up to 4 kbaud with ASK, bit-length coding
    - Uplink data rate: up to 8 kbaud with FSK
  - Selectable challenge/response length of 32/32, 64/64, or 96/64 bit
  - Mutual authentication for all commands with 32-bit reader signature
  - Selective addressing mode, 8 bit
  - Burst read mode
  - Anticollision encryption

### 6.1.2 EEPROM

The EEPROM can be accessed by SPI commands. Features of the EEPROM include:

- Total memory size: 2048 Bytes
- User memory size: 1776 Bytes
  - User memory has up to 4 banks
  - User memory is organized in 64 pages per bank of 8 bytes each
- EEPROM has one system memory bank organized in 64 pages of 4 bytes each.
  - System memory is organized in 64 pages of 4 bytes each
  - System memory is used for special information (configuration, four 128-bit encryption keys, counter values)
- The memory pages are configurable and provide different access modes
  - General-purpose memory (general read, program, and lock)
  - System only data (mutual only access)
  - Microcontroller only data (no access over LF interface)
  - Secured data (mutual program and lock, general read)
- All pages can be locked separately (no reprogramming possible)

Table 6-2 summarizes the EEPROM organization.

### 6.1.3 Switch Interface

The switch interface provides eight inputs. Features of the switch interface include:

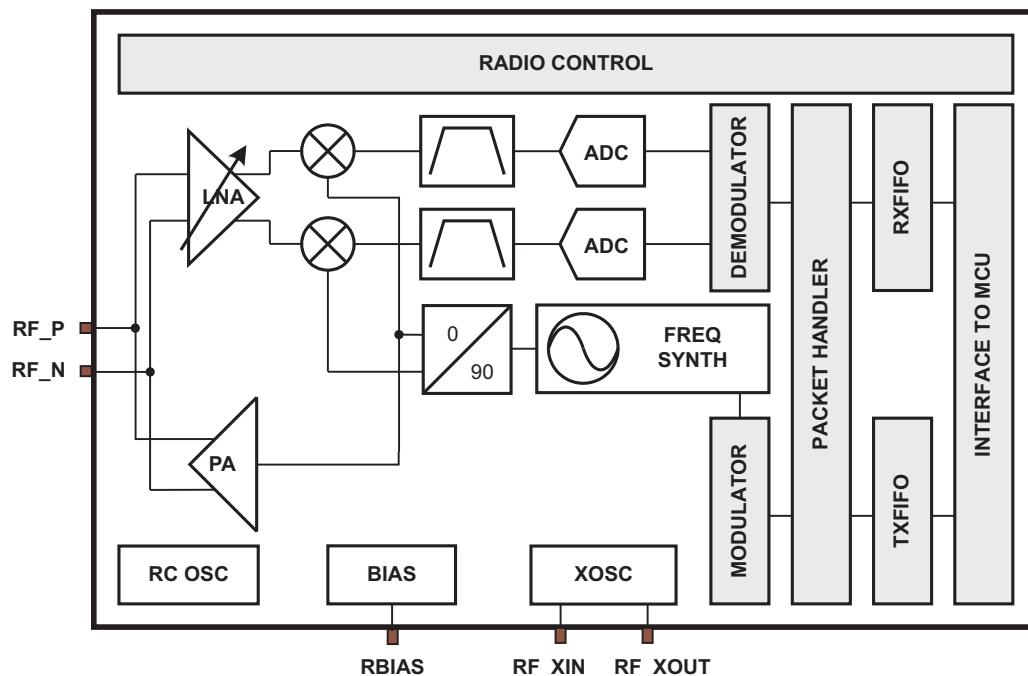
- Internal pullups to minimize external components
- Embedded stuck button handling
- Embedded debouncing for each switch debounce time: 10, 20, 40, or 80 ms

**Table 6-2. LF Front End EEPROM Memory Map**

EEPROM (MEM)									
BANK	BYTE								PAGE
	7	6	5	4	3	2	1	0	
0	User Data								0
	⋮								⋮
	User Data								7
	⋮								⋮
	User Data								63
1	User Data								0
	⋮								⋮
	User Data								7
	⋮								⋮
	User Data								63
2	User Data								0
	⋮								⋮
	User Data								7
	⋮								⋮
	User Data								63
3	User Data								0
	⋮								⋮
	User Data								7
	⋮								⋮
	User Data								29
7	Configuration Data				Configuration Data				1 0
	⋮				⋮				3 2
	⋮				⋮				5 4
	⋮				⋮				7 6
	⋮				⋮				9 8
	⋮				⋮				11 10
	⋮				⋮				13 12
	⋮				⋮				15 14
	⋮				⋮				17 16
	⋮				⋮				19 18
	⋮				⋮				21 20
	⋮				⋮				23 22
	⋮				⋮				25 24
	⋮				⋮				27 26
	⋮				⋮				29 28
	⋮				⋮				31 30
Encryption Keys									

## 6.2 Sub-1-GHz Radio

The sub-1-GHz radio module is based on the industry-leading CC1101 and requires very few external components. [Figure 6-2](#) shows a high-level block diagram of the implemented radio.



**Figure 6-2. Sub-1-GHz Radio Block Diagram**

The radio features a low intermediate frequency (IF) receiver. The received RF signal is amplified by a low-noise amplifier (LNA) and down converted in quadrature to the IF. At the IF, the I/Q signals are digitized. Automatic gain control (AGC), fine channel filtering, and demodulation bit and packet synchronization are performed digitally.

The transmitter is based on direct synthesis of the RF frequency. The frequency synthesizer includes a completely on-chip LC VCO and a 90-degree phase shifter for generating the I and Q LO signals to the down-conversion mixers in receive mode.

The 26-MHz crystal oscillator generates the reference frequency for the synthesizer and the clocks for the ADC and the digital peripherals.

A memory-mapped register interface is used for data access, configuration, and status request by the CPU.

The digital baseband includes support for channel configuration, packet handling, and data buffering.

For complete module descriptions, see the *RF430F5978 User's Guide (SLAU378)*.

## 6.3 CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator, respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

The instruction set consists of the original 51 instructions with three formats and seven address modes and additional instructions for the expanded address range. Each instruction can operate on word and byte data.

## 6.4 Operating Modes

The device has one active mode and five software-selectable low-power modes of operation. An interrupt event can wake up the device from any of the low-power modes, service the request, and restore back to the low-power mode on return from the interrupt program.

The following operating modes can be configured by software:

- Active mode (AM)
  - All clocks are active
- Low-power mode 0 (LPM0)
  - CPU is disabled
  - ACLK and SMCLK remain active, MCLK is disabled
  - FLL loop control remains active
- Low-power mode 1 (LPM1)
  - CPU is disabled
  - FLL loop control is disabled
  - ACLK and SMCLK remain active, MCLK is disabled
- Low-power mode 2 (LPM2)
  - CPU is disabled
  - MCLK and FLL loop control and DCOCLK are disabled
  - DC generator of the DCO remains enabled
  - ACLK remains active
- Low-power mode 3 (LPM3)
  - CPU is disabled
  - MCLK, FLL loop control, and DCOCLK are disabled
  - DC generator of the DCO is disabled
  - ACLK remains active
- Low-power mode 4 (LPM4)
  - CPU is disabled
  - ACLK is disabled
  - MCLK, FLL loop control, and DCOCLK are disabled
  - DC generator of the DCO is disabled
  - Crystal oscillator is stopped
  - Complete data retention

## 6.5 Interrupt Vector Addresses

The interrupt vectors and the power-up start address are in the address range 0FFFFh to 0FF80h. The vector contains the 16-bit address of the appropriate interrupt-handler instruction sequence.

**Table 6-3. Interrupt Sources, Flags, and Vectors**

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
<b>System Reset</b> Power-Up External Reset Watchdog Time-out, Password Violation Flash Memory Password Violation	WDTIFG, KEYV (SYSRSTIV) <sup>(1)</sup> <sup>(2)</sup>	Reset	0FFF Eh	63, highest
<b>System NMI</b> PMM Vacant Memory Access JTAG Mailbox	SVMLIFG, SVMHIFG, DLYLIFG, DLYHIFG, VRLIFG, VLRHIFG, VMAIFG, JMBNIFG, JMBOUTIFG (SYSSNIV) <sup>(1)</sup> <sup>(3)</sup>	(Non)maskable	0FFF Ch	62
<b>User NMI</b> NMI Oscillator Fault Flash Memory Access Violation	NMIIFG, OFIFG, ACCVIFG (SYSUNIV) <sup>(1)</sup> <sup>(3)</sup>	(Non)maskable	0FFF Ah	61
Comparator_B	Comparator_B Interrupt Flags (CBIV) <sup>(1)</sup>	Maskable	0FFF 8h	60
Watchdog Interval Timer Mode	WDTIFG	Maskable	0FFF 6h	59
USCI_A0 Receive or Transmit	UCA0RXIFG, UCA0TXIFG (UCA0IV) <sup>(1)</sup>	Maskable	0FFF 4h	58
USCI_B0 Receive or Transmit	UCB0RXIFG, UCB0TXIFG, I <sup>2</sup> C Status Interrupt Flags (UCB0IV) <sup>(1)</sup>	Maskable	0FFF 2h	57
ADC12_A	ADC12IFG0 ... ADC12IFG15 (ADC12IV) <sup>(1)</sup>	Maskable	0FFF 0h	56
TA0	TA0CCR0 CCIFG0	Maskable	0FFE Eh	55
TA0	TA0CCR1 CCIFG1 ... TA0CCR4 CCIFG4, TA0IFG (TA0IV) <sup>(1)</sup>	Maskable	0FFE Ch	54
RF1A CC1101-based Radio	Radio Interface Interrupt Flags (RF1AIFIV) Radio Core Interrupt Flags (RF1AIV)	Maskable	0FFE Ah	53
DMA	DMA0IFG, DMA1IFG, DMA2IFG (DMAIV) <sup>(1)</sup>	Maskable	0FFE 8h	52
TA1	TA1CCR0 CCIFG0	Maskable	0FFE 6h	51
TA1	TA1CCR1 CCIFG1 ... TA1CCR2 CCIFG2, TA1IFG (TA1IV) <sup>(1)</sup>	Maskable	0FFE 4h	50
I/O Port P1	P1IFG.0 to P1IFG.7 (P1IV) <sup>(1)</sup>	Maskable	0FFE 2h	49
I/O Port P2	P2IFG.0 to P2IFG.7 (P2IV) <sup>(1)</sup>	Maskable	0FFE 0h	48
Reserved	Reserved <sup>(4)</sup>		0FFDEh	47
RTC_A	RTCRDYIFG, RTCTEVIFG, RTCAIFG, RT0PSIFG, RT1PSIFG (RTCIV) <sup>(1)</sup>	Maskable	0FFDCh	46
AES	AESRDYIFG	Maskable	0FFDAh	45
Reserved	Reserved <sup>(4)</sup>		0FFD8h	44
			⋮	⋮
			0FF80h	0, lowest

(1) Multiple source flags

(2) A reset is generated if the CPU tries to fetch instructions from within peripheral space.

(3) (Non)maskable: the individual interrupt-enable bit can disable an interrupt event, but the general interrupt enable cannot disable it.

(4) Reserved interrupt vectors at addresses are not used in this device and can be used for regular program code if necessary. To maintain compatibility with other devices, TI recommends reserving these locations.

## 6.6 Memory Organization

Table 6-4 summarizes the memory organization of the device.

**Table 6-4. Memory Organization**

		<b>RF430F5978<sup>(1)</sup></b>
Main Memory (flash)	Total Size	32KB
		00FFFFh to 00FF80h
Main: code memory	Bank 0	32KB 00FFFFh to 008000h
RAM	Total Size	4KB
	Sect 1	2KB 002BFFh to 002400h
	Sect 0	2KB 0023FFh to 001C00h
Device descriptor		128 B 001AFFh to 001A80h
		128 B 001A7Fh to 001A00h
Information memory (flash)	Info A	128 B 0019FFh to 001980h
	Info B	128 B 00197Fh to 001900h
	Info C	128 B 0018FFh to 001880h
	Info D	128 B 00187Fh to 001800h
Bootloader (BSL) memory (flash)	BSL 3	512 B 0017FFh to 001600h
	BSL 2	512 B 0015FFh to 001400h
	BSL 1	512 B 0013FFh to 001200h
	BSL 0	512 B 0011FFh to 001000h
Peripherals		4KB 000FFFh to 0h

(1) All memory regions not specified here are vacant memory, and any access to them causes a Vacant Memory Interrupt.

## 6.7 Bootloader (BSL)

The BSL enables users to program the flash memory or RAM using various serial interfaces. Access to the device memory through the BSL is protected by an user-defined password. BSL entry requires a specific entry sequence on the RST/NMI/SBWTdio and TEST/SBWTCK pins. For complete description of the features of the BSL and its implementation, see the *MSP430 Programming With the Bootloader User's Guide* ([SLAU319](#)). [Table 6-5](#) lists the BSL in requirements.

**Table 6-5. UART BSL Pin Requirements and Functions**

DEVICE SIGNAL	BSL FUNCTION
<u>RST/NMI/SBWTdio</u>	Entry sequence signal
TEST/SBWTCK	Entry sequence signal
P1.6	Data transmit
P1.5	Data receive
VCC	Power supply
VSS	Ground supply

## 6.8 JTAG Operation

### 6.8.1 JTAG Standard Interface

The RF430F5978 supports the standard JTAG interface, which requires four signals for sending and receiving data. The JTAG signals are shared with general-purpose I/Os. The TEST/SBWTCK pin enables the JTAG signals. In addition to these signals, the RST/NMI/SBWTdio pin is required to interface with MSP430 development tools and device programmers. [Table 6-6](#) lists the JTAG pin requirements. For further details on interfacing to development tools and device programmers, see the *MSP430 Hardware Tools User's Guide* ([SLAU278](#)). For a complete description of the features of the JTAG interface and its implementation, see *MSP430 Programming Via the JTAG Interface* ([SLAU320](#)).

**Table 6-6. JTAG Pin Requirements and Functions**

DEVICE SIGNAL	DIRECTION	FUNCTION
PJ.3/TCK	IN	JTAG clock input
PJ.2/TMS	IN	JTAG state control
PJ.1/TDI/TCLK	IN	JTAG data input, TCLK input
PJ.0/TDO	OUT	JTAG data output
TEST/SBWTCK	IN	Enable JTAG pins
<u>RST/NMI/SBWTdio</u>	IN	External reset
VCC		Power supply
VSS		Ground supply

### 6.8.2 Spy-Bi-Wire Interface

In addition to the standard JTAG interface, the RF430F5978 supports the two-wire Spy-Bi-Wire interface. Spy-Bi-Wire can be used to interface with MSP430 development tools and device programmers. [Table 6-7](#) lists the Spy-Bi-Wire interface pin requirements. For further details on interfacing to development tools and device programmers, see the *MSP430 Hardware Tools User's Guide* ([SLAU278](#)). For a complete description of the features of the JTAG interface and its implementation, see *MSP430 Programming Via the JTAG Interface* ([SLAU320](#)).

**Table 6-7. Spy-Bi-Wire Pin Requirements and Functions**

DEVICE SIGNAL	DIRECTION	FUNCTION
TEST/SBWTCK	IN	Spy-Bi-Wire clock input
<u>RST/NMI/SBWTDO</u>	IN, OUT	Spy-Bi-Wire data input and output
VCC		Power supply
VSS		Ground supply

### 6.9 Flash Memory

The flash memory can be programmed through the JTAG port, Spy-Bi-Wire (SBW), or in-system by the CPU. The CPU can perform single-byte, single-word, and long-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and four segments of information memory (Info A to Info D) of 128 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments Info A to Info D can be erased individually, or as a group with the main memory segments. Segments Info A to Info D are also called *information memory*.
- Segment A can be locked separately.

### 6.10 RAM

The RAM is made up of n sectors. Each sector can be completely powered down to save leakage; however, all data are lost. Features of the RAM include:

- RAM has n sectors of 2KB each.
- Each sector 0 to n can be completely disabled; however, data retention is lost.
- Each sector 0 to n automatically enters low-power retention mode when possible.

## 6.11 Peripherals

Peripherals are connected to the CPU through data, address, and control buses. Peripherals can be handled using all instructions. For complete module descriptions, see the *RF430F5978 User's Guide (SLAU378)*.

### 6.11.1 Oscillator and System Clock

The Unified Clock System (UCS) module includes support for a 32768-Hz watch crystal oscillator, an internal very-low-power low-frequency oscillator (VLO), an internal trimmed low-frequency oscillator (REFO), an integrated internal digitally controlled oscillator (DCO), and a high-frequency crystal oscillator. The UCS module is designed to meet the requirements of both low system cost and low power consumption. The UCS module features digital frequency locked loop (FLL) hardware that, in conjunction with a digital modulator, stabilizes the DCO frequency to a programmable multiple of the watch crystal frequency. The internal DCO provides a fast turnon clock source and stabilizes in less than 5  $\mu$ s. The UCS module provides the following clock signals:

- Auxiliary clock (ACLK), sourced from a 32768-Hz watch crystal, a high-frequency crystal, the internal low-frequency oscillator (VLO), or the trimmed low-frequency oscillator (REFO).
- Main clock (MCLK), the system clock used by the CPU. MCLK can be sourced by same sources made available to ACLK.
- Sub-Main clock (SMCLK), the subsystem clock used by the peripheral modules. SMCLK can be sourced by same sources that are available to ACLK.
- ACLK/n, the buffered output of ACLK, ACLK/2, ACLK/4, ACLK/8, ACLK/16, ACLK/32.

### 6.11.2 Power-Management Module (PMM)

The PMM includes an integrated voltage regulator that supplies the core voltage to the device and contains programmable output levels to provide for power optimization. The PMM also includes supply voltage supervisor (SVS) and supply voltage monitor (SVM) circuitry, as well as brownout protection. The brownout circuit is implemented to provide the proper internal reset signal to the device during power-on and power-off. The SVS and SVM circuitry detects if the supply voltage drops below a user-selectable level and supports both supply voltage supervision (the device is automatically reset) and supply voltage monitoring (the device is not automatically reset). SVS and SVM circuitry is available on the primary supply and core supply.

### 6.11.3 Digital I/O

Five I/O ports are implemented: ports P1 through P3 are 8 bit, P4 is 1 bit, and P5 is 2 bit.

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Programmable pullup or pulldown on all ports.
- Programmable drive strength on all ports.
- Edge-selectable interrupt input capability for all the eight bits of ports P1 and P2.
- Read and write access to port-control registers is supported by all instructions.
- Ports can be accessed byte-wise (P1 through P3) or word-wise in pairs (PA and PB).

#### 6.11.4 Port Mapping Controller

The port mapping controller allows the flexible and reconfigurable mapping of digital functions to port pins of ports P1 through P3. [Table 6-8](#) lists the available port mapping assignments, and [Table 6-9](#) lists the default assignments.

**Table 6-8. Port Mapping Mnemonics and Functions**

VALUE	PxMAPy MNEMONIC	INPUT PIN FUNCTION (PxDIR.y = 0)	OUTPUT PIN FUNCTION (PxDIR.y = 1)
0	PM_NONE	None	DVSS
1 <sup>(1)</sup>	PM_CBOUT0	–	Comparator_B output (on TA0 clock input)
	PM_TA0CLK	TA0 clock input	–
2 <sup>(1)</sup>	PM_CBOUT1	–	Comparator_B output (on TA1 clock input)
	PM_TA1CLK	TA1 clock input	–
3	PM_ACLK	None	ACLK output
4	PM_MCLK	None	MCLK output
5	PM_SMCLK	None	SMCLK output
6	PM_RTCCLK	None	RTCCLK output
7 <sup>(1)</sup>	PM_ADC12CLK	–	ADC12CLK output
	PM_DMAE0	DMA external trigger input	–
8	PM_SVMOUT	None	SVM output
9	PM_TA0CCR0A	TA0 CCR0 capture input CCI0A	TA0 CCR0 compare output Out0
10	PM_TA0CCR1A	TA0 CCR1 capture input CCI1A	TA0 CCR1 compare output Out1
11	PM_TA0CCR2A	TA0 CCR2 capture input CCI2A	TA0 CCR2 compare output Out2
12	PM_TA0CCR3A	TA0 CCR3 capture input CCI3A	TA0 CCR3 compare output Out3
13	PM_TA0CCR4A	TA0 CCR4 capture input CCI4A	TA0 CCR4 compare output Out4
14	PM_TA1CCR0A	TA1 CCR0 capture input CCI0A	TA1 CCR0 compare output Out0
15	PM_TA1CCR1A	TA1 CCR1 capture input CCI1A	TA1 CCR1 compare output Out1
16	PM_TA1CCR2A	TA1 CCR2 capture input CCI2A	TA1 CCR2 compare output Out2
17 <sup>(2)</sup>	PM_UCA0RXD	USCI_A0 UART RXD (direction controlled by USCI – input)	
	PM_UCA0SOMI	USCI_A0 SPI slave out/master in (direction controlled by USCI)	
18 <sup>(2)</sup>	PM_UCA0TXD	USCI_A0 UART TXD (direction controlled by USCI – output)	
	PM_UCA0SIMO	USCI_A0 SPI slave in/master out (direction controlled by USCI)	
19 <sup>(3)</sup>	PM_UCA0CLK	USCI_A0 clock input/output (direction controlled by USCI)	
	PM_UCB0STE	USCI_B0 SPI slave transmit enable (direction controlled by USCI – input)	
20 <sup>(4)</sup>	PM_UCB0SOMI	USCI_B0 SPI slave out/master in (direction controlled by USCI)	
	PM_UCB0SCL	USCI_B0 I <sup>2</sup> C clock (open drain and direction controlled by USCI)	
21 <sup>(4)</sup>	PM_UCB0SIMO	USCI_B0 SPI slave in/master out (direction controlled by USCI)	
	PM_UCB0SDA	USCI_B0 I <sup>2</sup> C data (open drain and direction controlled by USCI)	
22 <sup>(5)</sup>	PM_UCB0CLK	USCI_B0 clock input/output (direction controlled by USCI)	
	PM_UCA0STE	USCI_A0 SPI slave transmit enable (direction controlled by USCI – input)	
23	PM_RFGDO0	Radio GDO0 (direction controlled by radio)	
24	PM_RFGDO1	Radio GDO1 (direction controlled by radio)	
25	PM_RFGDO2	Radio GDO2 (direction controlled by Radio)	

(1) Input or output function is selected by the corresponding setting in the port direction register PxDIR.

(2) UART or SPI functionality is determined by the selected USCI mode.

(3) UCA0CLK function takes precedence over UCB0STE function. If the mapped pin is required as UCA0CLK input or output, USCI\_B0 is forced to 3-wire SPI mode even if 4-wire mode is selected.

(4) SPI or I<sup>2</sup>C functionality is determined by the selected USCI mode. If I<sup>2</sup>C functionality is selected, the output of the mapped pin drives only the logical 0 to V<sub>SS</sub> level.

(5) UCB0CLK function takes precedence over UCA0STE function. If the mapped pin is required as UCB0CLK input or output, USCI\_A0 is forced to 3-wire SPI mode even if 4-wire mode is selected.

**Table 6-8. Port Mapping Mnemonics and Functions (continued)**

VALUE	PxMAPy MNEMONIC	INPUT PIN FUNCTION (PxDIR.y = 0)	OUTPUT PIN FUNCTION (PxDIR.y = 1)
26	Reserved	None	DVSS
27	Reserved	None	DVSS
28	Reserved	None	DVSS
29	Reserved	None	DVSS
30	Reserved	None	DVSS
31 (0FFh) <sup>(6)</sup>	PM_ANALOG	Disables the output driver and the input Schmitt-trigger to prevent parasitic cross currents when applying analog signals.	

(6) The value of the PM\_ANALOG mnemonic is FFh. The port mapping registers are 5 bits wide, and the upper bits are ignored, which results in a read value of 31.

**Table 6-9. Default Mapping**

PIN	PxMAPy MNEMONIC	INPUT PIN FUNCTION (PxDIR.y = 0)	OUTPUT PIN FUNCTION (PxDIR.y = 1)
P1.0/P1MAP0	PM_RFGDO0	None	Radio GDO0
P1.1/P1MAP1	PM_RFGDO2	None	Radio GDO2
P1.2/P1MAP2	PM_UCB0SOMI/PM_UCB0SCL	USCI_B0 SPI slave out/master in (direction controlled by USCI) USCI_B0 I <sup>2</sup> C clock (open drain and direction controlled by USCI)	
P1.3/P1MAP3	PM_UCB0SIMO/PM_UCB0SDA	USCI_B0 SPI slave in/master out (direction controlled by USCI) USCI_B0 I <sup>2</sup> C data (open drain and direction controlled by USCI)	
P1.4/P1MAP4	PM_UCB0CLK/PM_UCA0STE	USCI_B0 clock input/output (direction controlled by USCI) USCI_A0 SPI slave transmit enable (direction controlled by USCI – input)	
P1.5/P1MAP5	PM_UCA0RXD/PM_UCA0SOMI	USCI_A0 UART RXD (direction controlled by USCI – input) USCI_A0 SPI slave out/master in (direction controlled by USCI)	
P1.6/P1MAP6	PM_UCA0TXD/PM_UCA0SIMO	USCI_A0 UART TXD (direction controlled by USCI – output) USCI_A0 SPI slave in/master out (direction controlled by USCI)	
P1.7/P1MAP7	PM_UCA0CLK/PM_UCB0STE	USCI_A0 clock input/output (direction controlled by USCI) USCI_B0 SPI slave transmit enable (direction controlled by USCI – input)	
P2.0/P2MAP0	PM_CBTOUT1/PM_TA1CLK	TA1 clock input	Comparator_B output
P2.1/P2MAP1	PM_TA1CCR0A	TA1 CCR0 capture input CCI0A	TA1 CCR0 compare output Out0
P2.2/P2MAP2	PM_TA1CCR1A	TA1 CCR1 capture input CCI1A	TA1 CCR1 compare output Out1
P2.3/P2MAP3	PM_TA1CCR2A	TA1 CCR2 capture input CCI2A	TA1 CCR2 compare output Out2
P2.4/P2MAP4	PM_RTCCLK	None	RTCCLK output
P2.5/P2MAP5	PM_SVMO	None	SVM output
P2.6/P2MAP6	PM_ACLK	None	ACLK output
P2.7/P2MAP7	PM_ADC12CLK/PM_DMAE0	DMA external trigger input	ADC12CLK output
P3.0/P3MAP0	PM_CBTOUT0/PM_TA0CLK	TA0 clock input	Comparator_B output
P3.1/P3MAP1	PM_TA0CCR0A	TA0 CCR0 capture input CCI0A	TA0 CCR0 compare output Out0
P3.2/P3MAP2	PM_TA0CCR1A	TA0 CCR1 capture input CCI1A	TA0 CCR1 compare output Out1
P3.3/P3MAP3	PM_TA0CCR2A	TA0 CCR2 capture input CCI2A	TA0 CCR2 compare output Out2
P3.4/P3MAP4	PM_TA0CCR3A	TA0 CCR3 capture input CCI3A	TA0 CCR3 compare output Out3
P3.5/P3MAP5	PM_TA0CCR4A	TA0 CCR4 capture input CCI4A	TA0 CCR4 compare output Out4
P3.6/P3MAP6	PM_RFGDO1	None	Radio GDO1
P3.7/P3MAP7	PM_SMCLK	None	SMCLK output

### 6.11.5 System (SYS) Module

The SYS module handles many of the system functions within the device. These functions include power-on reset (POR) and power-up clear (PUC) handling, NMI source selection and management, reset interrupt vector generators, bootloader entry mechanisms, and configuration management (device descriptors). The SYS module also includes a data exchange mechanism through JTAG called a JTAG mailbox that can be used in the application. [Table 6-10](#) lists the interrupt vector registers supported by the SYS module.

**Table 6-10. System Module Interrupt Vector Registers**

INTERRUPT VECTOR REGISTER	ADDRESS	INTERRUPT EVENT	VALUE	PRIORITY
SYSRSTIV, System Reset	019Eh	No interrupt pending	00h	
		Brownout (BOR)	02h	Highest
		RST/NMI (POR)	04h	
		DoBOR (BOR)	06h	
		Reserved	08h	
		Security violation (BOR)	0Ah	
		SVSL (POR)	0Ch	
		SVSH (POR)	0Eh	
		SVML_OVP (POR)	10h	
		SVMH_OVP (POR)	12h	
		DoPOR (POR)	14h	
		WDT time-out (PUC)	16h	
		WDT password violation (PUC)	18h	
		KEYV flash password violation (PUC)	1Ah	
		Reserved	1Ch	
		Peripheral area fetch (PUC)	1Eh	
		PMM password violation (PUC)	20h	
		Reserved	22h to 3Eh	Lowest
SYSSNIV, System NMI	019Ch	No interrupt pending	00h	
		SVMLIFG	02h	Highest
		SVMHIFG	04h	
		DLYLIFG	06h	
		DLYHIFG	08h	
		VMAIFG	0Ah	
		JMBINIFG	0Ch	
		JMBOUTIFG	0Eh	
		VLRLIFG	10h	
		VLRHIFG	12h	
		Reserved	14h to 1Eh	Lowest
SYSUNIV, User NMI	019Ah	No interrupt pending	00h	
		NMIIIFG	02h	Highest
		OFIFG	04h	
		ACCVIFG	06h	
		Reserved	08h to 1Eh	Lowest

### 6.11.6 DMA Controller

The DMA controller allows movement of data from one memory address to another without CPU intervention. Using the DMA controller can increase the throughput of peripheral modules. The DMA controller reduces system power consumption by allowing the CPU to remain in sleep mode, without having to awaken to move data to or from a peripheral. [Table 6-11](#) lists the available DMA trigger assignments.

**Table 6-11. DMA Trigger Assignments<sup>(1)</sup>**

TRIGGER	CHANNEL		
	0	1	2
0	DMAREQ	DMAREQ	DMAREQ
1	TA0CCR0 CCIFG	TA0CCR0 CCIFG	TA0CCR0 CCIFG
2	TA0CCR2 CCIFG	TA0CCR2 CCIFG	TA0CCR2 CCIFG
3	TA1CCR0 CCIFG	TA1CCR0 CCIFG	TA1CCR0 CCIFG
4	TA1CCR2 CCIFG	TA1CCR2 CCIFG	TA1CCR2 CCIFG
5	Reserved	Reserved	Reserved
6	Reserved	Reserved	Reserved
7	Reserved	Reserved	Reserved
8	Reserved	Reserved	Reserved
9	Reserved	Reserved	Reserved
10	Reserved	Reserved	Reserved
11	Reserved	Reserved	Reserved
12	Reserved	Reserved	Reserved
13	Reserved	Reserved	Reserved
14	Reserved	Reserved	Reserved
15	Reserved	Reserved	Reserved
16	UCA0RXIFG	UCA0RXIFG	UCA0RXIFG
17	UCA0TXIFG	UCA0TXIFG	UCA0TXIFG
18	UCB0RXIFG	UCB0RXIFG	UCB0RXIFG
19	UCB0TXIFG	UCB0TXIFG	UCB0TXIFG
20	Reserved	Reserved	Reserved
21	Reserved	Reserved	Reserved
22	Reserved	Reserved	Reserved
23	Reserved	Reserved	Reserved
24	ADC12IFGx	ADC12IFGx	ADC12IFGx
25	Reserved	Reserved	Reserved
26	Reserved	Reserved	Reserved
27	Reserved	Reserved	Reserved
28	Reserved	Reserved	Reserved
29	MPY ready	MPY ready	MPY ready
30	DMA2IFG	DMA0IFG	DMA1IFG
31	DMAE0	DMAE0	DMAE0

(1) Reserved DMA triggers may be used by other devices in the family. Reserved DMA triggers do not cause any DMA trigger event when selected.

### **6.11.7 Watchdog Timer (WDT\_A)**

The primary function of the watchdog timer is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the timer can be configured as an interval timer and can generate interrupts at selected time intervals.

### **6.11.8 CRC16**

The CRC16 module produces a signature based on a sequence of entered data values and can be used for data checking purposes. The CRC16 module signature is based on the CRC-CCITT standard.

### **6.11.9 Hardware Multiplier**

The multiplication operation is supported by a dedicated peripheral module. The module performs operations with 32-, 24-, 16-, and 8-bit operands. The module supports signed and unsigned multiplication as well as signed and unsigned multiply-and-accumulate operations.

### **6.11.10 AES128 Accelerator**

The AES accelerator module performs encryption and decryption of 128-bit data with 128-bit keys according to the Advanced Encryption Standard (AES) (FIPS PUB 197) in hardware.

### **6.11.11 Universal Serial Communication Interface (USCI)**

The USCI module is used for serial data communication. The USCI module supports synchronous communication protocols such as SPI (3 or 4 pin) and I<sup>2</sup>C, and asynchronous communication protocols such as UART, enhanced UART with automatic baud-rate detection, and IrDA.

The USCI\_An module provides support for SPI (3- or 4-pin), UART, enhanced UART, and IrDA.

The USCI\_Bn module provides support for SPI (3- or 4-pin) and I<sup>2</sup>C.

A USCI\_A0 and USCI\_B0 module are implemented.

### 6.11.12 TA0

TA0 is a 16-bit timer/counter (Timer\_A type) with five capture/compare registers. TA0 can support multiple capture/comparisons, PWM outputs, and interval timing. TA0 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers (see [Table 6-12](#)).

**Table 6-12. TA0 Signal Connections**

DEVICE INPUT SIGNAL	MODULE INPUT NAME	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
PM_TA0CLK	TACLK	Timer	NA	
ACLK (internal)	ACLK			
SMCLK (internal)	SMCLK			
RFCLK/192 <sup>(1)</sup>	INCLK			
PM_TA0CCR0A	CCI0A	CCR0	TA0	PM_TA0CCR0A
DV <sub>SS</sub>	CCI0B			
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			
PM_TA0CCR1A	CCI1A	CCR1	TA1	PM_TA0CCR1A
CBOUT (internal)	CCI1B			ADC12 (internal) ADC12SHSx = {1}
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			
PM_TA0CCR2A	CCI2A	CCR2	TA2	PM_TA0CCR2A
ACLK (internal)	CCI2B			
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			
PM_TA0CCR3A	CCI3A	CCR3	TA3	PM_TA0CCR3A
GDO1 from Radio (internal)	CCI3B			
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			
PM_TA0CCR4A	CCI4A	CCR4	TA4	PM_TA0CCR4A
GDO2 from Radio (internal)	CCI4B			
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			

(1) If a different RFCLK divider setting is selected for a radio GDO output, this divider setting is also used for the Timer\_A INCLK.

### 6.11.13 TA1

TA1 is a 16-bit timer/counter (Timer\_A type) with three capture/compare registers. TA1 can support multiple capture/comparisons, PWM outputs, and interval timing. TA1 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers (see [Table 6-13](#)).

**Table 6-13. TA1 Signal Connections**

DEVICE INPUT SIGNAL	MODULE INPUT NAME	MODULE BLOCK	MODULE OUTPUT SIGNAL	DEVICE OUTPUT SIGNAL
				PZ
PM_TA1CLK	TACLK	Timer	NA	
ACLK (internal)	ACLK			
SMCLK (internal)	SMCLK			
RFCLK/192 <sup>(1)</sup>	INCLK			
PM_TA1CCR0A	CCI0A			PM_TA1CCR0A
RF Async. Output (internal)	CCI0B	CCR0	TA0	RF Async. Input (internal)
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			
PM_TA1CCR1A	CCI1A			PM_TA1CCR1A
CBOUT (internal)	CCI1B	CCR1	TA1	
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			
PM_TA1CCR2A	CCI2A			PM_TA1CCR2A
ACLK (internal)	CCI2B	CCR2	TA2	
DV <sub>SS</sub>	GND			
DV <sub>CC</sub>	V <sub>CC</sub>			

(1) If a different RFCLK divider setting is selected for a radio GDO output, this divider setting is also used for the Timer\_A INCLK.

### 6.11.14 Real-Time Clock (RTC\_A)

The RTC\_A module can be used as a general-purpose 32-bit counter (counter mode) or as an integrated real-time clock (RTC) (calendar mode). In counter mode, the RTC\_A also includes two independent 8-bit timers that can be cascaded to form a 16-bit timer/counter. Both timers can be read and written by software. Calendar mode integrates an internal calendar which compensates for months with less than 31 days and includes leap year correction. The RTC\_A also supports flexible alarm functions and offset-calibration hardware.

### 6.11.15 REF Voltage Reference

The reference module (REF) is responsible for generation of all critical reference voltages that can be used by the various analog peripherals in the device. These include the ADC12\_A, LCD\_B, and COMP\_B modules.

### 6.11.16 Comparator\_B

The primary function of the Comparator\_B module is to support precision slope analog-to-digital conversions, battery voltage supervision, and monitoring of external analog signals.

### 6.11.17 ADC12\_A

The ADC12\_A module supports fast, 12-bit analog-to-digital conversions. The module implements a 12-bit SAR core, sample select control, reference generator and a 16 word conversion-and-control buffer. The conversion-and-control buffer allows up to 16 independent ADC samples to be converted and stored without any CPU intervention.

### 6.11.18 Embedded Emulation Module (EEM) (S Version)

The EEM supports real-time in-system debugging. The S version of the EEM has the following features:

- Three hardware triggers or breakpoints on memory access
- One hardware trigger or breakpoint on CPU register write access
- Up to four hardware triggers can be combined to form complex triggers or breakpoints
- One cycle counter
- Clock control on module level

### 6.11.19 Peripheral File Map

Table 6-14 lists the register base address and offset range for each peripheral. Table 6-15 through Table 6-45 list the registers that are available in each peripheral.

**Table 6-14. Peripherals**

MODULE NAME	BASE ADDRESS	OFFSET ADDRESS RANGE
Special Functions (see Table 6-15)	0100h	000h-01Fh
PMM (see Table 6-16)	0120h	000h-00Fh
Flash Control (see Table 6-17)	0140h	000h-00Fh
CRC16 (see Table 6-18)	0150h	000h-007h
RAM Control (see Table 6-19)	0158h	000h-001h
Watchdog (see Table 6-20)	015Ch	000h-001h
UCS (see Table 6-21)	0160h	000h-01Fh
SYS (see Table 6-22)	0180h	000h-01Fh
Shared Reference (see Table 6-23)	01B0h	000h-001h
Port Mapping Control (see Table 6-24)	01C0h	000h-007h
Port Mapping Port P1 (see Table 6-25)	01C8h	000h-007h
Port Mapping Port P2 (see Table 6-26)	01D0h	000h-007h
Port Mapping Port P3 (see Table 6-27)	01D8h	000h-007h
Port P1, P2 (see Table 6-28)	0200h	000h-01Fh
Port P3, P4 (see Table 6-29)	0220h	000h-01Fh
Port P5 (see Table 6-30)	0240h	000h-01Fh
Port PJ (see Table 6-31)	0320h	000h-01Fh
TA0 (see Table 6-32)	0340h	000h-03Fh
TA1 (see Table 6-33)	0380h	000h-03Fh
RTC_A (see Table 6-34)	04A0h	000h-01Fh
32-Bit Hardware Multiplier (see Table 6-35)	04C0h	000h-02Fh
DMA Module Control (see Table 6-36)	0500h	000h-00Fh
DMA Channel 0 (see Table 6-37)	0510h	000h-00Fh
DMA Channel 1 (see Table 6-38)	0520h	000h-00Fh
DMA Channel 2 (see Table 6-39)	0530h	000h-00Fh
USCI_A0 (see Table 6-40)	05C0h	000h-01Fh
USCI_B0 (see Table 6-41)	05E0h	000h-01Fh
ADC12 (see Table 6-42)	0700h	000h-03Fh
Comparator_B (see Table 6-43)	08C0h	000h-00Fh
AES Accelerator (see Table 6-44)	09C0h	000h-00Fh
Radio Interface (see Table 6-45)	0F00h	000h-03Fh

**Table 6-15. Special Function Registers (Base Address: 0100h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
SFR interrupt enable	SFRIE1	00h
SFR interrupt flag	SFRIFG1	02h
SFR reset pin control	SFRRPCR	04h

**Table 6-16. PMM Registers (Base Address: 0120h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
PMM control 0	PMMCTL0	00h
PMM control 1	PMMCTL1	02h
SVS high-side control	SVSMHCTL	04h
SVS low-side control	SVSMLCTL	06h
PMM interrupt flags	PMMIFG	0Ch
PMM interrupt enable	PMMIE	0Eh
PMM power mode 5 control	PM5CTL0	10h

**Table 6-17. Flash Control Registers (Base Address: 0140h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Flash control 1	FCTL1	00h
Flash control 3	FCTL3	04h
Flash control 4	FCTL4	06h

**Table 6-18. CRC16 Registers (Base Address: 0150h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
CRC data input	CRC16DI	00h
CRC data input reverse byte	CRCDIRB	02h
CRC initialization and result	CRCINIRES	04h
CRC result reverse byte	CRCRESR	06h

**Table 6-19. RAM Control Registers (Base Address: 0158h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
RAM control 0	RCCTL0	00h

**Table 6-20. Watchdog Registers (Base Address: 015Ch)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Watchdog timer control	WDTCTL	00h

**Table 6-21. UCS Registers (Base Address: 0160h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
UCS control 0	UCSCTL0	00h
UCS control 1	UCSCTL1	02h
UCS control 2	UCSCTL2	04h
UCS control 3	UCSCTL3	06h
UCS control 4	UCSCTL4	08h
UCS control 5	UCSCTL5	0Ah
UCS control 6	UCSCTL6	0Ch
UCS control 7	UCSCTL7	0Eh
UCS control 8	UCSCTL8	10h

**Table 6-22. SYS Registers (Base Address: 0180h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
System control	SYSCTL	00h
Bootloader configuration area	SYSBSLC	02h
JTAG mailbox control	SYSJMBC	06h
JTAG mailbox input 0	SYSJMBI0	08h
JTAG mailbox input 1	SYSJMBI1	0Ah
JTAG mailbox output 0	SYSJMBO0	0Ch
JTAG mailbox output 1	SYSJMBO1	0Eh
Bus error vector generator	SYSBERRIV	18h
User NMI vector generator	SYSUNIV	1Ah
System NMI vector generator	SYSSNIV	1Ch
Reset vector generator	SYSRSTIV	1Eh

**Table 6-23. Shared Reference Registers (Base Address: 01B0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Shared reference control	REFCTL	00h

**Table 6-24. Port Mapping Control Registers (Base Address: 01C0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port mapping key register	PMAPKEYID	00h
Port mapping control register	PMAPCTL	02h

**Table 6-25. Port Mapping Port P1 Registers (Base Address: 01C8h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P1.0 mapping register	P1MAP0	00h
Port P1.1 mapping register	P1MAP1	01h
Port P1.2 mapping register	P1MAP2	02h
Port P1.3 mapping register	P1MAP3	03h
Port P1.4 mapping register	P1MAP4	04h
Port P1.5 mapping register	P1MAP5	05h
Port P1.6 mapping register	P1MAP6	06h
Port P1.7 mapping register	P1MAP7	07h

**Table 6-26. Port Mapping Port P2 Registers (Base Address: 01D0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P2.0 mapping register	P2MAP0	00h
Port P2.1 mapping register	P2MAP2	01h
Port P2.2 mapping register	P2MAP2	02h
Port P2.3 mapping register	P2MAP3	03h
Port P2.4 mapping register	P2MAP4	04h
Port P2.5 mapping register	P2MAP5	05h
Port P2.6 mapping register	P2MAP6	06h
Port P2.7 mapping register	P2MAP7	07h

**Table 6-27. Port Mapping Port P3 Registers (Base Address: 01D8h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P3.0 mapping register	P3MAP0	00h
Port P3.1 mapping register	P3MAP3	01h
Port P3.2 mapping register	P3MAP2	02h
Port P3.3 mapping register	P3MAP3	03h
Port P3.4 mapping register	P3MAP4	04h
Port P3.5 mapping register	P3MAP5	05h
Port P3.6 mapping register	P3MAP6	06h
Port P3.7 mapping register	P3MAP7	07h

**Table 6-28. Port P1, P2 Registers (Base Address: 0200h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P1 input	P1IN	00h
Port P1 output	P1OUT	02h
Port P1 direction	P1DIR	04h
Port P1 pullup or pulldown enable	P1REN	06h
Port P1 drive strength	P1DS	08h
Port P1 selection	P1SEL	0Ah
Port P1 interrupt vector word	P1IV	0Eh
Port P1 interrupt edge select	P1IES	18h
Port P1 interrupt enable	P1IE	1Ah
Port P1 interrupt flag	P1IFG	1Ch
Port P2 input	P2IN	01h
Port P2 output	P2OUT	03h
Port P2 direction	P2DIR	05h
Port P2 pullup or pulldown enable	P2REN	07h
Port P2 drive strength	P2DS	09h
Port P2 selection	P2SEL	0Bh
Port P2 interrupt vector word	P2IV	1Eh
Port P2 interrupt edge select	P2IES	19h
Port P2 interrupt enable	P2IE	1Bh
Port P2 interrupt flag	P2IFG	1Dh

**Table 6-29. Port P3, P4 Registers (Base Address: 0220h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P3 input	P3IN	00h
Port P3 output	P3OUT	02h
Port P3 direction	P3DIR	04h
Port P3 pullup or pulldown enable	P3REN	06h
Port P3 drive strength	P3DS	08h
Port P3 selection	P3SEL	0Ah

**Table 6-30. Port P5 Registers (Base Address: 0240h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port P5 input	P5IN	00h
Port P5 output	P5OUT	02h
Port P5 direction	P5DIR	04h
Port P5 pullup or pulldown enable	P5REN	06h
Port P5 drive strength	P5DS	08h
Port P5 selection	P5SEL	0Ah

**Table 6-31. Port J Registers (Base Address: 0320h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Port PJ input	PJIN	00h
Port PJ output	PJOUT	02h
Port PJ direction	PJDIR	04h
Port PJ pullup or pulldown enable	PJREN	06h
Port PJ drive strength	PJDS	08h

**Table 6-32. TA0 Registers (Base Address: 0340h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
TA0 control	TA0CTL	00h
Capture/compare control 0	TA0CCTL0	02h
Capture/compare control 1	TA0CCTL1	04h
Capture/compare control 2	TA0CCTL2	06h
Capture/compare control 3	TA0CCTL3	08h
Capture/compare control 4	TA0CCTL4	0Ah
TA0 counter	TA0R	10h
Capture/compare register 0	TA0CCR0	12h
Capture/compare register 1	TA0CCR1	14h
Capture/compare register 2	TA0CCR2	16h
Capture/compare register 3	TA0CCR3	18h
Capture/compare register 4	TA0CCR4	1Ah
TA0 expansion register 0	TA0EX0	20h
TA0 interrupt vector	TA0IV	2Eh

**Table 6-33. TA1 Registers (Base Address: 0380h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
TA1 control	TA1CTL	00h
Capture/compare control 0	TA1CCTL0	02h
Capture/compare control 1	TA1CCTL1	04h
Capture/compare control 2	TA1CCTL2	06h
TA1 counter	TA1R	10h
Capture/compare register 0	TA1CCR0	12h
Capture/compare register 1	TA1CCR1	14h
Capture/compare register 2	TA1CCR2	16h
TA1 expansion register 0	TA1EX0	20h
TA1 interrupt vector	TA1IV	2Eh

**Table 6-34. Real-Time Clock Registers (Base Address: 04A0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
RTC control 0	RTCCTL0	00h
RTC control 1	RTCCTL1	01h
RTC control 2	RTCCTL2	02h
RTC control 3	RTCCTL3	03h
RTC prescaler 0 control	RTCPS0CTL	08h
RTC prescaler 1 control	RTCPS1CTL	0Ah
RTC prescaler 0	RTCPS0	0Ch
RTC prescaler 1	RTCPS1	0Dh
RTC interrupt vector word	RTCIV	0Eh
RTC seconds/counter register 1	RTCSEC/RTCNT1	10h
RTC minutes/counter register 2	RTCMIN/RTCNT2	11h
RTC hours/counter register 3	RTCHOUR/RTCNT3	12h
RTC day of week/counter register 4	RTCDOW/RTCNT4	13h
RTC days	RTCDAY	14h
RTC month	RTCMON	15h
RTC year low	RTCYEARL	16h
RTC year high	RTCYEARH	17h
RTC alarm minutes	RTCAMIN	18h
RTC alarm hours	RTCAHOUR	19h
RTC alarm day of week	RTCADOW	1Ah
RTC alarm days	RTCADAY	1Bh

**Table 6-35. 32-Bit Hardware Multiplier Registers (Base Address: 04C0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
16-bit operand 1 – multiply	MPY	00h
16-bit operand 1 – signed multiply	MPYS	02h
16-bit operand 1 – multiply accumulate	MAC	04h
16-bit operand 1 – signed multiply accumulate	MACS	06h
16-bit operand 2	OP2	08h
16 × 16 result low word	RESLO	0Ah
16 × 16 result high word	RESHI	0Ch
16 × 16 sum extension register	SUMEXT	0Eh
32-bit operand 1 – multiply low word	MPY32L	10h
32-bit operand 1 – multiply high word	MPY32H	12h
32-bit operand 1 – signed multiply low word	MPYS32L	14h
32-bit operand 1 – signed multiply high word	MPYS32H	16h
32-bit operand 1 – multiply accumulate low word	MAC32L	18h
32-bit operand 1 – multiply accumulate high word	MAC32H	1Ah
32-bit operand 1 – signed multiply accumulate low word	MACS32L	1Ch
32-bit operand 1 – signed multiply accumulate high word	MACS32H	1Eh
32-bit operand 2 – low word	OP2L	20h
32-bit operand 2 – high word	OP2H	22h
32 × 32 result 0 – least significant word	RES0	24h
32 × 32 result 1	RES1	26h
32 × 32 result 2	RES2	28h
32 × 32 result 3 – most significant word	RES3	2Ah
MPY32 control register 0	MPY32CTL0	2Ch

**Table 6-36. DMA Module Control Registers (Base Address: 0500h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA module control 0	DMACTL0	00h
DMA module control 1	DMACTL1	02h
DMA module control 2	DMACTL2	04h
DMA module control 3	DMACTL3	06h
DMA module control 4	DMACTL4	08h
DMA interrupt vector	DMAIV	0Ah

**Table 6-37. DMA Channel 0 Registers (Base Address: 0510h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA channel 0 control	DMA0CTL	00h
DMA channel 0 source address low	DMA0SAL	02h
DMA channel 0 source address high	DMA0SAH	04h
DMA channel 0 destination address low	DMA0DAL	06h
DMA channel 0 destination address high	DMA0DAH	08h
DMA channel 0 transfer size	DMA0SZ	0Ah

**Table 6-38. DMA Channel 1 Registers (Base Address: 0520h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA channel 1 control	DMA1CTL	00h
DMA channel 1 source address low	DMA1SAL	02h
DMA channel 1 source address high	DMA1SAH	04h
DMA channel 1 destination address low	DMA1DAL	06h
DMA channel 1 destination address high	DMA1DAH	08h
DMA channel 1 transfer size	DMA1SZ	0Ah

**Table 6-39. DMA Channel 2 Registers (Base Address: 0530h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
DMA channel 2 control	DMA2CTL	00h
DMA channel 2 source address low	DMA2SAL	02h
DMA channel 2 source address high	DMA2SAH	04h
DMA channel 2 destination address low	DMA2DAL	06h
DMA channel 2 destination address high	DMA2DAH	08h
DMA channel 2 transfer size	DMA2SZ	0Ah

**Table 6-40. USCI\_A0 Registers (Base Address: 05C0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
USCI control 1	UCA0CTL1	00h
USCI control 0	UCA0CTL0	01h
USCI baud rate 0	UCA0BR0	06h
USCI baud rate 1	UCA0BR1	07h
USCI modulation control	UCA0MCTL	08h
USCI status	UCA0STAT	0Ah
USCI receive buffer	UCA0RXBUF	0Ch
USCI transmit buffer	UCA0TXBUF	0Eh
USCI LIN control	UCA0ABCTL	10h
USCI IrDA transmit control	UCA0IRCTL	12h
USCI IrDA receive control	UCA0IRRCTL	13h
USCI interrupt enable	UCA0IE	1Ch
USCI interrupt flags	UCA0IFG	1Dh
USCI interrupt vector word	UCA0IV	1Eh

**Table 6-41. USCI\_B0 Registers (Base Address: 05E0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
USCI synchronous control 1	UCB0CTL1	00h
USCI synchronous control 0	UCB0CTL0	01h
USCI synchronous bit rate 0	UCB0BR0	06h
USCI synchronous bit rate 1	UCB0BR1	07h
USCI synchronous status	UCB0STAT	0Ah
USCI synchronous receive buffer	UCB0RXBUF	0Ch
USCI synchronous transmit buffer	UCB0TXBUF	0Eh
USCI I2C own address	UCB0I2COA	10h
USCI I2C slave address	UCB0I2CSA	12h
USCI interrupt enable	UCB0IE	1Ch
USCI interrupt flags	UCB0IFG	1Dh
USCI interrupt vector word	UCB0IV	1Eh

**Table 6-42. ADC12\_A Registers (Base Address: 0700h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Control register 0	ADC12CTL0	00h
Control register 1	ADC12CTL1	02h
Control register 2	ADC12CTL2	04h
Interrupt-flag register	ADC12IFG	0Ah
Interrupt-enable register	ADC12IE	0Ch
Interrupt-vector-word register	ADC12IV	0Eh
ADC memory-control register 0	ADC12MCTL0	10h
ADC memory-control register 1	ADC12MCTL1	11h
ADC memory-control register 2	ADC12MCTL2	12h
ADC memory-control register 3	ADC12MCTL3	13h
ADC memory-control register 4	ADC12MCTL4	14h
ADC memory-control register 5	ADC12MCTL5	15h
ADC memory-control register 6	ADC12MCTL6	16h
ADC memory-control register 7	ADC12MCTL7	17h
ADC memory-control register 8	ADC12MCTL8	18h
ADC memory-control register 9	ADC12MCTL9	19h
ADC memory-control register 10	ADC12MCTL10	1Ah
ADC memory-control register 11	ADC12MCTL11	1Bh
ADC memory-control register 12	ADC12MCTL12	1Ch
ADC memory-control register 13	ADC12MCTL13	1Dh
ADC memory-control register 14	ADC12MCTL14	1Eh
ADC memory-control register 15	ADC12MCTL15	1Fh
Conversion memory 0	ADC12MEM0	20h
Conversion memory 1	ADC12MEM1	22h
Conversion memory 2	ADC12MEM2	24h
Conversion memory 3	ADC12MEM3	26h
Conversion memory 4	ADC12MEM4	28h
Conversion memory 5	ADC12MEM5	2Ah
Conversion memory 6	ADC12MEM6	2Ch
Conversion memory 7	ADC12MEM7	2Eh
Conversion memory 8	ADC12MEM8	30h
Conversion memory 9	ADC12MEM9	32h
Conversion memory 10	ADC12MEM10	34h
Conversion memory 11	ADC12MEM11	36h
Conversion memory 12	ADC12MEM12	38h
Conversion memory 13	ADC12MEM13	3Ah
Conversion memory 14	ADC12MEM14	3Ch
Conversion memory 15	ADC12MEM15	3Eh

**Table 6-43. Comparator\_B Registers (Base Address: 08C0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Comp_B control register 0	CBCTL0	00h
Comp_B control register 1	CBCTL1	02h
Comp_B control register 2	CBCTL2	04h
Comp_B control register 3	CBCTL3	06h
Comp_B interrupt register	CBINT	0Ch
Comp_B interrupt vector word	CBIV	0Eh

**Table 6-44. AES Accelerator Registers (Base Address: 09C0h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
AES accelerator control register 0	AESACTL0	00h
Reserved		02h
AES accelerator status register	AESASTAT	04h
AES accelerator key register	AESAKEY	06h
AES accelerator data in register	AESADIN	008h
AES accelerator data out register	AESADOUT	00Ah

**Table 6-45. Radio Interface Registers (Base Address: 0F00h)**

REGISTER DESCRIPTION	REGISTER	OFFSET
Radio interface control 0	RF1AIFCTL0	00h
Radio interface control 1	RF1AIFCTL1	02h
Radio interface error flag	RF1AIFERR	06h
Radio interface error vector word	RF1AIFERRV	0Ch
Radio interface interrupt vector word	RF1AIFIV	0Eh
Radio instruction word	RF1AINSTRW	10h
Radio instruction word, 1-byte auto-read	RF1AINSTR1W	12h
Radio instruction word, 2-byte auto-read	RF1AINSTR2W	14h
Radio data in register	RF1ADINW	16h
Radio status word	RF1ASTATW	20h
Radio status word, 1-byte auto-read	RF1ASTAT1W	22h
Radio status word, 2-byte auto-read	RF1AISTAT2W	24h
Radio data out	RF1ADOUTW	28h
Radio data out, 1-byte auto-read	RF1ADOUT1W	2Ah
Radio data out, 2-byte auto-read	RF1ADOUT2W	2Ch
Radio core signal input	RF1AIN	30h
Radio core interrupt flag	RF1AIFG	32h
Radio core interrupt edge select	RF1AIES	34h
Radio core interrupt enable	RF1AIE	36h
Radio core interrupt vector word	RF1AIV	38h

## 6.12 Input/Output Schematics

### 6.12.1 Port P1, P1.0 to P1.4, Input/Output With Schmitt Trigger

Figure 6-3 shows the port schematic, and Table 6-46 summarizes selection of the pin function.

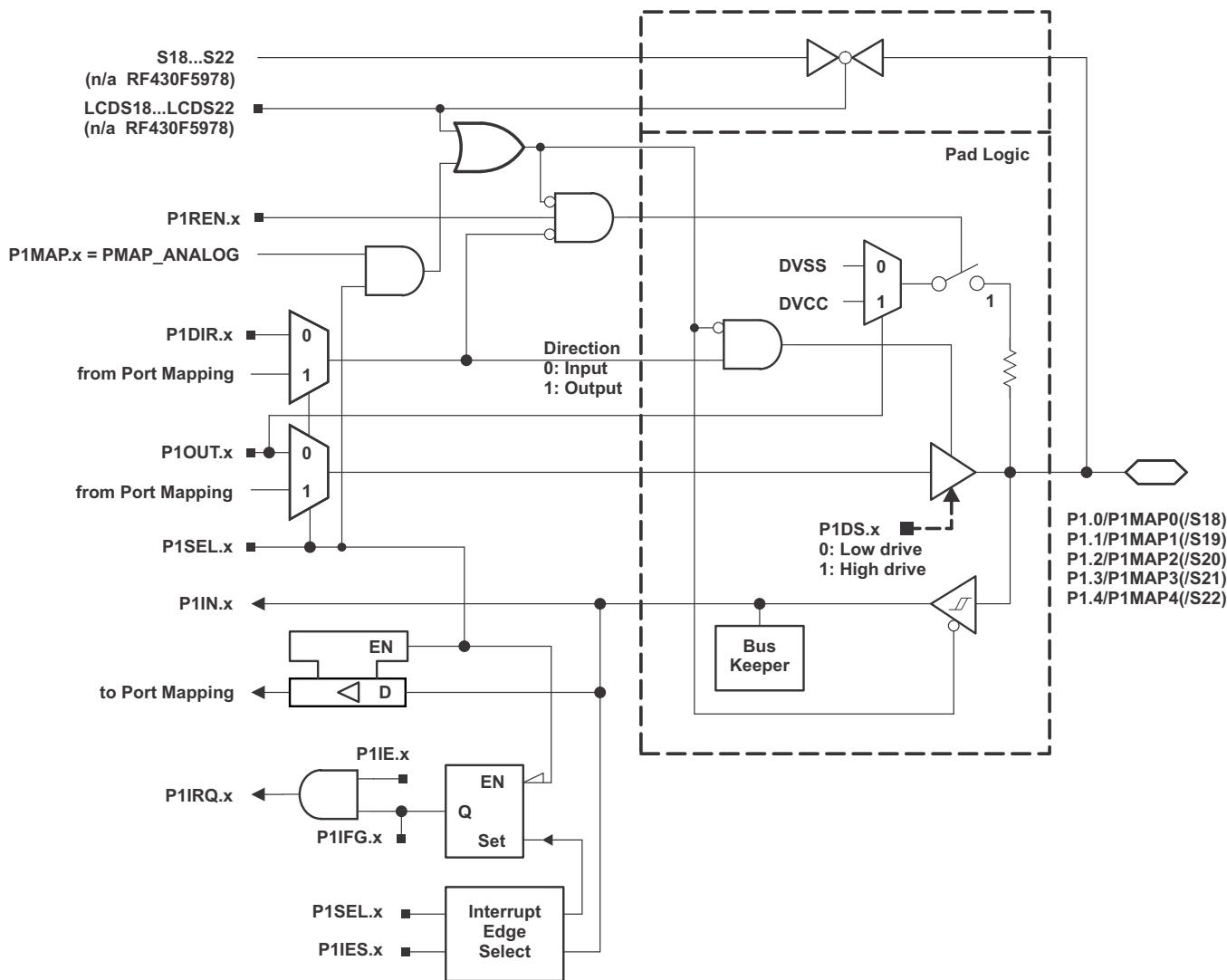


Figure 6-3. Port P1 (P1.0 to P1.4) Schematic

**Table 6-46. Port P1 (P1.0 to P1.4) Pin Functions**

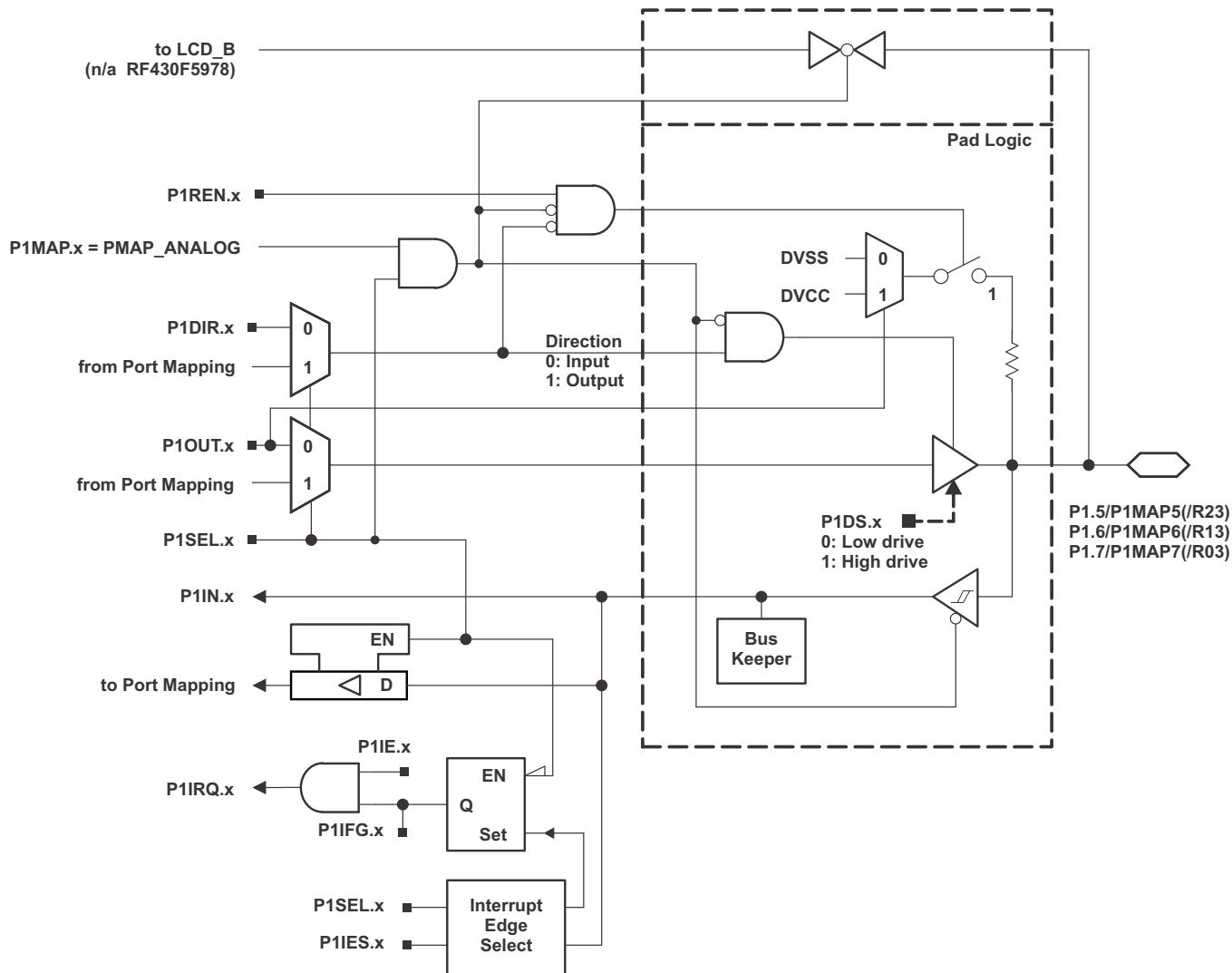
PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>			
			P1DIR.x	P1SEL.x	P1MAPx	LCDS19 to LCDS22
P1.0/P1MAP/S18	0	P1.0 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	≤ 30 <sup>(2)</sup>	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S18	X	X	X	1
P1.1/P1MAP1/S19	1	P1.1 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	≤ 30 <sup>(2)</sup>	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S19	X	X	X	1
P1.2/P1MAP2/S20	2	P1.2 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	≤ 30 <sup>(2)</sup>	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S20	X	X	X	1
P1.3/P1MAP3/S21	3	P1.3 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	≤ 30 <sup>(2)</sup>	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S21	X	X	X	1
P1.4/P1MAP4/S22	4	P1.4 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	≤ 30 <sup>(2)</sup>	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S22	X	X	X	1

(1) X = don't care

(2) According to mapped function - see [Table 6-8](#).

### 6.12.2 Port P1, P1.5 to P1.7, Input/Output With Schmitt Trigger

Figure 6-4 shows the port schematic, and Table 6-47 summarizes selection of the pin function.



**Figure 6-4. Port P1 (P1.5 to P1.7) Schematic**

**Table 6-47. Port P1 (P1.5 to P1.7) Pin Functions**

PIN NAME (P1.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>		
			P1DIR.x	P1SEL.x	P1MAPx
P1.5/P1MAP5/R23	5	P1.5 (I/O)	I: 0; O: 1	0	X
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$
		R23 <sup>(3)</sup>	X	1	= 31
P1.6/P1MAP6/R13/ LCDREF	6	P1.6 (I/O)	I: 0; O: 1	0	X
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$
		R13/LCDREF <sup>(3)</sup>	X	1	= 31
P1.7/P1MAP7/R03	7	P1.7 (I/O)	I: 0; O: 1	0	X
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$
		R03 <sup>(3)</sup>	X	1	= 31

(1) X = don't care

(2) According to mapped function - see [Table 6-8](#).

(3) Setting P1SEL.x bit together with P1MAPx = PM\_ANALOG disables the output driver and the input Schmitt trigger.

### 6.12.3 Port P2, P2.0 to P2.2, Input/Output With Schmitt Trigger

Figure 6-5 shows the port schematic, and [Table 6-48](#) summarizes selection of the pin function.

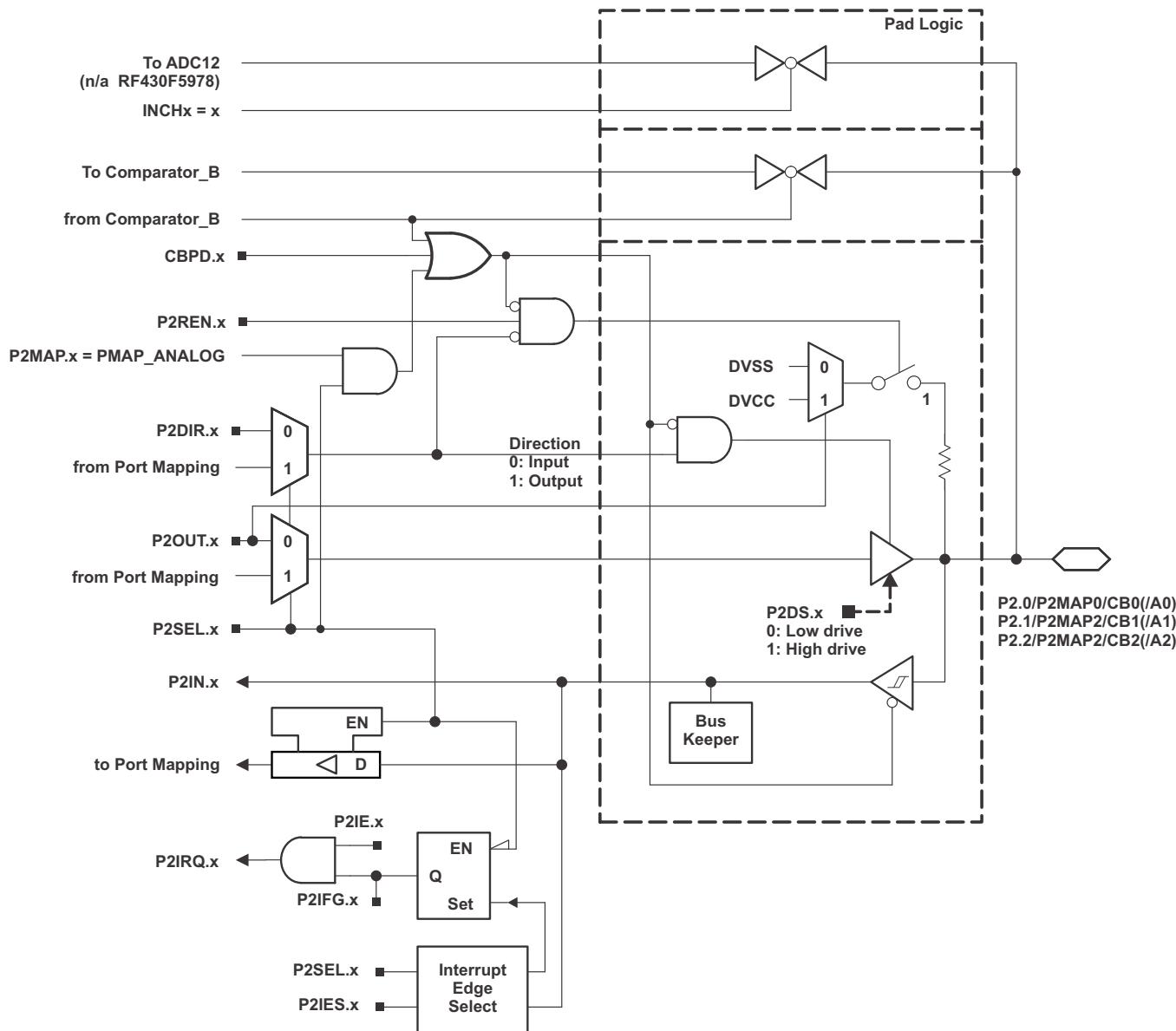


Figure 6-5. Port P2 (P2.0 to P2.2) Schematic

### 6.12.4 Port P2, P2.4 and P2.5, Input/Output With Schmitt Trigger

Figure 6-6 shows the port schematic, and Table 6-48 summarizes selection of the pin function.

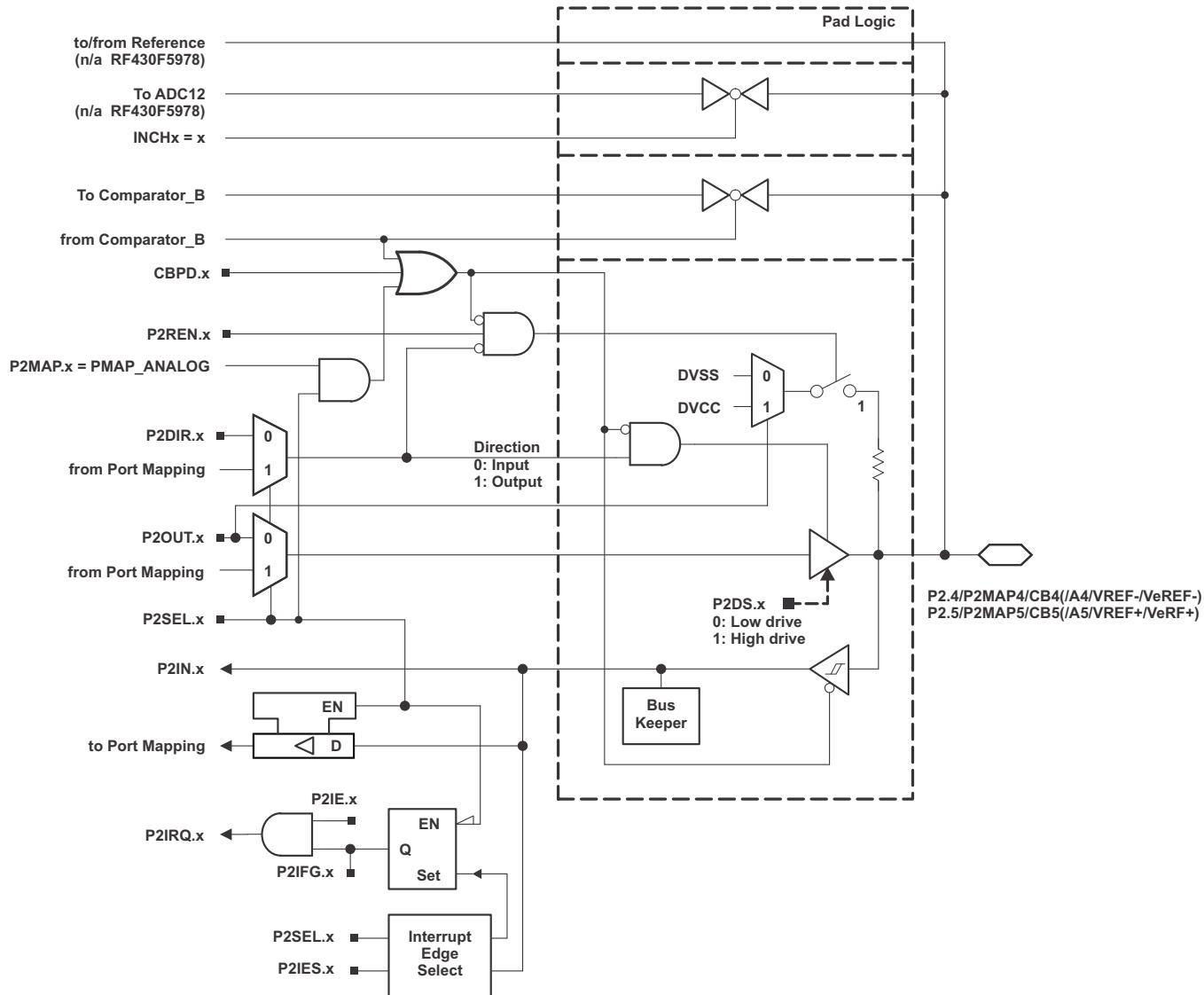


Figure 6-6. Port P2 (P2.4 and P2.5) Schematic

**Table 6-48. Port P2 (P2.0 to P2.2, P2.4, and P2.5) Pin Functions**

PIN NAME (P2.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>			
			P2DIR.x	P2SEL.x	P2MAPx	CBPD.x
P2.0/P2MAP0/CB0 (/A0)	0	P2.0 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$	0
		A0 <sup>(3)</sup>	X	1	= 31	X
		CB0 <sup>(4)</sup>	X	X	X	1
P2.1/P2MAP1/CB1 (/A1)	1	P2.1 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$	0
		A1 <sup>(3)</sup>	X	1	= 31	X
		CB1 <sup>(4)</sup>	X	X	X	1
P2.2/P2MAP2/CB2 (/A2)	2	P2.2 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$	0
		A2 <sup>(3)</sup>	X	1	= 31	X
		CB2 <sup>(4)</sup>	X	X	X	1
P2.4/P2MAP4/CB4 (/A4/VREF-/VeREF-)	4	P2.4 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$	0
		A4/VREF-/VeREF- <sup>(3)</sup>	X	1	= 31	X
		CB4 <sup>(4)</sup>	X	X	X	1
P2.5/P2MAP5/CB5 (/A5/VREF+/VeREF+)	5	P2.5 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(2)</sup>	1	$\leq 30^{(2)}$	0
		A5/VREF+/VeREF+ <sup>(3)</sup>	X	1	= 31	X
		CB5 <sup>(4)</sup>	X	X	X	1

(1) X = don't care

(2) According to mapped function - see [Table 6-8](#).

(3) Setting P2SEL.x bit together with P2MAPx = PM\_ANALOG disables the output driver and the input Schmitt trigger.

(4) Setting the CBPD.x bit disables the output driver and the input Schmitt trigger to prevent parasitic cross currents when applying analog signals. Selecting the CBx input pin to the comparator multiplexer with the CBx bits automatically disables output driver and input buffer for that pin, regardless of the state of the associated CBPD.x bit.

### 6.12.5 Port P3, P3.1 to P3.3, P3.5, and P3.7, Input/Output With Schmitt Trigger

Figure 6-7 shows the port schematic, and Table 6-49 summarizes selection of the pin function.

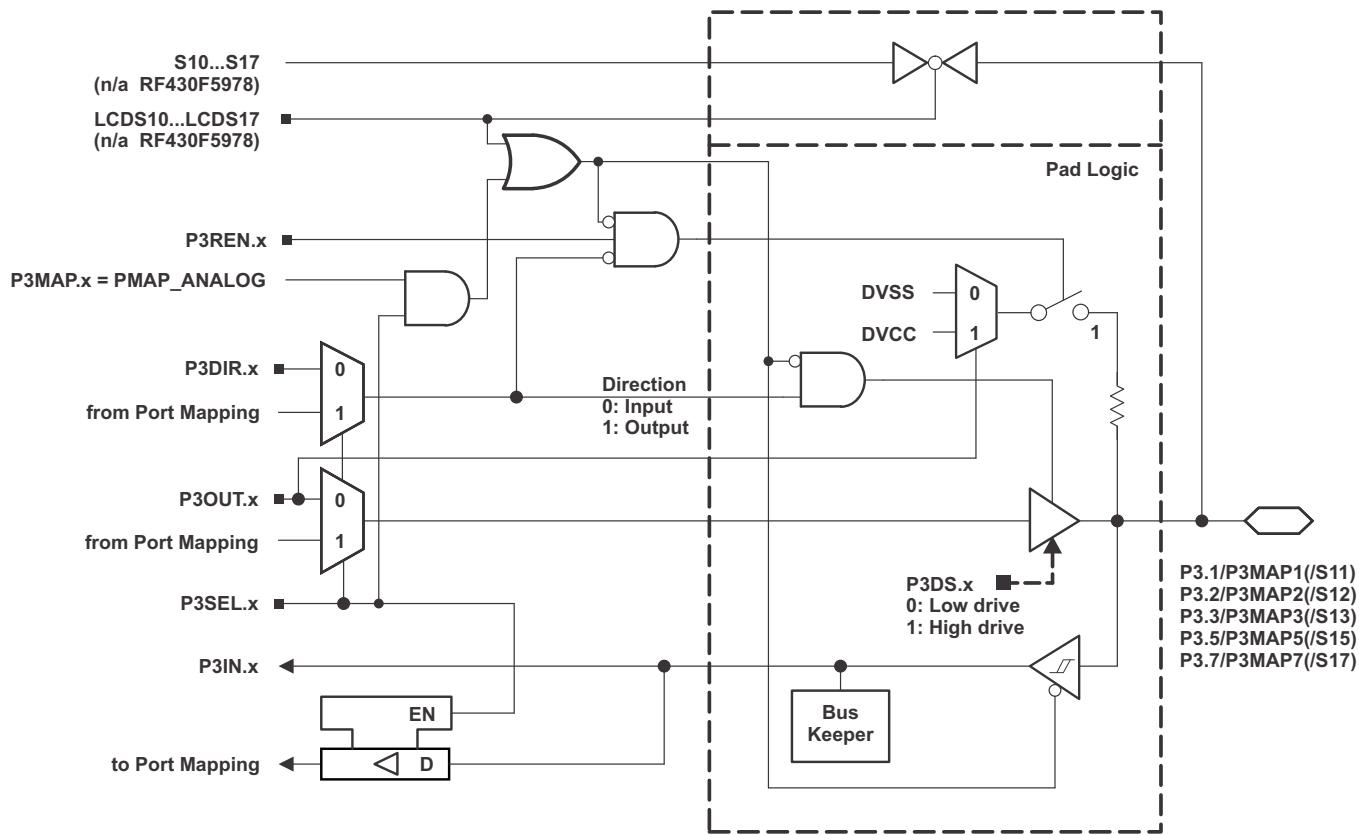


Figure 6-7. Port P3 (P3.1 to P3.3, P3.5, and P3.7) Schematic

**Table 6-49. Port P3 (P3.1 to P3.3, P3.5, and P3.7) Pin Functions**

PIN NAME (P3.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>			
			P3DIR.x	P3SEL.x	P3MAPx	LCDS10 to LCDS17
P3.1/P3MAP1/S11 <sup>(2)</sup>	1	P3.1 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(3)</sup>	1	$\leq 30^{(3)}$	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S11	X	X	X	1
P3.2/P3MAP7/S12 <sup>(2)</sup>	2	P3.2 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(3)</sup>	1	$\leq 30^{(3)}$	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S12	X	X	X	1
P3.3/P3MAP3/S13 <sup>(2)</sup>	3	P3.3 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(3)</sup>	1	$\leq 30^{(3)}$	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S13	X	X	X	1
P3.5/P3MAP5/S15 <sup>(2)</sup>	5	P3.5 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(3)</sup>	1	$\leq 30^{(3)}$	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S15	X	X	X	1
		S16	X	X	X	1
P3.7/P3MAP7/S17	7	P3.7 (I/O)	I: 0; O: 1	0	X	0
		Mapped secondary digital function - see <a href="#">Table 6-8</a>	0; 1 <sup>(3)</sup>	1	$\leq 30^{(3)}$	0
		Output driver and input Schmitt trigger disabled	X	1	= 31	0
		S17	X	X	X	1

(1) X = don't care

(2) Internal connection to LF front end

(3) According to mapped function - see [Table 6-8](#).

### 6.12.6 Port P4, P4.0 to P4.2, Input/Output With Schmitt Trigger

Figure 6-8 shows the port schematic, and Table 6-50 summarizes selection of the pin function.

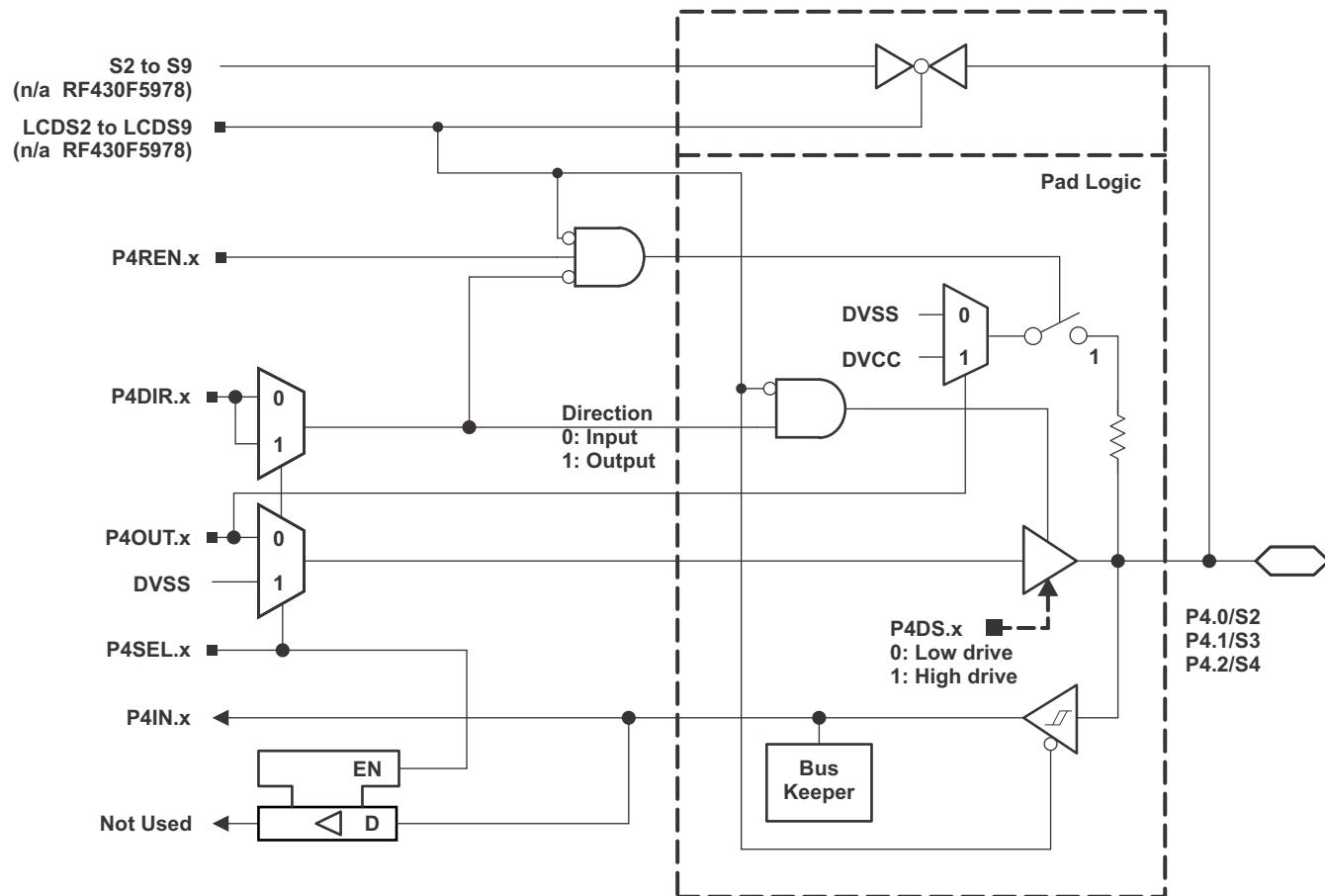


Figure 6-8. Port P4 (P4.0 to P4.2) Schematic

**Table 6-50. Port P4 (P4.0 to P4.2) Pin Functions**

PIN NAME (P4.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>		
			P4DIR.x	P4SEL.x	LCDS2 to LCDS7
P4.0/P4MAP0/S2	0	P4.0 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S2	X	X	1
P4.1/P4MAP1/S3 <sup>(2)</sup>	1	P4.1 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S3	X	X	1
P4.2/P4MAP7/S4 <sup>(2)</sup>	2	P4.2 (I/O)	I: 0; O: 1	0	0
		N/A	0	1	0
		DVSS	1	1	0
		S4	X	X	1

(1) X = don't care

(2) Internal connection to LF front end

### 6.12.7 Port P5, P5.0, Input/Output With Schmitt Trigger

Figure 6-9 shows the port schematic, and Table 6-51 summarizes selection of the pin function.

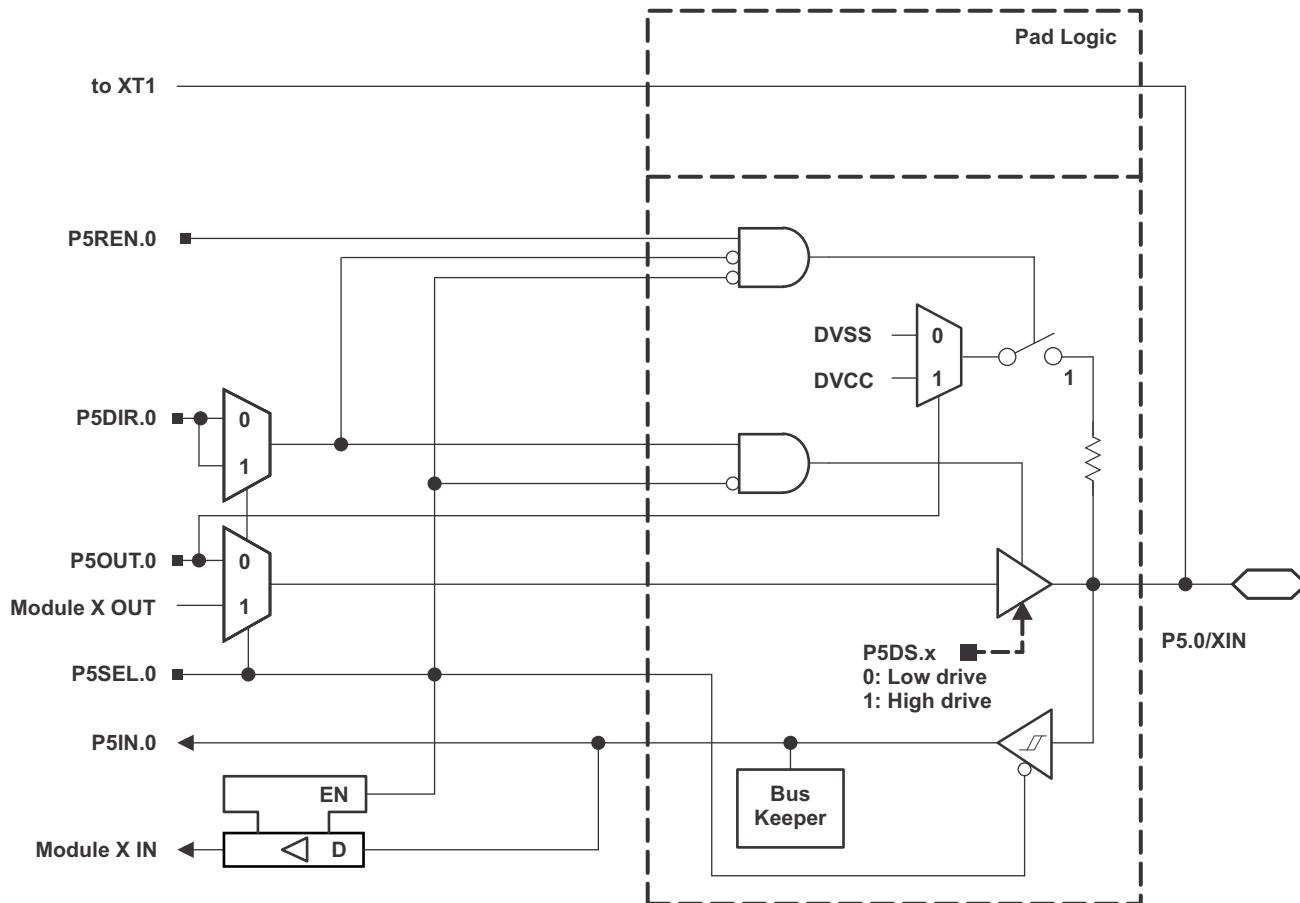


Figure 6-9. Port P5 (P5.0) Schematic

### 6.12.8 Port P5, P5.1, Input/Output With Schmitt Trigger

Figure 6-10 shows the port schematic, and Table 6-51 summarizes selection of the pin function.

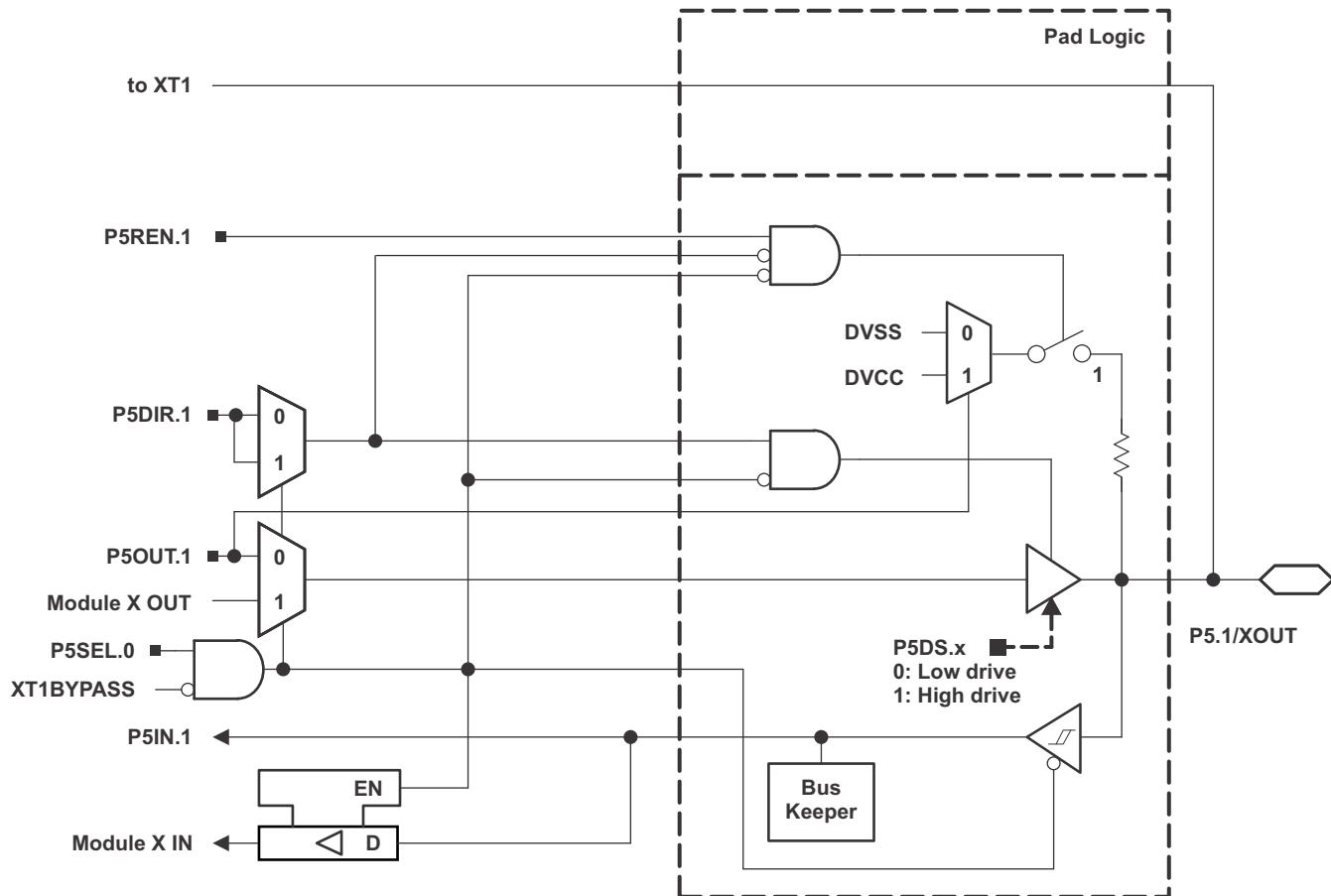


Figure 6-10. Port P5 (P5.1) Schematic

Table 6-51. Port P5 (P5.0 and P5.1) Pin Functions

PIN NAME (P5.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>			
			P5DIR.x	P5SEL.0	P5SEL.1	XT1BYPASS
P5.0/XIN	0	P5.0 (I/O)	I: 0; O: 1	0	X	X
		XIN crystal mode <sup>(2)</sup>	X	1	X	0
		XIN bypass mode <sup>(2)</sup>	X	1	X	1
P5.1/XOUT	1	P5.1 (I/O)	I: 0; O: 1	0	X	X
		XOUT crystal mode <sup>(3)</sup>	X	1	X	0
		P5.1 (I/O) <sup>(3)</sup>	X	1	X	1

(1) X = don't care

(2) Setting P5SEL.0 causes the general-purpose I/O to be disabled. Pending the setting of XT1BYPASS, P5.0 is configured for crystal mode or bypass mode.

(3) Setting P5SEL.0 causes the general-purpose I/O to be disabled in crystal mode. When using bypass mode, P5.1 can be used as general-purpose I/O.

### 6.12.9 Port J, J.0 JTAG Pin TDO, Input/Output With Schmitt Trigger or Output

Figure 6-11 shows the port schematic, and Table 6-52 summarizes selection of the pin function.

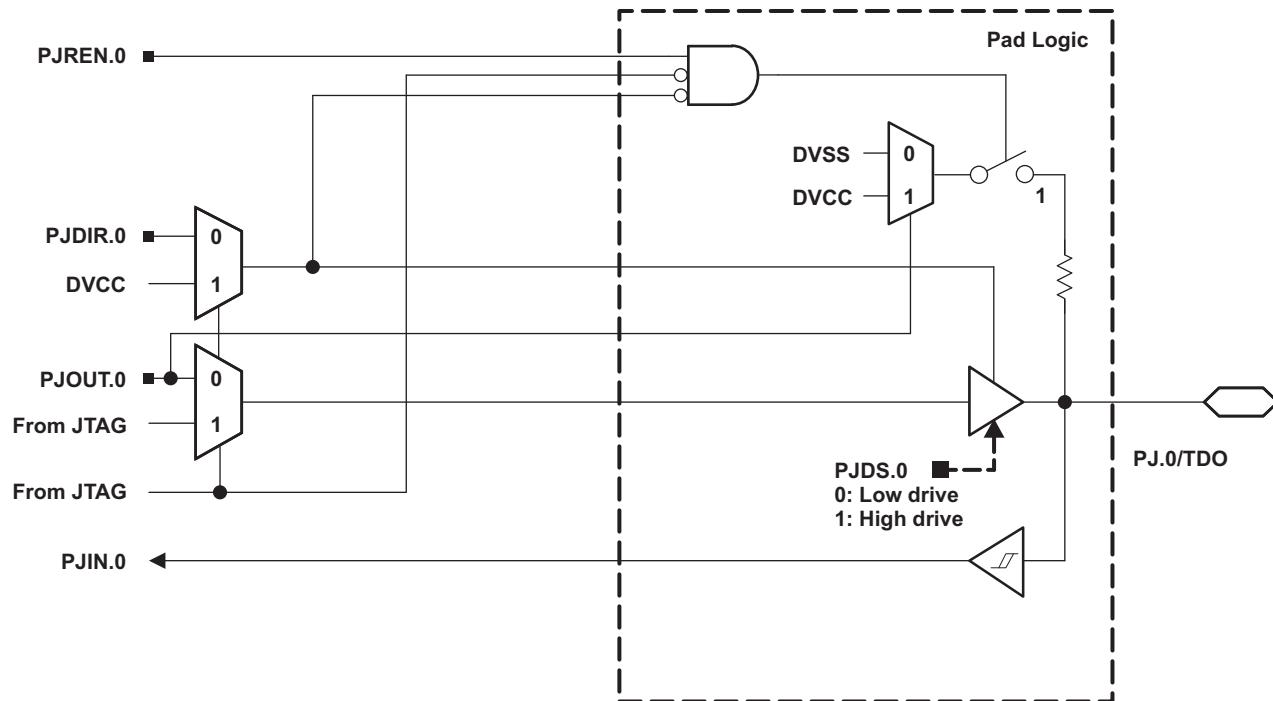
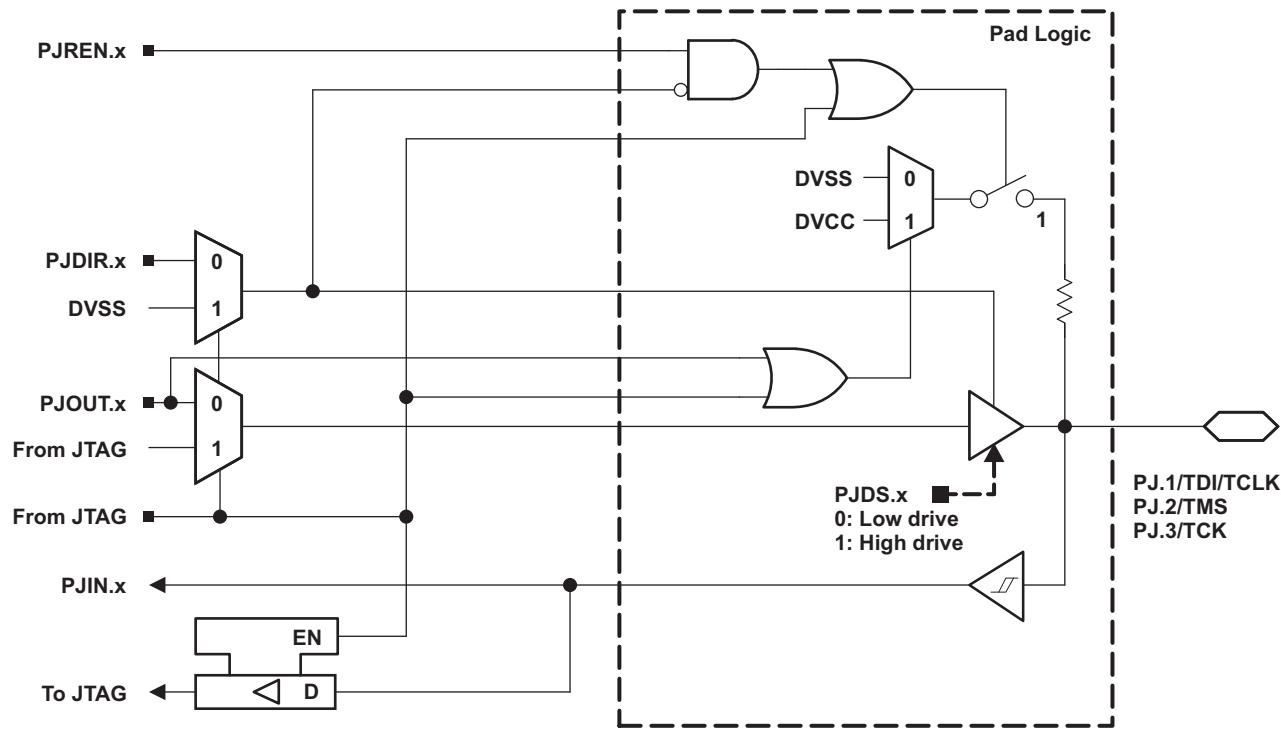


Figure 6-11. Port PJ (PJ.0) Schematic

### 6.12.10 Port J, J.1 to J.3 JTAG Pins TMS, TCK, TDI/TCLK, Input/Output With Schmitt Trigger or Output

Figure 6-12 shows the port schematic, and Table 6-52 summarizes selection of the pin function.



**Figure 6-12. Port PJ (PJ.1 to PJ.3) Schematic**

**Table 6-52. Port PJ (PJ.0 to PJ.3) Pin Functions**

PIN NAME (PJ.x)	x	FUNCTION	CONTROL BITS OR SIGNALS <sup>(1)</sup>
			PJDIR.x
PJ.0/TDO	0	PJ.0 (I/O) <sup>(2)</sup>	I: 0; O: 1
		TDO <sup>(3)</sup>	X
PJ.1/TDI/TCLK	1	PJ.1 (I/O) <sup>(2)</sup>	I: 0; O: 1
		TDI/TCLK <sup>(3) (4)</sup>	X
PJ.2/TMS	2	PJ.2 (I/O) <sup>(2)</sup>	I: 0; O: 1
		TMS <sup>(3) (4)</sup>	X
PJ.3/TCK	3	PJ.3 (I/O) <sup>(2)</sup>	I: 0; O: 1
		TCK <sup>(3) (4)</sup>	X

(1) X = don't care

## (2) Default condition

(3) The pin direction is controlled by the JTAG module.

(4) In JTAG mode, pullups are activated automatically on TMS, TCK, and TDI/TCLK. PJREN.x are don't care.

## 6.13 Device Descriptor Structures

Table 6-53 lists the content of the device descriptor tag-length-value (TLV) structure.

**Table 6-53. Device Descriptor Table**

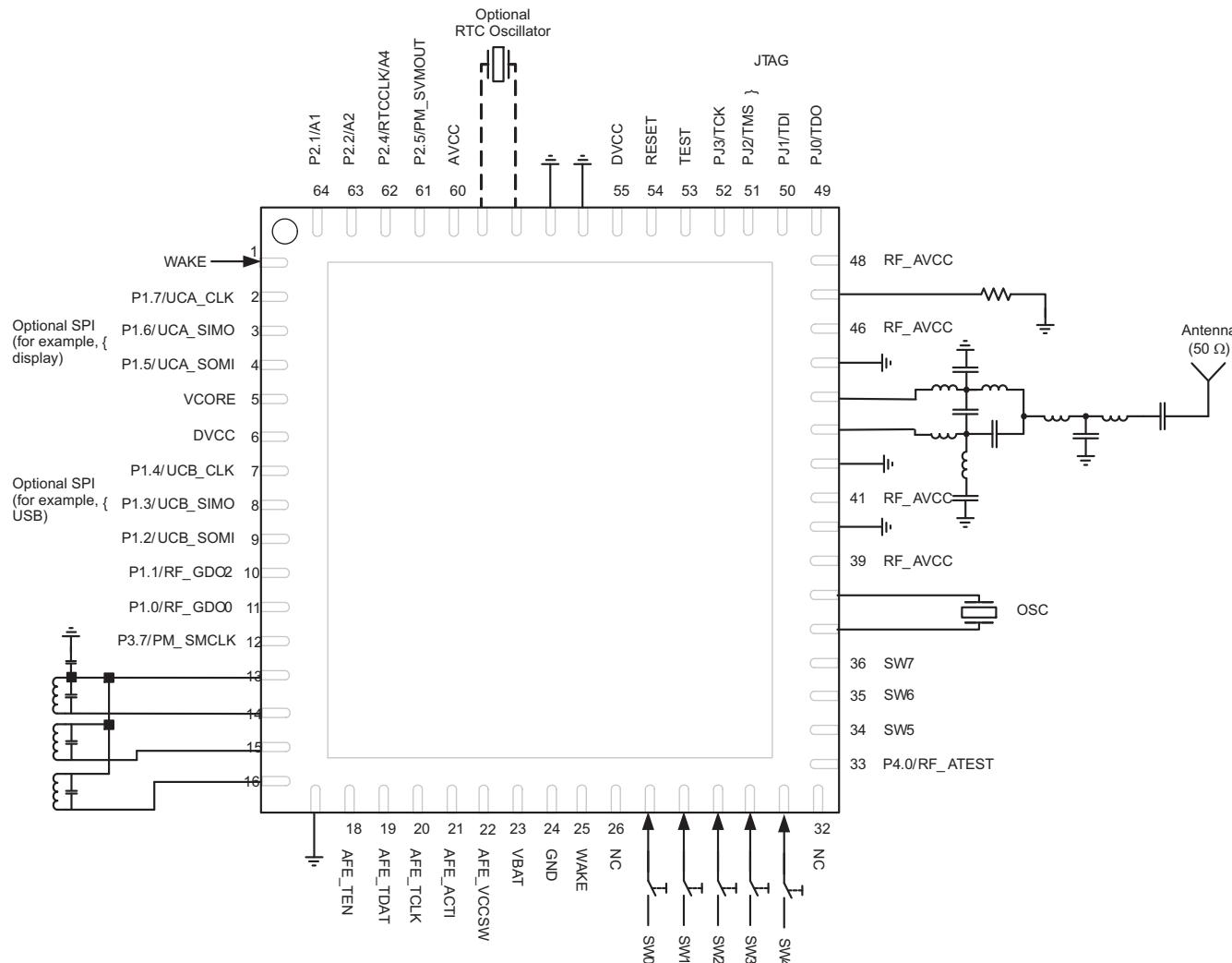
DESCRIPTION		ADDRESS	SIZE (bytes)	VALUE
				RF430F5978
Info Block	Info length	01A00h	1	06h
	CRC length	01A01h	1	06h
	CRC value	01A02h	2	per unit
	Device ID	01A04h	1	61h
	Device ID	01A05h	1	37h
	Hardware revision	01A06h	1	per unit
	Firmware revision	01A07h	1	per unit
Die Record	Die record tag	01A08h	1	08h
	Die record length	01A09h	1	0Ah
	Lot/wafer ID	01A0Ah	4	per unit
	Die X position	01A0Eh	2	per unit
	Die Y position	01A10h	2	per unit
	Test results	01A12h	2	per unit
ADC12 Calibration	ADC12 calibration tag	01A14h	1	11h
	ADC12 calibration length	01A15h	1	10h
	ADC gain factor	01A16h	2	per unit
	ADC offset	01A18h	2	per unit
	ADC 1.5-V reference Temperature sensor 30°C	01A1Ah	2	per unit
	ADC 1.5-V reference Temperature sensor 85°C	01A1Ch	2	per unit
	ADC 2.0-V reference Temperature sensor 30°C	01A1Eh	2	per unit
	ADC 2.0-V reference Temperature sensor 85°C	01A20h	2	per unit
	ADC 2.5-V reference Temperature sensor 30°C	01A22h	2	per unit
	ADC 2.5-V reference Temperature sensor 85°C	01A24h	2	per unit
REF Calibration	REF calibration tag	01A26h	1	12h
	REF calibration length	01A27h	1	06h
	1.5-V reference factor	01A28h	2	per unit
	2.0-V reference factor	01A2Ah	2	per unit
	2.5-V reference factor	01A2Ch	2	per unit
Peripheral Descriptor (PD)	Peripheral descriptor tag	01A2Eh	1	02h
	Peripheral descriptor length	01A2Fh	1	57h
	Peripheral descriptors	01A30h	PD Length	...

## 7 Applications, Implementation, and Layout

### NOTE

Information in the following Applications section is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 7.1 Application Circuit



For a complete reference design including layout, see the Sub-1-GHz Transceiver, LF Wake Receiver/Transponder SoC Evaluation Kit (RF430F5978EVM) and the *MSP430 Hardware Tools User's Guide* (SLAU278).

**Figure 7-1. Typical Application Circuit RF430F5978**

## 8 Device and Documentation Support

### 8.1 Device Support

#### 8.1.1 Development Support

##### 8.1.1.1 Getting Started and Next Steps

TI offers an extensive line of development tools, including tools to evaluate the performance of the processors, generate code, develop algorithm implementations, and fully integrate and debug software and hardware modules. The tool's support documentation is electronically available within the Code Composer Studio™ Integrated Development Environment (IDE).

The following products support development of the RF430F5978 device applications:

**Software Development Tools:** Code Composer Studio Integrated Development Environment (IDE): including Editor C/C++/Assembly Code Generation, and Debug plus additional development tools.

**Hardware Development Tools:** For a complete listing of development-support tools for the RF430F5978 platform, visit the TI website at [www.ti.com](http://www.ti.com). For information on pricing and availability, contact the nearest TI field sales office or authorized distributor.

#### 8.1.2 Device and Development Tool Nomenclature

To designate the stages in the product development cycle, TI assigns prefixes to the part numbers of all RF430 MCU devices and support tools. Each commercial family member has one of three prefixes: RF, P, or X (for example, RF430F5978). TI recommends two of three possible prefix designators for its support tools: RF and X. These prefixes represent evolutionary stages of product development from engineering prototypes (with X for devices and tools) through fully qualified production devices and tools (with RF for devices tools).

Device development evolutionary flow:

**X** – Experimental device that is not necessarily representative of the electrical specifications of the final device

**P** – Silicon die that conforms to the electrical specifications of the final device but has not completed quality and reliability verification

**RF** – Fully qualified production device

Support tool development evolutionary flow:

**X** – Development-support product that has not yet completed TI's internal qualification testing.

**RF** – Fully-qualified development-support product

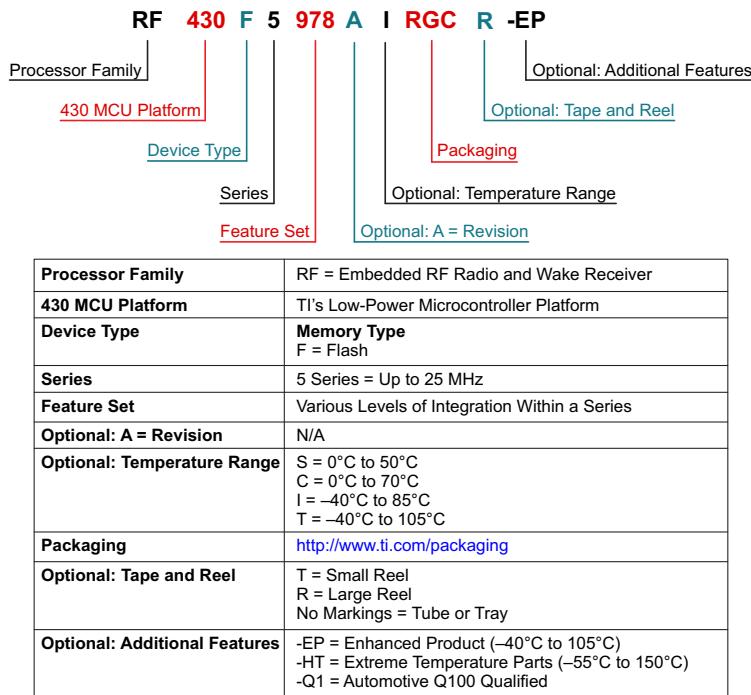
X and P devices and X development-support tools are shipped against the following disclaimer:

"Developmental product is intended for internal evaluation purposes."

RF devices and RF development-support tools have been characterized fully, and the quality and reliability of the device have been demonstrated fully. TI's standard warranty applies.

Predictions show that prototype devices (X and P) have a greater failure rate than the standard production devices. TI recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the package type (for example, RGC) and temperature range (for example, I). [Figure 8-1](#) provides a legend for reading the complete device name for any family member.



**Figure 8-1. Device Nomenclature**

## 8.2 Documentation Support

### 8.2.1 Related Documentation

The following documents describe the RF430F5978 SoC. Copies of these documents are available on the Internet at [www.ti.com](http://www.ti.com).

**SLAU378 RF430 Family User's Guide.** Detailed descriptions of all of the modules available in this device family.

## 8.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### TI E2E™ Community

[TI's Engineer-to-Engineer \(E2E\) Community](#). Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

### TI Embedded Processors Wiki

[Texas Instruments Embedded Processors Wiki](#). Established to help developers get started with embedded processors from TI and to foster innovation and growth of general knowledge about the hardware and software surrounding these devices.

## 8.4 Trademarks

MSP430, Code Composer Studio, E2E are trademarks of Texas Instruments.  
All other trademarks are the property of their respective owners.

## 8.5 Electrostatic Discharge Caution

 This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 8.6 Export Control Notice

Recipient agrees to not knowingly export or re-export, directly or indirectly, any product or technical data (as defined by the U.S., EU, and other Export Administration Regulations) including software, or any controlled product restricted by other applicable national regulations, received from disclosing party under nondisclosure obligations (if any), or any direct product of such technology, to any destination to which such export or re-export is restricted or prohibited by U.S. or other applicable laws, without obtaining prior authorization from U.S. Department of Commerce and other competent Government authorities to the extent required by those laws.

## 8.7 Glossary

[SLYZ022 — TI Glossary](#).

This glossary lists and explains terms, acronyms and definitions.

## 9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
RF430F5978IRGCR	ACTIVE	VQFN	RGC	64	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	RF430F5978	<b>Samples</b>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

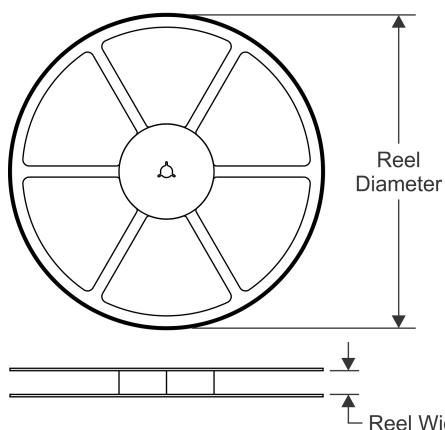
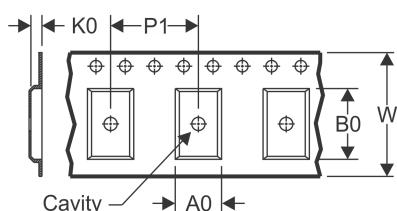


www.ti.com

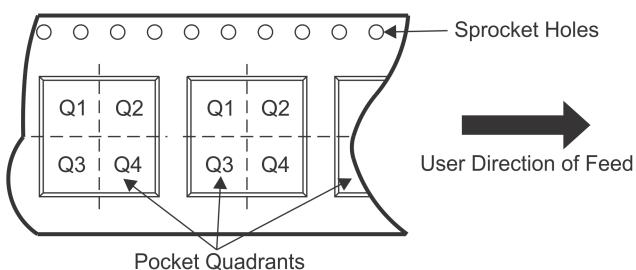
## PACKAGE OPTION ADDENDUM

29-Sep-2015

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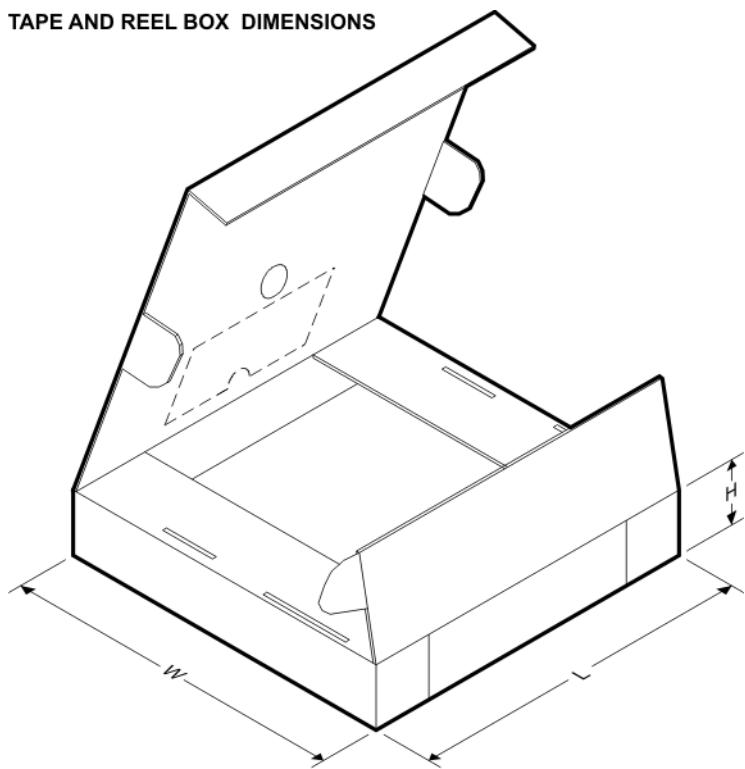
**TAPE AND REEL INFORMATION**
**REEL DIMENSIONS**

**TAPE DIMENSIONS**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

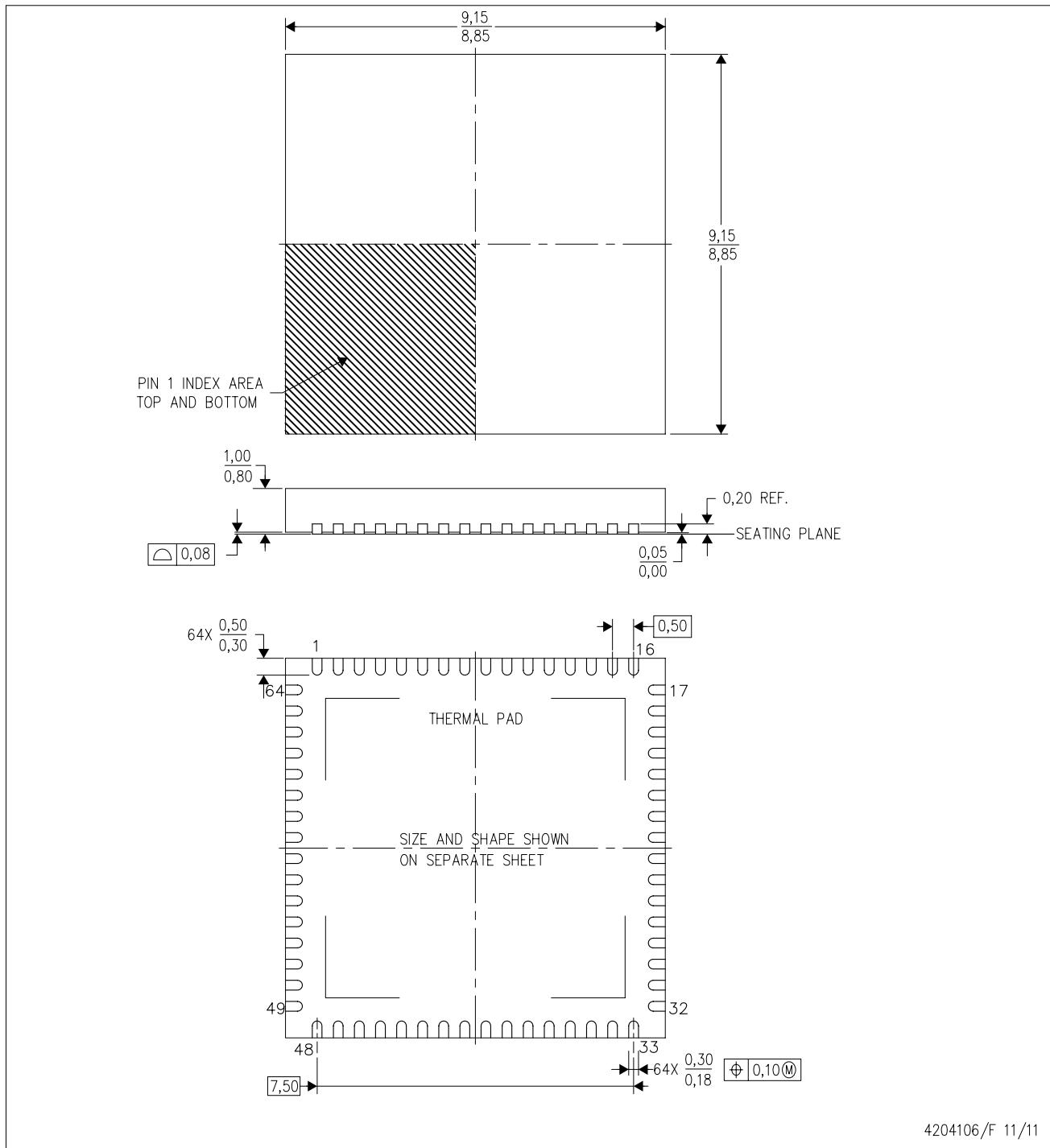
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
RF430F5978IRGCR	VQFN	RGC	64	2000	330.0	16.4	9.3	9.3	1.1	12.0	16.0	Q2

**TAPE AND REEL BOX DIMENSIONS**

\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
RF430F5978IRGCR	VQFN	RGC	64	2000	367.0	367.0	38.0

RGC(S-PVQFN-N64) CUSTOM DEVICE PLASTIC QUAD FLATPACK NO-LEAD



4204106/F 11/11

NOTES:

- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
- This drawing is subject to change without notice.
- Quad Flatpack, No-leads (QFN) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

# THERMAL PAD MECHANICAL DATA

RGC (S-PVQFN-N64)

PLASTIC QUAD FLATPACK NO-LEAD

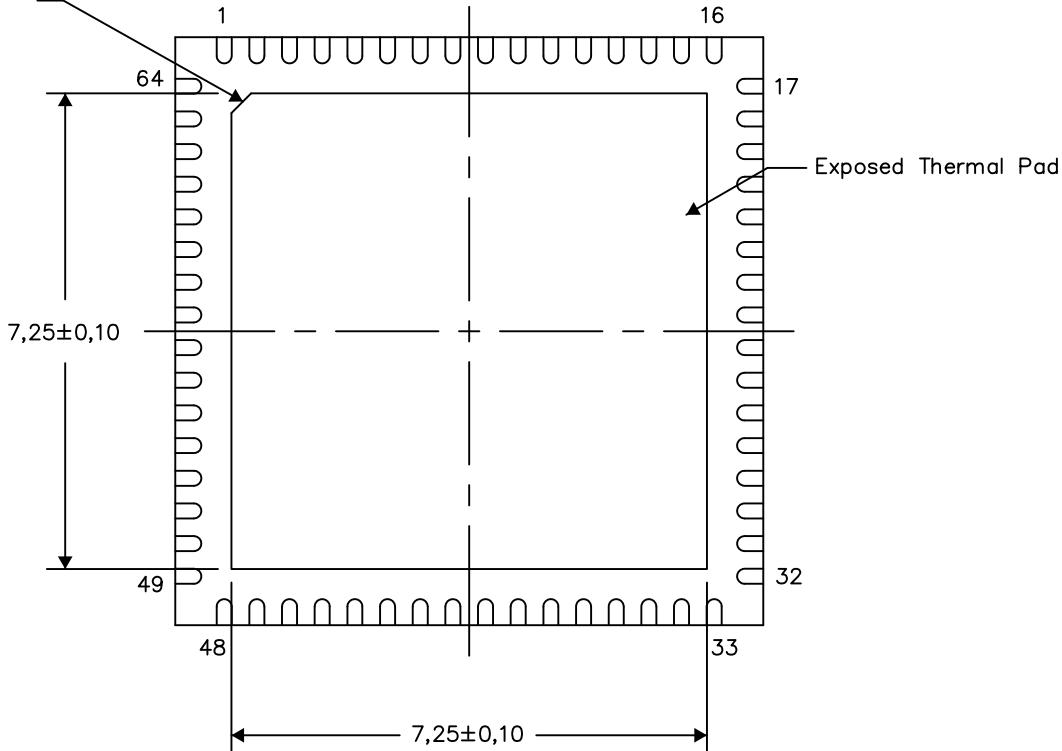
## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.

PIN 1 INDICATOR  
CO,30



Bottom View

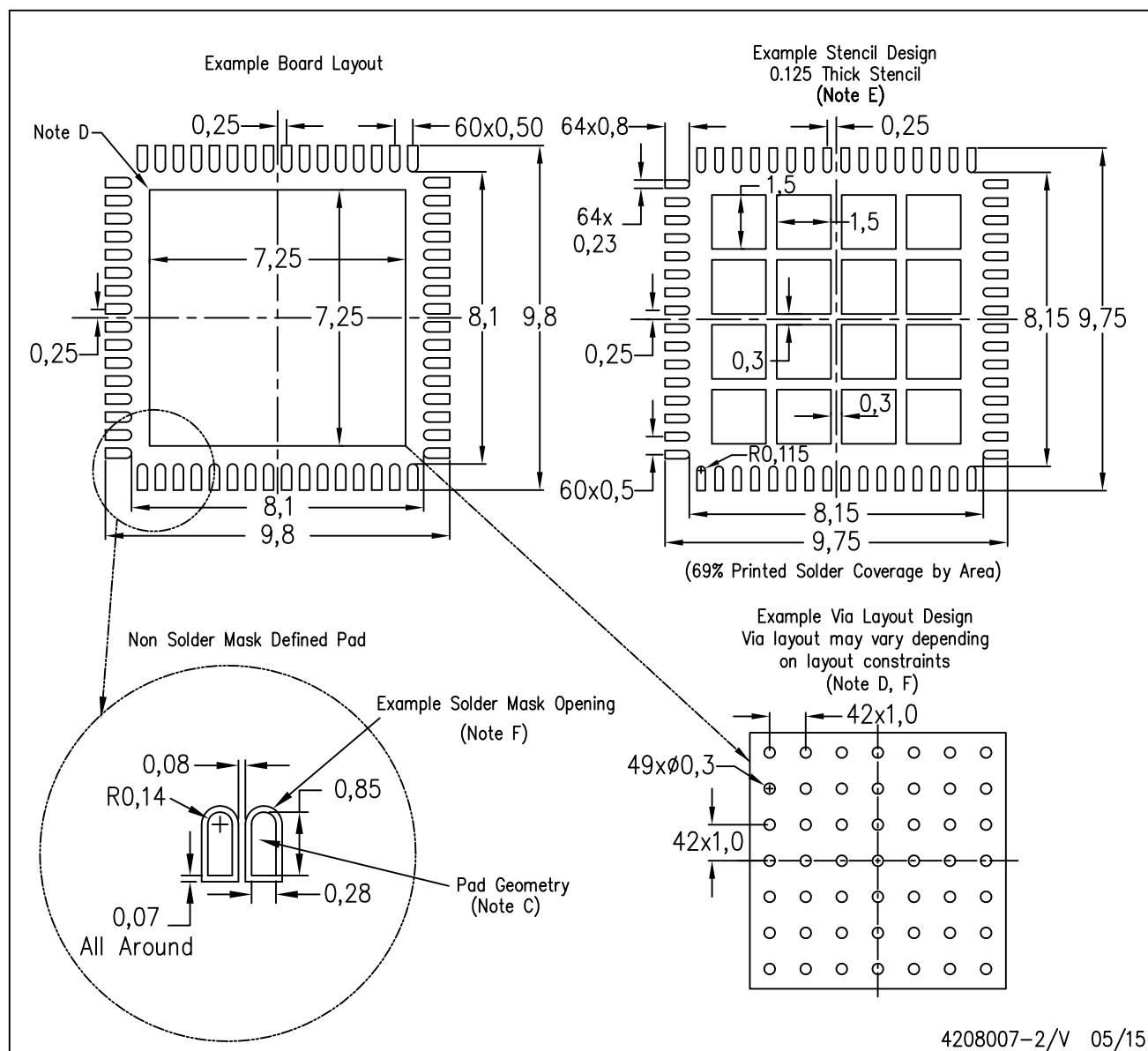
Exposed Thermal Pad Dimensions

4206192-2/AE 03/15

NOTE: A. All linear dimensions are in millimeters

RGC (S-PVQFN-N64)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Publication IPC-7351 is recommended for alternate designs.
- This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
- Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in thermal pad.

## IMPORTANT NOTICE

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